DATASHEET

inter_{sil}

Advanced Linear EAPP Digital 6-Phase Green PWM Controller for Digital Power Management with NVM and AUTO Phase Shedding

ISL6398

The ISL6398 is a **smart** and **smallest** 6-Phase **Green** PWM controller, designed for networking, datacenter, and POL applications. It includes programmable functions and telemetries for easy use and system flexibility using SMBus, PMBus, or I²C interface, which is designed to program NVM banks up to 8 different compensations and system parameters. This **minimizes** external components and significantly reduces design complexity and PCB area, and **simplifies** the manufacturing process.

The ISL6398 utilizes Intersil's proprietary Advanced Linear EAPP (Enhanced Active Pulse Positioning) Digital control scheme to achieve the extremely fast linear transient response with fewer output capacitors and overcomes many hurdles of traditional digital approach, which uses non-linear, discrete control method for both voltage loop and current balance loop and runs into beat frequency oscillation and non-linear response. The ISL6398 accurately monitors the load current via the IMON pin and reports this information via the READ_IOUT register for power management. The ISL6398 features auto-phase shedding. In low power operation, the magnetic core and switching losses are significantly reduced with lower phase count operation, yielding high efficiency at light load. When APA is triggered, the dropped phase(s) are added back to sustain heavy load transient response and efficiency. It optimizes the efficiency from light to full load for Greener Environment without sacrificing the transient performance.

The ISL6398 senses the output current continuously by a dedicated current sense resistor or the DCR of the output inductor. The sensed current flows through a digitally programmable 1% droop resistor for precision load line control. Current sensing circuits also provide the needed signals for channel-current balancing, average overcurrent protection and individual phase current limiting. The TM pin senses an NTC thermistor's temperature, which is internally digitized for thermal monitoring and for integrated thermal compensation of the current sense elements of the regulator.

The ISL6398 features remote voltage sensing and completely eliminates any potential difference between remote and local grounds. This improves regulation and protection accuracy. The threshold-sensitive enable input is available to accurately coordinate the start-up of the ISL6398 with other voltage rails.

Features

- SMBus/PMBus/I²C Compatible
 - Programmable IMAX, TMAX, BOOT, and address
 - Programmable soft-start rate and DVID rate
 - Up to 1.5MHz
 - NVM to store up to 8 Configurations with programmable frequency, droop, auto, faults (OCP, UVP, CFP), etc.
 - No firmware requirement and hassle
- Advanced Linear EAPP Digital control scheme (patented)
 - Digitally programmable compensation
 - Auto phase shedding option for greener environment
 - Variable frequency control during load transients to reduce beat frequency oscillation
 - Linear control with evenly distributed PWM pulses for better phase current balance during load transients
- Voltage feed-forward and ramp adjustable options
- High frequency compensation option
- Active phase adding and dropping for enhanced light load efficiency
- Phase doubler and coupled-inductor compatibility
- + Differential remote voltage sensing with $\pm 0.5\%$ accuracy
- Programmable minimum phase count operation
- Programmable slew rate of dynamic VID with dynamic VID compensation (DVC)
- Support 3-state 5V or 3.3V PWM DrMOS and driver
- · Zero current shutdown with ISL6627
- Precision resistor or DCR differential current sensing
 - Accurate load-line (Droop) programming and control
 - Accurate current monitoring and channel-current balancing with calibration capability
- True input current sensing for catastrophic failure protection
- · Average overcurrent protection and channel current limiting
- High common mode current sense input (VCC-1.5V)
- · Open sensing and single point of loop failure protection
- · Thermal monitoring and integrated compensation
- 1- to 6-Phase option and up to 2MHz per phase
- · Start-up into precharged load
- Pb-free (RoHS Compliant)
- 40 Ld 5x5 Plastic Package

Applications

- · High efficiency and high density digital power
- · High performance multi-phase POL and network
- Cloud Computing, Router, Data Center and Storage
- · General processor power

ISL6398

Table of Contents

Ordering Information3
Driver Recommendation4
ISL6398 Internal Block Diagram5
Typical Application: 6-Phase VR with DrMOS and PMBus/SMBus/I ² C6
Typical Application: 4-Phase VR with DrMOS and PMBus/SMBus/I ² C7
Typical Application: 6-Phase VR for General Processor Power
Typical Application: 12-Phase VR for Over-clocking
Applications9
Absolute Maximum Ratings10
Thermal Information10
Recommended Operating Conditions10
Electrical Specifications
Functional Pin Descriptions14
Operation
Multiphase Power Conversion15Interleaving15PWM Modulation Scheme16PWM Operation17DrMOS and Driver Compatibility17Phase Doubler Compatibility17Precharged Start-up Capability17Switching Frequency17Current Sensing18R _{SET} and L/DCR Matching for Coupled inductor19Channel-current Balance20Voltage Regulation (5mV and 10mV Mode)23Dynamic VID24
Operation Initialization24
Enable and Disable 24 Soft-start 25 Current Sense Output 25

Fault Monitoring and Protection	. 26
VR_Ready Signal. Overvoltage Protection Undervoltage Protection Overcurrent Protection Thermal Monitoring (VR_HOT#) Temperature Compensation Integrated Temperature Compensation Design Procedure Dynamic VID Compensation (DVC). Programmable Compensation Catastrophic Fault Protection	26 27 27 27 28 29 29 .30 .30 .30
Input Current Sensing	
Auto-phase Shedding	. 31
Resistor Reader (Patented)	. 32
Memory Banks	. 33
SMBus, PMBus and I ² C Operation	. 35
General Design Guide	49
Power Stages Current Sensing Resistor Load-line Regulation Resistor Output Filter Design Switching Frequency Selection Input Capacitor Selection	49 50 51 51 52
Layout and Design Considerations	
Pin Noise Sensitivity, Design and Layout Consideration Component Placement	
Powering Up And Open-Loop Test	. 55
Voltage Regulator (VR) Design Materials	. 55
Revision History	
About Intersil	
Package Outline Drawing	

Ordering Information

PART NUMBER (Notes 1, 2, 3)	PART MARKING	TEMP. RANGE (°C)	PACKAGE (Pb-Free)	PKG. DWG. #
ISL6398HRTZ	ISL6398 HRTZ	-10 to +100	40 Ld 5x5 TQFN	L40.5x5
ISL6398IRTZ	ISL6398 IRTZ	-40 to +85	40 Ld 5x5 TQFN	L40.5x5
SL6398EVAL1Z 120A 3-Phase Evaluation Board with On Board Transient				

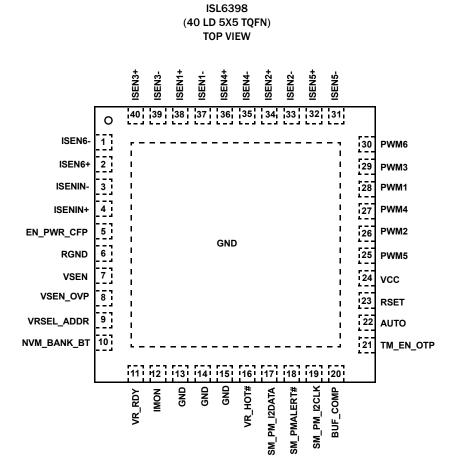
NOTES:

1. Add "-T*" suffix for tape and reel. Please refer to TB347 for details on reel specifications

 These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

3. For Moisture Sensitivity Level (MSL), please see product information page for ISL6398. For more information on MSL please see techbrief TB363.

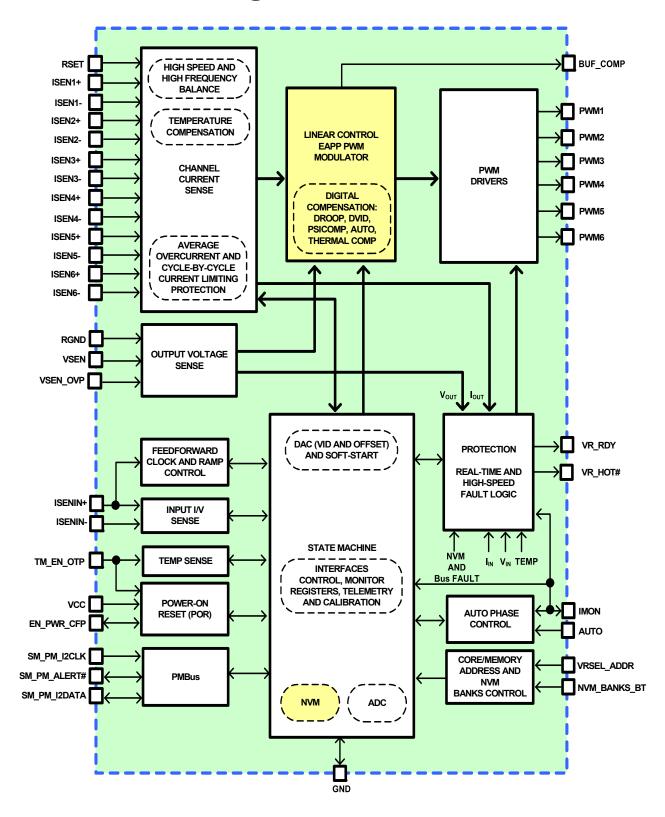
Pin Configuration



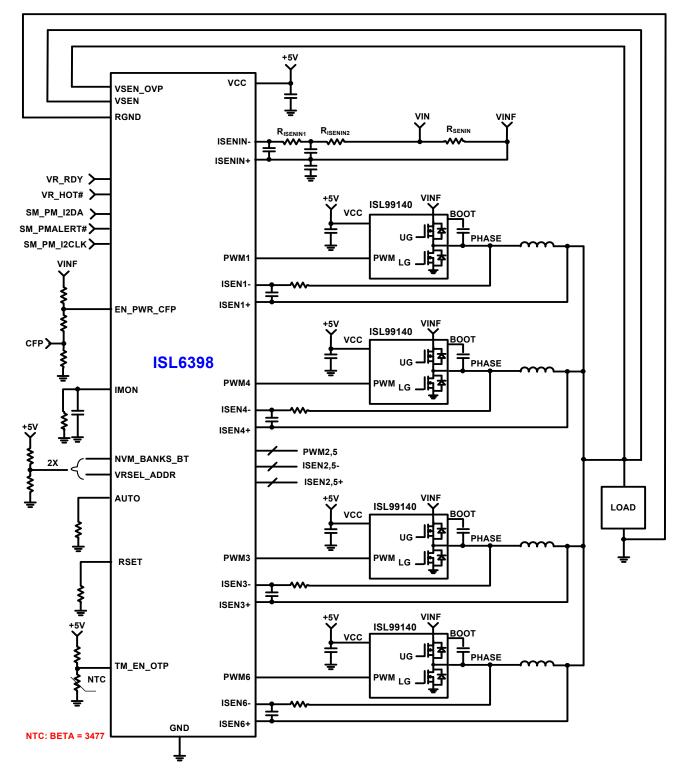
Driver Recommendation

DRIVER	QUIESCENT CURRENT (mA)	GATE DRIVE (V)	# OF DRIVERS	DIODE EMULATION (DE)	COMMENTS
ISL6627	1.0	5V	Single	Yes	For dropped phases or all channels with Diode Emulation (DE) for low stress shutdown or phase dropping.
ISL6596	0.19	5V	Single	No	For dropped phases or all channels without DE.
ISL6610 ISL6610A	0.24	5V	Dual	No	For dropped phases or all channels without DE.
ISL6611A	1.25	5V	Dual	No	Phase Doubler with Integrated Drivers, up to 12-Phase. For all channels with DE Disabled.
ISL6617	5.0	N/A	N/A	No	PWM Doubler for DrMOS, up to 12- or 24-Phase. For all channels with DE Disabled.
ISL99140	0.47	5V	Single	Yes	DrMOS with 40A current capability. ISL99140's diode emulation is not compatible with ISL6398. Both DrMOS and ISL6398 should disable their diode emulation operation.

NOTE: Intersil 5V and 12V drivers are mostly pin-to-pin compatible and allow for dual footprint layout implementation to optimize MOSFET selection and efficiency. The 5V Drivers are more suitable for high frequency and high power density applications.

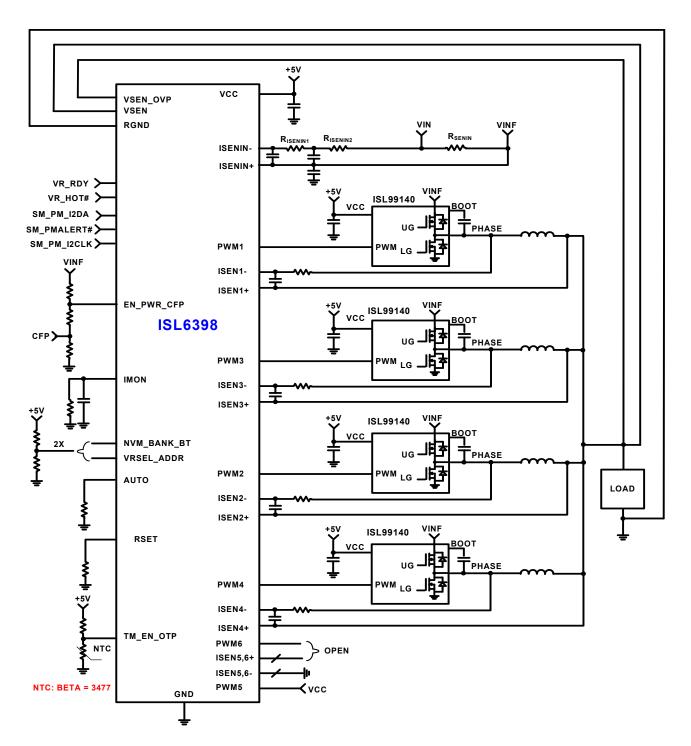


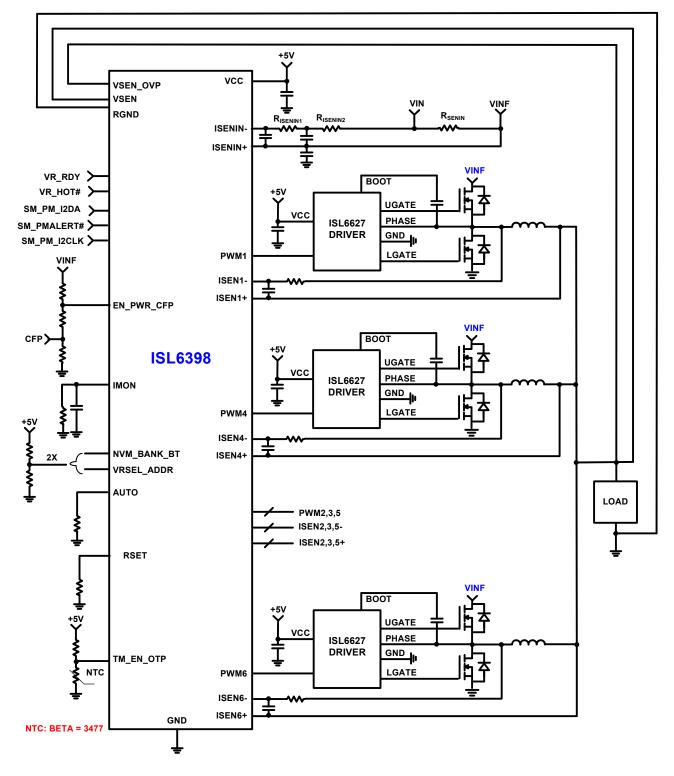
ISL6398 Internal Block Diagram



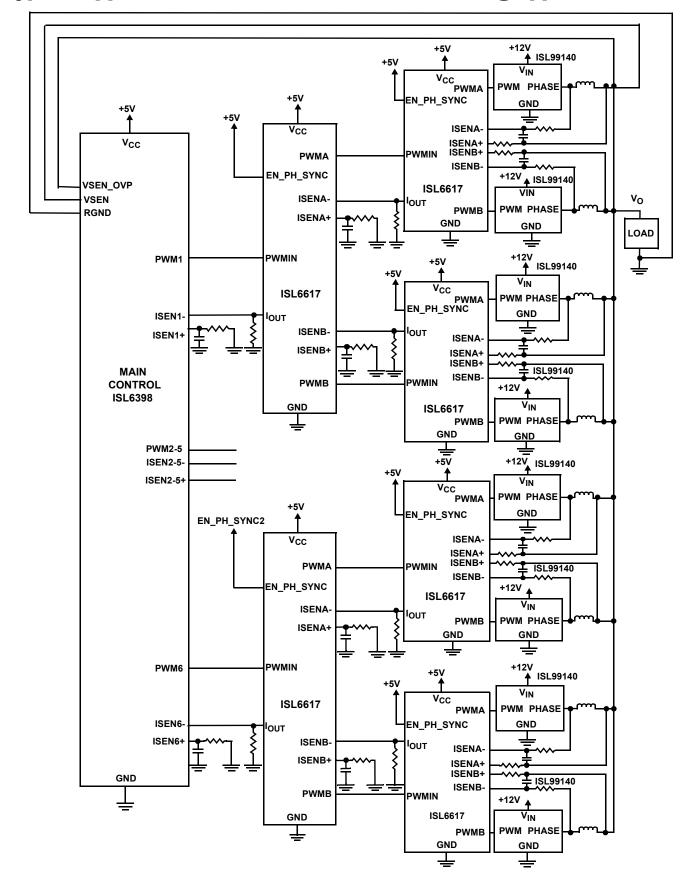
Typical Application: 6-Phase VR with DrMOS and PMBus/SMBus/ I^2C

Typical Application: 4-Phase VR with DrMOS and PMBus/SMBus/ I^2C





Typical Application: 6-Phase VR for General Processor Power



Typical Application: 12-Phase VR for Over-clocking Applications

Absolute Maximum Ratings

VCC, VR_RDY	+6V
ISENIN±	GND -0.3V to 27V
All Other Pins	GND -0.3V to V _{CC} + 0.3V

Recommended Operating Conditions

Supply Voltage, V _{CC}
EPROM Write and Store Command Temperature40°C to +85°C
Ambient Temperature
ISL6398HRTZ10°C to +100°C
ISL6398IRTZ40°C to +85°C

Thermal Information

Thermal Resistance (Notes 4, 5)	θ _{JA} (° C /W)	θ _{JC} (° C /W)
40 Ld 5x5 TQFN Package	29	1
Maximum Junction Temperature		+150°C
Maximum Storage Temperature Range	6	5°C to +150°C
Pb-Free Reflow Profile		see <u>TB493</u>

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- 4. θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief <u>TB379</u>.
- 5. For $\theta_{JC},$ the "case temp" location is the center of the exposed metal pad on the package underside.

Electrical Specifications Recommended Operating Conditions, V_{CC} = 5V, Unless Otherwise specified. Boldface limits apply across the operating temperature range.

PARAMETER	TEST CONDITIONS	MIN (Note 7)	ТҮР	MAX (Note 7)	UNITS
V _{CC} SUPPLY CURRENT					
Nominal Supply	V _{CC} = 5VDC; EN_PWR = 5VDC; F _{SW} = 400kHz	-	35	45	mA
Shutdown Supply	V _{CC} = 5VDC; EN_PWR = 0VDC; F _{SW} = 400kHz	-	27	33	mA
POWER-ON RESET AND ENABLE		i			
V _{CC} Rising POR Threshold		4.22	4.35	4.55	v
V _{CC} Falling POR Threshold		4.00	4.10	4.22	v
EN_PWR_CFP High Level Turn-OFF Threshold	Externally Driven	3.5	3.6	3.7	v
EN_PWR_CFP High Level Turn-ON Threshold	Externally Driven	3.33	3.52	3.58	v
EN_PWR_CFP Latch-OFF Level	Internally Driven, 5mA Load	4.80	-	-	v
EN_PWR_CFP Internal Pull-Up Impedance		•	12	34	Ω
EN_PWR_CFP Rising Threshold		0.83	0.85	0.87	v
EN_PWR_CFP Falling Threshold		0.70	0.77	0.84	v
DAC (VID+OFFSET)			1		
	DAC = 1.5V to 3.04 V	-0.5	-	0.5	%VID
System Accuracy of Commercial Temperature $(T_1 = 0^{\circ}C \text{ to } +70^{\circ}C, \text{ Note } 6, \text{ Closed-Loop})$	DAC = 0.8V to 1.49V	-5	-	5	mV
	DAC = 0.25V to 0.795V	-8	-	8	mV
	DAC = 1.5V to 3.04 V	-0.55	-	0.55	%VID
System Accuracy of ISL6398HRTZ (T _J = -10°C to +100°C, Note 6, Closed-Loop)	DAC = 0.8V to 1.49V	-7	-	7	mV
	DAC = 0.25V to 0.795V	-9	-	9	mV
	DAC = 1.5V to 3.04 V	-0.6	-	0.6	%VID
System Accuracy of ISL6398IRTZ (T ₁ = -40°C to +85°C, Note 6, Closed-Loop)	DAC = 0.8V to 1.49V	-10	-	10	mV
(DAC = 0.25V to 0.795V	-10	-	10	mV

Electrical Specifications Recommended Operating Conditions, V_{CC} = 5V, Unless Otherwise specified. **Boldface limits apply across the operating temperature range. (Continued)**

PARAMETER	TEST CONDITIONS	MIN (Note 7)	ТҮР	MAX (Note 7)	UNITS
OSCILLATORS					
	390kHz, F3[2:0] = 0h = Original, ISL6398HRTZ	355	390	425	kHz
Accuracy of Switching Frequency Setting	390kHz, F3[2:0] = 0h = Original, ISL6398IRTZ	348	390	425	kHz
Maximum Switching Frequency		-	2.025	-	MHz
Minimum Switching Frequency		-	0.120	-	MHz
	DVID = 0.3125mV/µs, Minimum	0.3125	-	-	mV/µs
	DVID = 2.5mV/µs	2.5	3.0	3.4	mV/µs
Soft-start Ramp Rate	DVID = 5.0mV/µs	5.0	6.0	7.0	mV/µs
	DVID = 13.25mV/µs, Maximum	13.25	-	-	mV/µs
Minimum Dynamic VID Slew Rate	DVID = 0.3125mV/µs, Minimum	0.3125	-	-	mV/µs
Maximum Dynamic VID Slew Rate	DVID = 13.25mV/µs, Maximum	13.25	-	-	mV/µs
Maximum Duty Cycle Per PWM	390kHz	95	98	99	%
PWM GENERATOR				I	
	VR _{RAMP_ADJ} = 0.7V, ISENIN+ = 12V	-	0.7	-	v
	VR _{RAMP_ADJ} = 1.0V, ISENIN+ = 12V	-	1.0	-	v
Sawtooth Amplitude	VR _{RAMP_ADJ} = 1.2V, ISENIN+ = 12V	-	1.2	-	v
	VR _{RAMP_ADJ} = 1.5V, ISENIN+ = 12V	-	1.5	-	v
BUFFERED COMP AMPLIFIER				I	
Open-Loop Gain	$R_L = 10k\Omega$ to ground	-	96	-	dB
Open-Loop Bandwidth		-	20	-	MHz
Maximum Output Voltage	No Load	3.6	4.0	-	v
Output High Voltage	1mA Load	3.4	3.9	-	v
Output Low Voltage	1mA Load	1.88		1.99	v
PWM OUTPUT (PWM[6:1])	1	I			
	PWM = Low with 1mA Load, for Fast Transition	-	80	-	Ω
PWM[6:1] Sink Impedance	PWM = Low with 1mA Load, ISL6398HRTZ	170	285	425	Ω
	PWM = Low with 1mA Load, ISL6398IRTZ	170	285	400	Ω
PWM[6:1] Source Impedance	PWM = High, Forced to 3.7V	60	125	210	Ω
PWM Mid-Level	0.4mA Load, 5V PWM	36	40	44	%VCC
PWM Mid-Level	0.4mA Load, 3.3V PWM	24	28	31	%VCC
CURRENT SENSE AND OVERCURRENT PROTECTIO	N			l.	
Sensed Current Tolerance	$(T_J = 0^{\circ}C \text{ to } +70^{\circ}C)$	73	78	82.5	μA
CS Offset and Mirror Error Included, $R_{SET} = 12.8 k\Omega$	(T _J = -40°C to +100°C, HRTZ, IRTZ)	72	78	83	μA
Average OC Trip Level at Normal CCM PWM Mode	$(T_J = 0^{\circ}C \text{ to } +70^{\circ}C)$	96	103	111	μA
CS Offset and Mirror Error Included, R _{SET} = 12.8k Ω	(T _J = -40°C to +100°C, HRTZ, IRTZ)	95	103	112	μA
Average Overcurrent Trip Level at PSI1/2/3 Mode CS Offset and Mirror Error Included,	(T _J = 0°C to +70°C)	92	107	122	μA
$R_{SET} = 12.8 k\Omega$	$(T_J = -40^{\circ}C \text{ to } +100^{\circ}C, \text{ HRTZ}, \text{ IRTZ})$	90	125	124	μA

Electrical Specifications Recommended Operating Conditions, V_{CC} = 5V, Unless Otherwise specified. **Boldface limits apply across the operating temperature range. (Continued)**

PARAMETER	TEST CONDITIONS	MIN (Note 7)	ТҮР	MAX (Note 7)	UNITS
Peak Current Limit for Individual Channel	$(T_{J} = 0^{\circ}C \text{ to } +70^{\circ}C)$	118	125	133	μA
CS Offset and Mirror Error Included, R _{SET} = 12.8k Ω	(T _J = -40 °C to +100 °C, HRTZ, IRTZ)	116	125	134	μA
IMON OCP Trip Level		2.9	3.0	3.1	v
IMON VOLTAGE IMAX (FF) TRIP POINT	Higher than this will be "FF"	2.45	2.5	2.56	v
READ_IIN (1F) Maximum Threshold		-	10	-	μA
Input Peak Current Trip Level		13.9	15	16.5	μA
THERMAL MONITORING		k			
VR_HOT# Pull-down Impedance		-	9.2	13	Ω
TM Voltage at VR_HOT# Trip	TMAX = +100 °C (see Table 6), Programmable via Tmax	-	39.12	-	%VCC
VR_HOT# and Thermal Alert# Hysteresis		-	3	-	°C
Leakage Current of VR_HOT#	With external pull-up resistor connected to V_{CC}	-	-	1	μA
Over-Temperature Shutdown Threshold		0.91	0.94	0.97	v
Over-Temperature Shutdown Reset Threshold		1.04	1.07	1.11	v
VR READY AND PROTECTION MONITORS		1			
Leakage Current of VR_RDY	With pull-up resistor externally connected to V_{CC}	-	-	1	μA
VR READY Low Voltage	4mA Load	-	-	0.3	v
	Voltage below VID E1[3:0] = 0h)	65	105	146	mV
	Voltage below VID E1[3:0] = 1h)	93	141	191	mV
	Voltage below VID E1[3:0] = 2h)	121	178	236	m٧
Undervoltage Protection Threshold (UVP)	Voltage below VID E1[3:0] = 3h)	149	214	281	mV
Can Be Disabled by DFh	Voltage below VID E1[3:0] = 4h)	177	252	330	mV
	Voltage below VID E1[3:0] = 5h)	207	291	378	mV
	Voltage below VID E1[3:0] = 6h)	233	328	426	mV
	Voltage below VID E1[3:0] = 7h)	288	402	519	mV
	Voltage below VID E1[3:0] = 0h)	10	41	72	mV
	Voltage below VID E1[3:0] = 1h)	35	72	109	mV
	Voltage below VID E1[3:0] = 2h)	61	103	146	mV
Undervoltage Warning Threshold (UVP Warning)	Voltage below VID E1[3:0] = 3h)	84	135	186	mV
Can Be Disable by DFh	Voltage below VID E1[3:0] = 4h)	109	168	226	mV
	Voltage below VID E1[3:0] = 5h)	133	202	268	mV
	Voltage below VID E1[3:0] = 6h)	157	234	307	mV
	Voltage below VID E1[3:0] = 7h)	201	298	389	mV
Undervoltage Protection Reset Hysteresis	Higher than UVP	-	19	-	mV
					(

ISL6398

Electrical Specifications Recommended Operating Conditions, V_{CC} = 5V, Unless Otherwise specified. Boldface limits apply across the operating temperature range. (Continued)

PARAMETER	TEST CONDITIONS	MIN (Note 7)	ТҮР	MAX (Note 7)	UNITS
	Prior to the End of Soft-start (D8h[4:3] = 0h)	1.51	1.58	1.70	v
	Prior to the End of Soft-start (D8h[4:3] = 1h)	1.75	1.86	1.95	v
	Prior to the End of Soft-start (D8h[4:3] = 2h)	2.20	2.29	2.40	v
	Prior to the End of Soft-start (D8h[4:3] = 3h)	3.10	3.32	3.50	v
	End of Soft-start, the voltage above VID D8[2:0] = 0h)	91	135	177	mV
Overvoltage Protection Threshold (OVP)	End of Soft-start, the voltage above VID D8[2:0] = 1h)	125	177	225	mV
Can Be Disabled by DFh	End of Soft-start, the voltage above VID D8[2:0] = 2h)	158	218	274	mV
	End of Soft-start, the voltage above VID D8[2:0] = 3h)	191	260	323	mV
	End of Soft-start, the voltage above VID D8[2:0] = 4h)	254	342	424	mV
	End of Soft-start, the voltage above VID D8[2:0] = 5h)	318	425	526	mV
	End of Soft-start, the voltage above VID D8[2:0] = 6h)	347	460	580	mV
	End of Soft-start, the voltage above VID D8[2:0] = 7h)	395	549	697	mV
	Prior to the end of Soft-start, lower than OVP	55	110	180	mV
Overvoltage Protection Reset Hysteresis	During operation, lower than OVP	-	83	-	mV
	End of Soft-start, the voltage above VID D8[2:0] = 0h)	22	54	83	mV
	End of Soft-start, the voltage above VID D8[2:0] = 1h)	60	96	129	mV
	End of Soft-start, the voltage above VID D8[2:0] = 2h)	97	138	176	mV
Overvoltage Warning Threshold (OVP)	End of Soft-start, the voltage above VID D8[2:0] = 3h)	132	179	225	mV
Can Be Disabled by DFh	End of soft-start, the voltage above VID D8[2:0] = 4h)	205	264	324	mV
	End of soft-start, the voltage above VID D8[2:0] = 5h)	273	347	427	mV
	End of soft-start, the voltage above VID D8[2:0] = 6h)	308	389	476	mV
	End of soft-start, the voltage above VID D8[2:0] = 7h)	377	474	578	mV
Overvoltage Warning Reset Hysteresis	Lower than OVP Warning	-	42	-	mV
SMBus/PMBus/I ² C					
Signal Input Low Voltage		-	-	0.8	v
Signal Input High Voltage		2.1	-	vcc	v
Signal Output Low Voltage	4mA loading on Alert#	-	-	0.4	v
ALERT# Pull-down Impedance		-	28	50	Ω
DATA Pull-down Impedance		-	28	50	Ω
CLOCK Maximum Speed		1.5	-	-	MHz
CLOCK Minimum Speed		-	-	0.05	MHz
Time-out		25	30	35	ms
EEPROM		I		1	
Number of NVM_BANK		-	8	-	
NVM_BANK Loading Time	Including POR delay and Resistor Reading Time	-	16	20	ms

NOTES:

6. These parts are designed and adjusted for accuracy with all errors in the voltage loop included.

7. Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design.

Functional Pin Descriptions

Refer to Table 19 on page 53 for Design and Layout Considerations.

VCC - Supplies the power necessary to operate the chip. Connect this pin directly to a +5V supply with a high quality ceramic bypass capacitor. The controller start to operate, when the voltage on this pin exceeds the rising POR threshold and shuts down when the voltage on this pin drops below the falling POR threshold.

GND - The bottom metal base of ISL6398 is return of VCC supply. It is also the return of the PMBus as well as all PWM output drivers. Connect it to system ground; also externally connect pins 13, 14, and 15 to system GND.

ISENIN+, ISENIN- - These pins are current sense inputs to the differential amplifier of the input supply. The sensed current is used for input power monitoring and power management of the system. When not used, connect ISENIN+ to VIN and a resistor divider with a ratio of 1/3 on ISENIN± pin, say 499k Ω in between ISENIN± pins and then 1.5M Ω from ISENIN- to ground (see Figure 29). Refer to "Input Current Sensing" on page 30 for configuration details. Regardless input current sense is used or not, ISENIN+ should be connected to input voltage (V_{IN}) for feed-forward compensation to maintain a constant loop gain over the input line variation.

EN PWR CFP - This pin is a threshold-sensitive enable input and a catastrophic failure protection (CFP) output. Connecting the power train input supply to this through an appropriate resistor divider provides input undervoltage protection and a means to synchronize the power sequencing of the controller and the MOSFET driver ICs. When EN_PWR_CFP is driven above 0.85V but below 3.3V, the controller is actively depending on status of the TM_EN_OTP, the internal POR, and pending fault states. Driving EN_PWR_CFP below 0.75V or above 3.7V will turn off the controller, clear all fault states (except for CFP fault) and prepare the ISL6398 to soft-start when re-enabled. In addition, this pin will be latched high (VCC) by the input overcurrent (monitored by ISENIN±) or VR overvoltage event. The latch resets by cycling VCC and cannot reset by TM_EN_OTP or EN_PWR_CFP since when the catastrophic failure (CFP) is triggered, the input power is removed from VR so is the VTT voltage rail and it is PGOOD signal. To keep CFP active, VCC should be biased with a standby supply. This feature means to provide protection to the case that the VR with shorted high-side MOSFET draws insufficient current to trigger the input supply's over current trip level, this pin will send an active high signal (CFP) to disconnect the input supply before catching fire or further damage of PCB. Refer "Catastrophic Fault Protection" on page 30 for more details.

VSEN_OVP - This pin monitors the regulator output for overvoltage protection. Connect this pin to the positive rail remote sensing point of the microprocessor or load. This pin tracks with the VSEN pin. If a resistive divider is placed on the VSEN pin, a resistive divider with the same ratio should be placed on the VSEN_OVP pin to track UVP and OVP.

VSEN - This pin compensates the voltage drop between the load and local output rail for precision regulation. Connect this pin to the positive rail remote sensing point of the microprocessor or load. It also is the APA level sensing input. **RGND** - This pin compensates the offset between the remote ground of the load and the local ground of this device for precision regulation. Connect this pin to the negative rail remote sensing point of the microprocessor or load.

VR_RDY - VR_RDY indicates that soft-start has completed and the output remains in normal operation. It is an open-drain logic output. When OCP, UVP, OVP, or CFP occurs, VR_RDY is pulled low.

TM_EN_OTP - Input pin for the temperature measurement. Connect this pin through an NTC thermistor to GND and a resistor to VCC of the controller. The voltage at this pin is inversely proportional to the VR temperature. The device monitors the VR temperature based on the voltage at the TM pin. Combined with "TCOMP" setting, the sensed current is thermally compensated. The VR_HOT# asserts low if the sensed temperature at this pin is higher than the maximum desired temperature, "TMAX". The NTC should be placed close to the current sensing element, the output inductor or dedicated sense resistor on Phase 1. A decoupling capacitor (0.1µF) is typically needed in close proximity to the controller. In addition, the controller is disabled when this pin's voltage drops below 0.95 (typically) and is active when it is above 1.05V (typically); it can serve as Enable and Over-Temperature functions, however, when it is used as an Enable toggle input, bit2 of STATUS_BYTE (78h) will flag OT; CLEAR_FAULTS (03h) command must be sent to clear the fault after VR start-up. If not used, connect a $1M\Omega/2M\Omega$ resistor divider or tie to V_{CC}.

PWM[6:1] - Pulse width modulation outputs. Connect these pins to the PWM input pins of the Intersil driver IC(s). The number of active channels is determined by the state of PWM[6:2]. Tie PWM(N+1) to VCC to configure for N-phase operation. The PWM firing order is sequential from 1 to N with N being the number of active phases. If PWM1 is tied high, the VR is disabled.

ISEN[6:1]+, ISEN[6:1] - The ISEN+ and ISEN- pins are current sense inputs to individual differential amplifiers of VR. The sensed current is used for channel current balancing, overcurrent protection, and droop regulation. Inactive channels should have their respective current sense inputs, ISEN[6:#]- grounded, and ISEN[6:#]+ open. For example, ground ISEN[6:5]- and open ISEN[6:5]+ for 4-phase operation. DO NOT ground ISEN[6:1]+. For DCR sensing, connect each ISEN- pin to the node between the RC sense elements. Tie the ISEN+ pin to the other end of the sense capacitor (typically output rail). The voltage across the sense capacitor is proportional to the inductor current. Therefore, the sensed current is proportional to the inductor current and scaled by the DCR of the inductor and R_{SET}.

BUF_COMP - Buffered output of internal COMP.

VR_HOT# - Indicator of VR temperature reaching above TMAX set by PMBus E8[2:0]. It is an open-drain logic output. Normally open if the measured VR temperature is less than TMAX, and pulled low when the measured VR temperature exceeds TMAX.

RSET - A resistor connected from this pin to ground sets the current gain of the current sensing amplifier. The **RSET** resistor value can be set from $3.84k\Omega$ to $60.4k\Omega$ and is 64x of the equivalent R_{ISEN} resistor value. Therefore, the effective current sense resistor value can be set between 60Ω and 943Ω .

IMON - IMON is the output pin of sensed, thermally compensated (if internal thermal compensation is used) average current of VRO. The voltage at the IMON pin is proportional to the load current and the resistor value. When it reaches to 3.0V, it initiates an overcurrent shutdown, while 2.5V IMON voltage corresponds to READ_IOUT (8Ch) maximum reading. By choosing the proper value for the resistor at IMON pin, the overcurrent trip level can be set lower than the fixed internal overcurrent threshold. During dynamic VID, the OCP function of this pin is disabled to avoid false triggering. Tie it to GND if not used. Refer to "Current Sense Output" on page 25 for more details.

AUTO - A resistor from the pin to ground sets the current threshold of phase dropping for operation. The AUTO mode can be permanently disabled by pulling this pin to ground or PMBus D4h[2]. See Table 2 on page 17 and Table 8 on page 32 for more details.

SM_PM_I2CLK - Synchronous clock signal input of SMBus/PMBus/I²C.

SM_PM_I2DATA - I/O pin for transferring data signals SMBus/PMBus/I 2 C and VR controller.

SM_PMALERT# - Output pin for transferring the active low signal driven asynchronously from the VR controller to SMBus/PMBus.

VRSEL_ADDR - Register pin used to program VR address (PMBus) and to determine 5m/step or 10mV/step mode.

NVM_BANK_BT - Register pin to select NVM memory bank to use (up to 8 configuration banks) and boot voltage, which can be set by this pin or the value stored in NVM bank.

Operation

The ISL6398 is the smallest 6-Phase PWM controller. It utilizes Intersil's proprietary Advanced Linear EAPP (Enhanced Active Pulse Positioning) digital control scheme that can process voltage and current information in real time for fast control and high speed protection and realize digital power management capability and flexibility. It achieves the extremely fast linear transient response with fewer output capacitors and overcomes many hurdles of traditional digital approach, which uses non-linear, discrete control method for both voltage loop and current balance loop and runs into beat frequency oscillation and non-linear response. The ISL6398 is designed to cloud computing, networking, datacenter, and POL applications. The system parameters and required registers are programmable and can be stored into selected NVM_BANK via PMBus, no firmware required. It allows up to 8 memory banks, i.e., 8 different applications. This greatly simplifies the system design for various platforms and lowers inventory complexity and cost by using a single device.

In addition, this controller is compatible with phase doublers (ISL6611A and ISL6617), which can double or quadruple the phase count. For instance, the multi-phase PWM can realize up to 24-phase count system. A higher phase count system can improve thermal distribution and power conversion efficiency at heavy load.

The ISL6398 also supports coupled (2-Phase CI) inductor design. Refer to Intersil's application note, <u>AN1268</u> for detailed coupled inductor discussion.

Multiphase Power Conversion

High Power processor load current profiles have changed to the point that the advantages of multiphase power conversion are impossible to ignore. The technical challenges associated with producing a single-phase converter (which are both cost-effective and thermally viable), have forced a change to the cost-saving approach of multiphase. The ISL6398 controller helps reduce the complexity of implementation by integrating vital functions and requiring minimal output components. The typical application circuits diagrams on pages 6 through 9 provide the top level views of multiphase power conversion using the ISL6398 controller.

Interleaving

The switching of each channel in a multiphase converter is timed to be symmetrically out-of-phase with each of the other channels. In a 3-phase converter, each channel switches 1/3 cycle after the previous channel and 1/3 cycle before the following channel. As a result, the 3-phase converter has a combined ripple frequency three times greater than the ripple frequency of any one phase, as illustrated in Figure 1. The three channel currents (IL1, IL2 and IL3) combine to form the AC ripple current and the DC load current. The ripple component has three times the ripple frequency of each individual channel current. Each PWM pulse is terminated 1/3 of a cycle after the PWM pulse of the previous phase. The DC components of the inductor currents combine to feed the load.

To understand the reduction of ripple current amplitude in the multiphase circuit, examine Equation 1, which represents an individual channel's peak-to-peak inductor current.

$$I_{p-p} = \frac{(V_{IN} - V_{OUT}) \cdot V_{OUT}}{L \cdot F_{SW} \cdot V_{IN}}$$
(EQ. 1)

In Equation 1, V_{IN} and V_{OUT} are the input and output voltages respectively, L is the single-channel inductor value, and F_{SW} is the switching frequency.

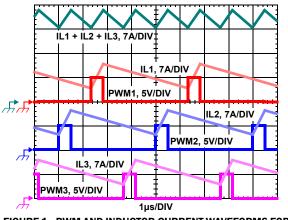


FIGURE 1. PWM AND INDUCTOR-CURRENT WAVEFORMS FOR 3-PHASE CONVERTER

In the case of multiphase converters, the capacitor current is the sum of the ripple currents from each of the individual channels. Compare Equation 1 to the expression for the peak-to-peak current after the summation of N symmetrically phase-shifted inductor currents in Equation 2, the peak-to-peak overall ripple current $I_{C(P-P)}$ decreases with the increase in the number of channels, as shown in Figure 2.

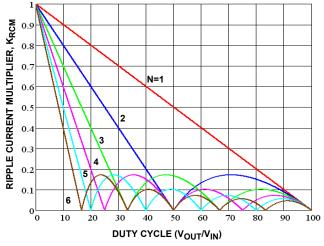


FIGURE 2. RIPPLE CURRENT MULTIPLIER VS. DUTY CYCLE

Output voltage ripple is a function of capacitance, capacitor Equivalent Series Resistance (ESR), and the summed inductor ripple current. Increased ripple frequency and lower ripple amplitude means that the designer can use less per-channel inductance and few or less costly output capacitors for any performance specification.

$$I_{c(p-p)} = \frac{V_{OUT}}{L \cdot F_{SW}} K_{RCM}$$
(EQ. 2)

$$K_{RCM} = \frac{(N \cdot D - m + 1) \cdot (m - (N \cdot D))}{N \cdot D}$$
for $m - 1 \le N \cdot D \le m$
 $m = ROUNDUP(N \cdot D, 0)$

Another benefit of interleaving is to reduce input ripple current. Input capacitance is determined in part by the maximum input ripple current. Multiphase topologies can improve overall system cost and size by lowering input ripple current and allowing the designer to reduce the cost of input capacitors. The example in Figure 3 illustrates input currents from a three-phase converter combining to reduce the total input ripple current.

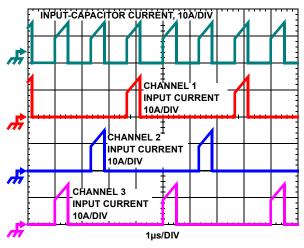


FIGURE 3. CHANNEL INPUT CURRENTS AND INPUT-CAPACITOR RMS CURRENT FOR 3-PHASE CONVERTER

The converter depicted in Figure 3 delivers 36A to a 1.5V load from a 12V input. The RMS input capacitor current is 5.9A. Compare this to a single-phase converter also stepping down 12V to 1.5V at 36A. The single-phase converter has 11.9A_{RMS} input capacitor current. The single-phase converter must use an input capacitor bank with twice the RMS current capacity as the equivalent three-phase converter.

Figures 37, 38 and 39, as described in "Input Capacitor Selection" on page 52, can be used to determine the input capacitor RMS current based on load current, duty cycle, and the number of channels. They are provided as aids in determining the optimal input capacitor solution. Figure 40 shows the single phase input-capacitor RMS current for comparison.

PWM Modulation Scheme

The ISL6398 adopts Intersil's proprietary Enhanced Active Pulse Positioning (EAPP) modulation scheme to improve transient performance. The EAPP is a unique dual-edge PWM modulation scheme with both PWM leading and trailing edges being independently moved to give the best response to transient loads. The EAPP has an inherited function, similar to Intersil's proprietary Adaptive Phase Alignment (APA) technique, to turn on all phases together to further improve the transient response, when there are sufficiently large load step currents. The EAPP is a variable frequency architecture, providing linear control over transient events and evenly distributing the pulses among all phases to achieve very good current balance and eliminate beat frequency oscillation over a wide range of load transient frequencies.

To further improve the line and load transient responses, the multi-phase PWM features feed-forward function to change the up ramp with the input line (voltage on ISENIN+ pin) to maintain a constant overall loop gain over a wide range input voltage. The up ramp of the internal sawtooth is defined in Equation 3.

$$V_{RAMP} = \frac{V_{IN} \cdot V_{RAMP_ADJ}}{12V}$$
(EQ. 3)

With EAPP control and feed-forward function, the ISL6398 can achieve excellent transient performance over wide frequency range of load step, resulting in lower demand on the output capacitors.

Under steady state conditions, the operation of the ISL6398 PWM modulator is similar to a conventional trailing edge modulator. Conventional analysis and design methods can therefore be used for steady state and small signal analysis.

PWM Operation

The timing of each channel is set by the number of active channels. The default channel setting for the ISL6398 is six. The switching cycle is defined as the time between PWM pulse termination signals of each channel. The cycle time of the pulse signal is the inverse of the switching frequency. The PWM signals command the MOSFET driver to turn on/off the channel MOSFETs.

The ISL6398 can work in a 0 to 6-Phase configuration. Tie PWM(N+1) to VCC to configure for N-phase operation. PWM firing order is sequential from 1 to N with N being the number of active phases, as summarized in Table 1. For 6-phase operation, the channel firing sequence is 1-2-3-4-5-6, and they are evenly spaced over 1/6 of a cycle. Connecting PWM6 to V_{CC} configures 5-phase operation, the channel firing order is 1-2-3-4-5 and the phase spacing is 1/5 of a cycle. If PWM2 is connected to V_{CC}, only Channel 1 operation is selected. If PWM1 is connected to V_{CC}, the VR operation is turned off.

TABLE 1. PHASE NUMBER AND PWM FIRING SEQUENCE

N	PHASE SEQUENCE	PWM# TIED TO V _{CC}	ACTIVE PHASE AT 0A LOAD
5	1-2-3-4-5	None	PWM1/3
4	1-2-3-4	PWM5	PWM1/3
3	1-2-3	PWM4	PWM1/2
2	1-2	PWM3	PWM1/2
1	1	PWM2	PWM1
0	OFF	PWM1	OFF

The controller starts phase shedding the next switching cycle. The controller reduces the number of active phases according to the logic state on Table 2. "NPSI" register and AUTO pin program the controller in operation of standard (SI), 2-phase coupled, or (N-x)-phase coupled inductors. Different cases yield different PWM output behaviors on both dropped phase(s) and operational phase(s) as load changes. When APA is triggered, it pulls the controller back to full phase operation to sustain an immediate heavy transient load. Note that "N-x" means N-x phase(s) coupled and x phase(s) are uncoupled.

For 2-Phase coupled inductor (CI) operation, both coupled phases should be 180° out-of-phase. In low power conditions, it drops to 2-phase and the opposite phase of the operational phase turns on its low-side MOSFET to circulate inductor current to minimize conduction loss when Phase 1 is high.

In low power condition, VR is in single-phase CCM operation with PWM1, or 2-phase CCM operation with PWM1 and 2, 3 or 4, as shown in Table 1. The number of operational phases is configured by "NPSI" register, shown in Table 2.

TABLE 2. PHASE DROPPING CONFIGURATION AT LOW POWER

NPSI D2[1:0]	CODE		AUTO MINIMUM PHASE COUNT
Oh	SI1	SI, (N-1)-CI	1-Phase
1h	SI2	SI, (N-2)-CI	2-Phase
2h	CI1	2-Phase CI	1-Phase
3h	CI2	2-Phase Cl	2-Phase

NOTE: For 2-Phase Cl option, the dropped coupled phase turns on LGATE to circulate current when PWM1 is high. Programmable via PMBus.

While the controller is operational (V_{CC} above POR, TM_EN_OTP and EN_PWR_CFP are both high, valid VID inputs), it can pull the PWM pins to ~40% of V_{CC} (~2V for 5V V_{CC} bias, for 5V PWM) or ~28% of V_{CC} (for 3.3V PWM) during various stages, such as soft-start delay, phase shedding operation, or fault conditions (OC or OV events). The matching driver's internal PWM resistor divider can further raise the PWM potential, but not lower it below the level set by the controller IC. Therefore, the controller's PWM outputs are designed to be compatible with DrMOS and Intersil drivers that require 3.3V and 5V PWM signal amplitudes, programmed by PMBus.

DrMOS and Driver Compatibility

In operational mode, the ISL6398 can actively drive PWM into tri-state level (mid level), which can be programmed to be compatible with 3.3V or 5V PWM input DrMOS or Drivers. The ISL6398's PWM "LOW" level is 0V and PWM "HIGH" level is V_{CC} (5V). The PWM "HIGH" minimum threshold of the DrMOS should be higher than 33% of V_{CC} for 3.3V PWM logic and 44% of V_{CC} for 5V PWM logic, while the PWM "LOW" maximum threshold of the DrMOS should be lower than 26% of V_{CC} for 3.3V PWM logic and 36% of V_{CC} for 5V PWM logic. Since most of industrial DrMOS devices are not compatible with Intersil's PWM protocol for diode emulation, therefore, the diode emulation mode should be disabled in both controller and DrMOS. Coupling with the ISL6627, zero current shutdown can be achieved, which minimizes the power stage stress.

Phase Doubler Compatibility

The ISL6398 is compatible with phase doublers (ISL6611A and ISL6617), which can double or quadruple the phase count. For instance, the multi-phase PWM can realize up to 24-phase count system. A higher phase count system can improve thermal distribution and power conversion efficiency at heavy load. Non-Intersil Phase doubler typically does not have current balance and is not compatible with Intersil's multi-phase controllers.

Precharged Start-up Capability

Since the ISL6398 uses 5V bias and the high efficiency power train mostly uses 5V driver, this makes the ISL6398 digital power system much more robust and reliable for power-up and down as well as precharged start-up, which is typically hardly managed for a system that deals with 3.3V, 5V, and 12V supplies.

Switching Frequency

The VR's switching frequency is programmable from 120kHz to 2.025MHz via PMBus. It is 15kHz/step with a slew rate of step/20 μ s.

Current Sensing

The ISL6398 senses current continuously for fast response. The ISL6398 supports inductor DCR sensing, or resistive sensing techniques. The associated channel current sense amplifier uses the ISEN inputs to reproduce a signal proportional to the inductor current, I_L . The sense current, I_{SEN} , is proportional to the inductor current. The sensed current is used for current balance, load-line regulation, and overcurrent protection.

The internal circuitry, shown in Figures 4 and 5, represents one channel of the VR output, respectively. The ISEN± circuitry is repeated for each channel, but may not be active depending on the status of the PWM[6:2] pins, as described in "PWM Operation" on page 17. The input bias current of the current sensing amplifier is typically 25nA; less than $8k\Omega$ input impedance is preferred to minimized the offset error, i.e., a larger C value as needed.

INDUCTOR DCR SENSING

An inductor's winding is characteristic of a distributed resistance, as measured by the Direct Current Resistance (DCR) parameter. Consider the inductor DCR as a separate lumped quantity, as shown in Figure 4. The channel current I_L, flowing through the inductor, will also pass through the DCR. Equation 4 shows the S-domain equivalent voltage across the inductor V_L. $V_{i}(s) = I_{i} \cdot (s \cdot L + DCR)$ (EQ. 4)

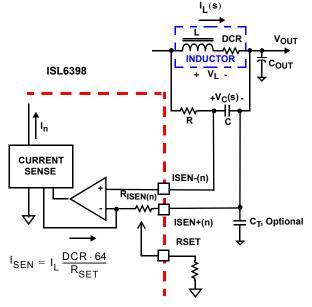


FIGURE 4. DCR SENSING CONFIGURATION

The voltage on the capacitor $V_{C},$ can be shown to be proportional to the channel current $I_{L}(\text{see Equation 5}).$

$$V_{C}(s) = \frac{\left(s \cdot \frac{L}{DCR} + 1\right) \cdot (DCR \cdot I_{L})}{(s \cdot RC + 1)}$$
(EQ. 5)

If the R-C network components are selected such that the RC time constant matches the inductor time constant (R*C = L/DCR), the

voltage across the capacitor $V_{\mbox{C}}$ is equal to the voltage drop across the DCR, i.e., proportional to the channel current.

With the internal low-offset current amplifier, the capacitor voltage V_C is replicated across the sense resistor R_{ISEN}. Therefore, the current out of the ISENS+ pin, I_{SEN}, is proportional to the inductor current.

Equation 6 shows that the ratio of the channel current to the sensed current, I_{SEN} , is driven by the value of the sense resistor and the DCR of the inductor.

$$I_{\text{SEN}} = I_{\text{L}} \cdot \frac{\text{DCR}}{\text{R}_{\text{ISEN}}} = I_{\text{L}} \frac{\text{DCR} \cdot 64}{\text{R}_{\text{SET}}}$$
(EQ. 6)

RESISTIVE SENSING

For more accurate current sensing, a dedicated current-sense resistor R_{SENSE} in series with each output inductor can serve as the current sense element (see Figure 5). This technique however reduces overall converter efficiency due to the additional power loss on the current sense element R_{SENSE} .

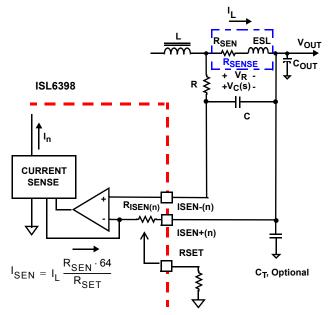


FIGURE 5. SENSE RESISTOR IN SERIES WITH INDUCTORS

A current sensing resistor has a distributed parasitic inductance, known as ESL (equivalent series inductance, typically less than 1nH) parameter. Consider the ESL as a separate lumped quantity, as shown in Figure 5. The channel current I_L , flowing through the inductor, will also pass through the ESL. Equation 7 shows the s-domain equivalent voltage across the resistor V_R .

$$V_{R}(s) = I_{L} \cdot (s \cdot ESL + R_{SEN})$$
(EQ. 7)

A simple R-C network across the current sense resistor extracts the R_{SEN} voltage, as shown in Figure 5.

The voltage on the capacitor $V_{C},$ can be shown to be proportional to the channel current I_{L} (see Equation 8).

$$V_{C}(s) = \frac{\left(s \cdot \frac{ESL}{R_{SEN}} + 1\right) \cdot (R_{SEN} \cdot I_{L})}{(s \cdot RC + 1)}$$
(EQ. 8)

If the R-C network components are selected such that the RC time constant matches the ESL-R_{SEN} time constant (R*C = ESL/R_{SEN}), the voltage across the capacitor V_C is equal to the voltage drop across the R_{SEN}, i.e., proportional to the channel current. As an example, a typical 1m Ω sense resistor can use R = 348 and C = 820pF for the matching. Figures 6 and 7 show the sensed waveforms with and without matching RC when using resistive sense.



FIGURE 6. VOLTAGE ACROSS R WITHOUT RC



FIGURE 7. VOLTAGE ACROSS C WITH MATCHING RC

Equation 9 shows that the ratio of the channel current to the sensed current, I_{SEN} , is driven by the value of the sense resistor and the R_{ISEN} .

$$I_{SEN} = I_{L} \cdot \frac{R_{SEN}}{R_{ISEN}} = I_{L} \frac{R_{SEN} \cdot 64}{R_{SET}}$$
(EQ. 9)

However, the R_{ISEN} resistor of each channel is integrated, while its value is determined by the R_{SET} resistor. The RSET resistor value can be from $3.84k\Omega$ to $60.4k\Omega$ and is 64x of the required I_{SEN} resistor value. Therefore, the current sense gain resistor (Integrated R_{ISEN}) value can be effectively set at 60Ω to 943Ω .

The inductor DCR value will increase as the temperature increases. Therefore, the sensed current will increase as the temperature of the current sense element increases. In order to compensate the temperature effect on the sensed current signal, a Negative Temperature Coefficient (NTC) resistor can be used for thermal compensation, or the integrated temperature compensation function of the ISL6398 should be utilized. The integrated temperature compensation function is described in "Temperature Compensation" on page 28.

Decoupling capacitor (C_T) on ISEN[6:1]- pins are optional and might be required for long sense traces and a poor layout.

L/DCR OR ESL/R_{SEN} MATCHING

Assuming the compensator design is correct, Figure 8 shows the expected load transient response waveforms if L/DCR or ESL/R_{SEN} is matching the R-C time constant. When the load current I_{OUT} has a square change, the output voltage V_{OUT} also has a square response, except for the overshoot at load release. However, there is always some PCB contact impedance of current sensing components between the two current sensing points; it hardly accounts into the L/DCR or ESL/R_{SEN} matching calculation. Fine tuning the matching is necessarily done in the board level to improve overall transient performance and system reliability.

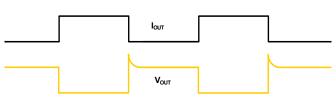


FIGURE 8. DESIRED LOAD TRANSIENT RESPONSE WAVEFORMS

If the R-C timing constant is too large or too small, V_C(s) will not accurately represent real-time I_{OUT}(s) and will worsen the transient response. Figure 9 shows the load transient response when the R-C timing constant is too small. V_{OUT} will sag excessively upon load insertion and may create a system failure or early overcurrent trip. Figure 10 shows the transient response when the R-C timing constant is too large. V_{OUT} is sluggish in drooping to its final value. There will be excessive overshoot if load insertion occurs during this time, which may potentially hurt the reliability.

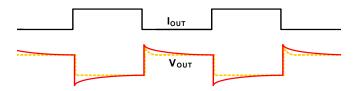


FIGURE 9. LOAD TRANSIENT RESPONSE WHEN R-C TIME CONSTANT IS TOO SMALL

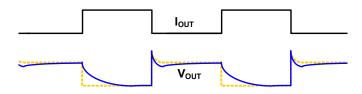


FIGURE 10. LOAD TRANSIENT RESPONSE WHEN R-C TIME CONSTANT IS TOO LARGE

\mathbf{R}_{SET} and L/DCR matching for coupled inductor

The current sense circuitry operates in a very similar manner for negative current feedback, where inductor current is flowing from the output of the regulator to the PHASE node, opposite of flow pictured in Figures 4 and 5. However, the range of proper operation with negative current sensing has a limitation. The worst-case peak-to-peak inductor ripple current should be kept less than 80% of the OCP trip point (~80µA). Care should be taken to avoid operation with negative current feedback exceeding this threshold, as this may lead to momentary loss of current balance between phases and disruption of normal circuit operation. Note that the negative current can especially affect coupled inductor designs, where the effective inductance is the leakage between the two channels, much lower than the specified mutual inductance (LM) and self inductance (L). To limit the impact, a higher RSET value (1.5x to 2x) is often used to reduce the effective negative current seen by the controller in coupled inductor designs.

Refer to Intersil's application note, <u>AN1268</u> for detailed coupled inductor discussion and ripple current calculation.

As explained in application note, <u>AN1268</u> the leakage inductance (not self inductance or mutual inductance) of the coupled inductor should be used as the inductance in the time constant calculation. Therefore, the leakage, self, and mutual inductance should be well controlled for a good coupled inductor design.

Channel-current Balance

The sensed current ${\rm I}_{\rm n}$ from each active channel is summed together and divided by the number of active channels. The resulting average current ${\rm I}_{\rm AVG}$ provides a measure of the total load current. Channel current balance is achieved by comparing the sensed current of each channel to the average current to make an appropriate adjustment to the PWM duty cycle of each channel with Intersil's patented current-balance method.

Channel current balance is essential in achieving the thermal advantage of multiphase operation. With good current balance, the power loss is equally dissipated over multiple devices and a greater area. The ISL6398 can adjust the thermal/current balance of the VR via registers F7 to FC.

Voltage Regulation (5mV and 10mV Mode)

The compensation network shown in Figure 11 assures that the steady-state error in the output voltage is limited only to the error in the reference voltage (DAC and OFFSET) and droop current source, remote sense, and error amplifier.

The sensed average current I_{DROOP} is tied to FB internally and will develop a voltage drop across the resistor between FB and V_{OUT} for droop control. This current can be disconnected from the FB node via PMBus for non-droop applications.

The output of the error amplifier, V_{COMP}, is compared to the internal sawtooth waveforms to generate the PWM signals. The PWM signals control the timing of the Intersil MOSFET drivers and regulate the converter output to the specified reference voltage.

For remote sensing, connect the load sensing pins to the non-inverting input, VSEN, and inverting input, RGND, of the error amplifier. This configuration effectively removes the voltage error encountered when measuring the output voltage relative to the local controller ground reference point.

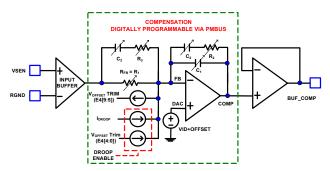


FIGURE 11. OUTPUT VOLTAGE AND LOAD-LINE REGULATION

A digital-to-analog converter (DAC) generates a reference voltage, which is programmable via PMBus bus. The DAC decodes the PMBus set VID command into one of the discrete voltages shown in Table 4. In addition, the output voltage can be margined in \pm 5mV step between -640mV and 635mV, \pm 10mV step between -1280mV and 1270mV, as shown in Table 4. For a finer than 5mV or 10mV offset, a large ratio resistor divider can be placed on the VSEN pin between the output and GND for positive offset or V_{CC} for negative offset, as in Figure 12. The VR operational mode is programmed by the "VRSEL_ADDR" pin. Table 3 shows the difference between 5mV and 10mV modes. VOUT_MAX and VBOOT registers must be programmed accordingly to support each mode, otherwise, the VR might NOT power-up correctly.

Furthermore, the PMBus register (E4h[9:5]) can program the additional droop current (range from -4μ A to 3.75μ A) into R₁ for DC offset calibration; a negative current will yield a negative offset, while a positive current will yield a positive offset: OFFSET = R₁* I(E4[9:5]). In droop applications, E4[4:0] can add current out of IMON pin and droop current through R₁ simultaneously (the negative current yields positive offset, and vice versa).

TABLE 3.	5mV vs	3 10mV	DAC I	Resolution

MODE (VRSEL)	MAXIMUM DAC (V)	VOUT_MAX (24h)	MAXIMUM VBOOT ("BT" pin)	MAXIMUM VBOOT (E6)
5mV	2.155	Table 18	1.50	1.52
10mV	3.011	Table 4 Follow DAC	3.00	3.04

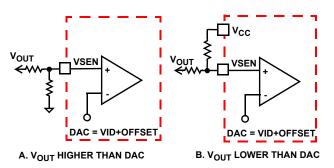


FIGURE 12. EXTERNAL PROGRAMMABLE REGULATION

TABLE 4. 5mV OR 10mV VID 8-BIT

BINARY CODE	HEX CODE	5mV VID (V)	10mV VID (V)	5mV OFFSET (mV)	10mV OFFSET (mV)
00000000	0	OFF	OFF	0	0
0000001	1	0.250	0.500	5	10
00000010	2	0.255	0.510	10	20
00000011	3	0.260	0.520	15	30
00000100	4	0.265	0.530	20	40
00000101	5	0.270	0.540	25	50
00000110	6	0.275	0.550	30	60
00000111	7	0.280	0.560	35	70
00001000	8	0.285	0.570	40	80
00001001	9	0.290	0.580	45	90
00001010	Α	0.295	0.590	50	100
00001011	В	0.300	0.600	55	110
00001100	С	0.305	0.610	60	120
00001101	D	0.310	0.620	65	130

TABLE 4. 5mV OR 10mV VID 8-BIT (Continued)

17					
BINARY CODE	HEX CODE	5mV VID (V)	10mV VID (V)	5mV OFFSET (mV)	10mV OFFSET (mV)
00001110	Е	0.315	0.630	70	140
00001111	F	0.320	0.640	75	150
00010000	10	0.325	0.650	80	160
00010001	11	0.330	0.660	85	170
00010010	12	0.335	0.670	90	180
00010011	13	0.340	0.680	95	190
00010100	14	0.345	0.690	100	200
00010101	15	0.350	0.700	105	210
00010110	16	0.355	0.710	110	220
00010111	17	0.360	0.720	115	230
00011000	18	0.365	0.730	120	240
00011001	19	0.370	0.740	125	250
00011010	1A	0.375	0.750	130	260
00011011	1B	0.380	0.760	135	270
00011100	1C	0.385	0.770	140	280
00011101	1D	0.390	0.780	145	290
00011110	1E	0.395	0.790	150	300
00011111	1F	0.400	0.800	155	310
00100000	20	0.405	0.810	160	320
00100001	21	0.410	0.820	165	330
00100010	22	0.415	0.830	170	340
00100011	23	0.420	0.840	175	350
00100100	24	0.425	0.850	180	360
00100101	25	0.430	0.860	185	370
00100110	26	0.435	0.870	190	380
00100111	27	0.440	0.880	195	390
00101000	28	0.445	0.890	200	400
00101001	29	0.450	0.900	205	410
00101010	2A	0.455	0.910	210	420
00101011	2B	0.460	0.920	215	430
00101100	2C	0.465	0.930	220	440
00101101	2D	0.470	0.940	225	450
00101110	2E	0.475	0.950	230	460
00101111	2F	0.480	0.960	235	470
00110000	30	0.485	0.970	240	480
00110001	31	0.490	0.980	245	490
00110010	32	0.495	0.990	250	500
00110011	33	0.500	1.000	255	510
00110100	34	0.505	1.010	260	520
00110101	35	0.510	1.020	265	530
00110110	36	0.515	1.030	270	540
00110111	37	0.520	1.040	275	550
00111000	38	0.525	1.050	280	560
00111001	39	0.530	1.060	285	570
00111010	ЗA	0.535	1.070	290	580

17	IDLE 4.	SHIV OR I			•)
BINARY CODE	HEX CODE	5mV VID (V)	10mV VID (V)	5mV OFFSET (mV)	10mV OFFSET (mV)
00111011	3B	0.540	1.080	295	590
00111100	3C	0.545	1.090	300	600
00111101	3D	0.550	1.100	305	610
00111110	3E	0.555	1.110	310	620
00111111	ЗF	0.560	1.120	315	630
01000000	40	0.565	1.130	320	640
01000001	41	0.570	1.140	325	650
01000010	42	0.575	1.150	330	660
01000011	43	0.580	1.160	335	670
01000100	44	0.585	1.170	340	680
01000101	45	0.590	1.180	345	690
01000110	46	0.595	1.190	350	700
01000111	47	0.600	1.200	355	710
01001000	48	0.605	1.210	360	720
01001001	49	0.610	1.220	365	730
01001010	4A	0.615	1.230	370	740
01001011	4B	0.620	1.240	375	750
01001100	4C	0.625	1.250	380	760
01001101	4D	0.630	1.260	385	770
01001110	4E	0.635	1.270	390	780
01001111	4F	0.640	1.280	395	790
01010000	50	0.645	1.290	400	800
01010001	51	0.650	1.300	405	810
01010010	52	0.655	1.310	410	820
01010011	53	0.660	1.320	415	830
01010100	54	0.665	1.330	420	840
01010101	55	0.670	1.340	425	850
01010110	56	0.675	1.350	430	860
01010111	57	0.680	1.360	435	870
01011000	58	0.685	1.370	440	880
01011001	59	0.690	1.380	445	890
01011010	5A	0.695	1.390	450	900
01011011	5B	0.700	1.400	455	910
01011100	5C	0.705	1.410	460	920
01011101	5D	0.710	1.420	465	930
01011110	5E	0.715	1.430	470	940
01011111	5F	0.720	1.440	475	950
01100000	60	0.725	1.450	480	960
01100001	61	0.730	1.460	485	970
01100010	62	0.735	1.470	490	980
01100011	63	0.740	1.480	495	990
01100100	64	0.745	1.490	500	1000
01100101	65	0.750	1.500	505	1010
01100101	66	0.755	1.510	510	1010
01100110	67	0.760	1.520	515	1020
OTTOOTIT	0/	0.760	1.520	919	1020

TABLE 4. 5mV OR 10mV VID 8-BIT (Continued)

21

TABLE 4. 5mV OR 10mV VID 8-BIT (Continued)

					-,
BINARY CODE	HEX CODE	5mV VID (V)	10mV VID (V)	5mV OFFSET (mV)	10mV OFFSET (mV)
01101000	68	0.765	1.530	520	1040
01101001	69	0.770	1.540	525	1050
01101010	6A	0.775	1.550	530	1060
01101011	6B	0.780	1.560	535	1070
01101100	6C	0.785	1.570	540	1080
01101101	6D	0.790	1.580	545	1090
01101110	6E	0.795	1.590	550	1100
01101111	6F	0.800	1.600	555	1110
01110000	70	0.805	1.610	560	1120
01110001	71	0.810	1.620	565	1130
01110010	72	0.815	1.630	570	1140
01110011	73	0.820	1.640	575	1150
01110100	74	0.825	1.650	580	1160
01110101	75	0.830	1.660	585	1170
01110110	76	0.835	1.670	590	1180
01110111	77	0.840	1.680	595	1190
01111000	78	0.845	1.690	600	1200
01111001	79	0.850	1.700	605	1210
01111010	7A	0.855	1.710	610	1220
01111011	7B	0.860	1.720	615	1230
01111100	7C	0.865	1.730	620	1240
01111101	7D	0.870	1.740	625	1250
01111110	7E	0.875	1.750	630	1260
01111111	7F	0.880	1.760	635	1270
10000000	80	0.885	1.770	-640	-1280
10000001	81	0.890	1.780	-635	-1270
10000010	82	0.895	1.790	-630	-1260
10000011	83	0.900	1.800	-625	-1250
10000100	84	0.905	1.810	-620	-1240
10000101	85	0.910	1.820	-615	-1230
10000110	86	0.915	1.830	-610	-1220
10000111	87	0.920	1.840	-605	-1210
10001000	88	0.925	1.850	-600	-1200
10001001	89	0.930	1.860	-595	-1190
10001010	8A	0.935	1.870	-590	-1180
10001011	8B	0.940	1.880	-585	-1170
10001100	8C	0.945	1.890	-580	-1160
10001101	8D	0.950	1.900	-575	-1150
10001110	8E	0.955	1.910	-570	-1140
10001111	8F	0.960	1.920	-565	-1130
10010000	90	0.965	1.930	-560	-1120
10010001	91	0.970	1.940	-555	-1110
10010010	92	0.975	1.950	-550	-1100
10010011	93	0.980	1.960	-545	-1090
10010100	94	0.985	1.970	-540	-1080
	I	L	1	I	

BINARY CODESINVJUNVYUJUNVSinVJUNV1001010950.9901.980-535-10701001011971.0002.000-525-10501001100981.0052.010-520-10401001101991.0102.020-515-10301001100941.0152.030-510-10201001101991.0202.040-505-10101001101901.0352.070-490-98010011110901.0352.0704490-98010011110911.0352.0704490-98010011111971.0402.080-485-9701010000A01.0452.090-485-97010100001A11.0502.100-477-9401010001A21.0552.110-470-9401010001A21.0552.130-465-9301010001A41.0652.130-455-9101010010A41.0652.130-455-9101010010A41.0852.190-430-8601010010A41.0952.190-430-8601010101A41.0952.190-430-8601010101A41.1052.200-425-8701010101A41.1102.200-435-7701010101A5 <t< th=""><th></th><th></th><th></th><th></th><th></th><th></th></t<>						
10010110 96 0.995 1.990 -530 -1.060 10011100 98 1.005 2.010 -522 .1040 10011001 99 1.010 2.020 -515 .1030 10011010 9A 1.015 2.030 -510 .1020 1001101 9B 1.022 2.040 -505 .1010 1001110 9C 1.025 2.050 .500 .1000 1001110 9C 1.035 2.070 .490 .980 1001111 9F 1.040 2.080 .485 .970 1010000 A0 1.045 2.090 .480 .960 10100001 A1 1.050 2.100 .477 .940 10100001 A2 1.055 2.110 .470 .940 10100010 A4 1.065 2.130 .460 .920 10100101 A5 1.070 2.140 .455 .910 101001	BINARY CODE	HEX CODE	5mV VID (V)	10mV VID (V)	5mV OFFSET (mV)	10mV OFFSET (mV)
10010111 97 1.000 2.000 -525 .1050 10011000 98 1.005 2.010 -5200 .1040 10011010 94 1.015 2.030 -510 .1020 10011010 9A 1.025 2.050 .500 .1000 1001110 9E 1.035 2.070 .490 .980 1001111 9F 1.040 2.080 .485 .970 1010000 A0 1.045 2.090 .480 .960 10100001 A1 1.050 2.100 .477 .940 1010001 A2 1.055 2.110 .470 .940 10100010 A4 1.065 2.130 .460 .920 10100101 A5 1.070 2.140 .455 .910 10100101 A5 1.070 2.140 .455 .910 1010101 A6 1.075 2.150 .440 .880 10101010	10010101	95	0.990	1.980	-535	-1070
10011000981.0052.010.520.104010011010941.0152.030.510.102010011011981.0202.040.505.1010100111009C1.0252.050.500.1000100111019D1.0302.060.495.990100111109E1.0352.070.490.980100111119F1.0402.080.485.9701010000A01.0452.090.480.9601010001A11.0502.100.477.95010100001A21.0552.110.470.9401010001A21.0552.110.470.9401010001A41.0652.130.460.9201010010A41.0652.130.460.9201010011A51.0702.140.455.9101010010A61.0752.150.450.9001010011A61.0752.150.445.8901010101A81.0902.180.435.8701010101A41.0952.190.440.8801010101A81.1002.200.425.8501010101A81.1002.200.425.8501010101A61.1552.300.410.8201010101A81.1022.20.415.8301010101A51.102 <t< td=""><td>10010110</td><td>96</td><td>0.995</td><td>1.990</td><td>-530</td><td>-1060</td></t<>	10010110	96	0.995	1.990	-530	-1060
10011001 99 1.010 2.020 .515 .1030 1001101 98 1.020 2.040 .505 .1010 1001101 90 1.025 2.050 .500 .1000 10011101 90 1.030 2.060 .495 .990 10011111 9E 1.035 2.070 .490 .980 10011111 9E 1.040 2.080 .485 .970 10100000 A0 1.045 2.090 .480 .960 10100001 A1 1.050 2.100 .475 .950 10100001 A2 1.055 2.110 .470 .940 10100001 A2 1.055 2.130 .460 .920 10100011 A3 1.060 2.120 .4455 .910 10100101 A6 1.075 2.150 .450 .870 1010101 A6 1.075 2.150 .4405 .880 101010	10010111	97	1.000	2.000	-525	-1050
10011010 9A 1.015 2.030 .510 .1020 1001101 9B 1.020 2.040 .505 .1010 10011101 9D 1.030 2.060 .495 .990 10011101 9E 1.035 2.070 .490 .980 10011111 9F 1.040 2.080 .485 .970 1010000 A0 1.045 2.090 .480 .960 10100001 A1 1.050 2.100 .475 .950 10100001 A2 1.055 2.110 .470 .940 1010001 A2 1.055 2.130 .460 .920 10100101 A5 1.070 2.140 .455 .910 10100101 A6 1.075 2.150 .440 .880 10101011 A7 1.080 2.160 .4415 .890 10101010 A4 1.095 2.190 .430 .860 10101010	10011000	98	1.005	2.010	-520	-1040
10011011 9B 1.020 2.040 .505 .1010 10011100 9C 1.025 2.050 .500 .1000 10011101 9D 1.030 2.060 .495 .990 10011110 9E 1.035 2.070 .490 .980 10011111 9F 1.040 2.080 .485 .970 10100000 A0 1.045 2.090 .480 .960 10100001 A1 1.050 2.100 .475 .950 10100011 A3 1.060 2.120 .465 .930 10100101 A5 1.070 2.140 .455 .910 10100101 A5 1.070 2.140 .450 .900 1010101 A6 1.075 2.150 .440 .880 1010101 A6 1.055 2.170 .440 .880 1010101 A8 1.100 2.200 .415 .830 10101010<	10011001	99	1.010	2.020	-515	-1030
10011100 9C 1.025 2.050 .500 .1000 10011101 9D 1.030 2.060 .495 .990 10011110 9E 1.035 2.070 .490 .980 10011111 9F 1.040 2.080 .485 .970 10100000 A0 1.045 2.090 .480 .960 10100001 A1 1.050 2.110 .477 .950 1010001 A2 1.055 2.110 .470 .940 1010001 A2 1.055 2.130 .460 .920 1010010 A4 1.065 2.130 .460 .920 1010010 A4 1.065 2.150 .450 .900 1010011 A7 1.080 2.160 .445 .890 1010101 A8 1.085 2.170 .440 .880 1010101 AB 1.100 2.200 .415 .830 10101010	10011010	9A	1.015	2.030	-510	-1020
10011101 9D 1.030 2.060 -495 -990 10011110 9E 1.035 2.070 -490 -980 10010000 A0 1.045 2.090 -485 -970 10100001 A1 1.050 2.100 -475 -950 10100010 A2 1.055 2.110 -470 -940 10100011 A3 1.060 2.120 -465 -930 10100010 A4 1.065 2.130 -460 -920 10100101 A5 1.070 2.140 -455 -910 10100101 A6 1.075 2.150 -450 -900 10100111 A7 1.080 2.160 -445 -890 1010101 A8 1.095 2.190 -440 -880 1010101 A 1.095 2.190 -430 -860 1010101 A 1.095 2.190 -440 -820 10101010	10011011	9B	1.020	2.040	-505	-1010
10011110 9E 1.035 2.070 -490 -980 10011111 9F 1.040 2.080 -485 970 10100000 A0 1.045 2.090 -480 -960 10100001 A1 1.050 2.100 -475 -950 1010001 A2 1.055 2.110 -470 -940 1010001 A2 1.055 2.110 -465 -930 1010001 A4 1.065 2.130 -460 -920 1010010 A4 1.065 2.130 -450 -900 1010011 A5 1.070 2.140 -455 -910 10100101 A6 1.075 2.150 -440 -880 1010101 A6 1.055 2.190 -433 -860 1010101 A4 1.095 2.190 -440 -840 1010101 AC 1.105 2.210 -415 -830 10101011	10011100	9C	1.025	2.050	-500	-1000
10011111 9F 1.040 2.080 -485 9-70 10100000 A0 1.045 2.090 -480 9-60 10100001 A1 1.050 2.100 -475 9-950 10100010 A2 1.055 2.110 -470 9-400 10100011 A3 1.060 2.120 -465 9-330 10100101 A4 1.065 2.130 -460 9-20 10100101 A5 1.070 2.140 -455 9-910 10100111 A7 1.080 2.160 -445 -890 10100101 A6 1.075 2.150 -440 -880 1010101 A8 1.085 2.170 -440 -880 1010100 A4 1.095 2.190 -430 -860 1010101 A4 1.095 2.190 -440 -820 1010101 AC 1.105 2.200 -415 -830 10101010	10011101	9D	1.030	2.060	-495	-990
10100000 A0 1.045 2.090 -480 -960 10100010 A1 1.050 2.100 -475 -950 10100010 A2 1.055 2.110 -470 -940 10100011 A3 1.060 2.120 -465 -930 10100101 A4 1.065 2.130 -460 -920 10100101 A5 1.070 2.140 -455 -910 10100101 A6 1.075 2.150 -450 -900 10100101 A6 1.075 2.150 -440 -880 10101001 A8 1.085 2.170 -440 -880 10101001 A4 1.095 2.190 -433 -860 1010101 AA 1.095 2.210 -420 -840 1010101 AC 1.105 2.210 -440 -830 1010101 AC 1.115 2.230 -410 -800 10110101 <td>10011110</td> <td>9E</td> <td>1.035</td> <td>2.070</td> <td>-490</td> <td>-980</td>	10011110	9E	1.035	2.070	-490	-980
10100001 A1 1.050 2.100 -475 -950 10100010 A2 1.055 2.110 -470 -940 10100011 A3 1.060 2.120 -465 -930 10100100 A4 1.065 2.130 -460 -920 10100101 A5 1.070 2.140 -455 -910 10100101 A6 1.075 2.150 -450 -900 10100101 A6 1.075 2.150 -440 -880 10101001 A8 1.085 2.170 -440 -880 10101001 A9 1.090 2.180 -435 -870 10101001 AA 1.095 2.190 -430 -860 10101011 AB 1.100 2.200 -415 -830 10101010 AC 1.115 2.230 -410 -820 10110101 AF 1.120 2.240 -405 -810 10110001	10011111	9F	1.040	2.080	-485	-970
10100010 A2 1.055 2.110 -470 -940 10100011 A3 1.060 2.120 -465 -930 10100100 A4 1.065 2.130 -460 -920 10100101 A5 1.070 2.140 -455 -910 10100110 A6 1.075 2.150 -450 -900 10100101 A6 1.075 2.150 -440 -880 10101011 A7 1.080 2.160 -445 -890 10101001 A9 1.090 2.180 -435 -870 10101001 A9 1.090 2.180 -430 -860 1010101 AB 1.100 2.200 -425 -850 1010101 AC 1.115 2.230 -410 -820 10101101 AF 1.120 2.240 -405 -810 10110101 B1 1.130 2.260 -385 -770 10110010 </td <td>10100000</td> <td>A0</td> <td>1.045</td> <td>2.090</td> <td>-480</td> <td>-960</td>	10100000	A0	1.045	2.090	-480	-960
10100011 A3 1.060 2.120 .465 .930 10100100 A4 1.065 2.130 .460 .920 10100101 A5 1.070 2.140 .455 .910 10100110 A6 1.075 2.150 .450 .900 10100111 A7 1.080 2.160 .445 .890 10101000 A8 1.085 2.170 .440 .880 10101001 A9 1.090 2.180 .435 .870 10101001 AA 1.095 2.190 .430 .860 10101010 AC 1.105 2.210 .425 .850 10101101 AD 1.110 2.220 .415 .830 10101101 AE 1.115 2.230 .410 .820 10101101 AF 1.120 2.240 .405 .810 10110101 B1 1.130 2.260 .385 .770 10110010	10100001	A1	1.050	2.100	-475	-950
10100100 A4 1.065 2.130 -460 -920 10100101 A5 1.070 2.140 455 -910 10100110 A6 1.075 2.150 450 -900 10100111 A7 1.080 2.160 -445 -890 10101000 A8 1.085 2.170 -440 -880 10101001 A9 1.090 2.180 -435 -870 1010101 A9 1.095 2.190 -430 -860 1010101 AA 1.095 2.190 -425 -850 1010101 AC 1.105 2.200 -425 -850 10101101 AC 1.105 2.210 -405 -810 10101101 AC 1.115 2.230 -410 -820 10101111 AF 1.120 2.240 405 -810 1011000 B0 1.125 2.250 -400 -800 10110001	10100010	A2	1.055	2.110	-470	-940
10100101 A5 1.070 2.140 -455 -910 10100110 A6 1.075 2.150 -450 -900 10100111 A7 1.080 2.160 -445 -890 1010100 A8 1.085 2.170 -440 -880 1010100 A9 1.090 2.180 -435 -870 1010101 A9 1.090 2.180 -430 -860 1010101 AA 1.095 2.190 -430 -860 1010101 AA 1.095 2.210 -420 -840 1010101 AC 1.105 2.220 -415 -830 10101101 AD 1.110 2.220 -410 -820 10101111 AF 1.120 2.240 -405 -810 1011000 B0 1.125 2.250 -400 -800 1011001 B2 1.135 2.270 -380 -760 10110010	10100011	A3	1.060	2.120	-465	-930
10100110 A6 1.075 2.150 -450 -900 10100111 A7 1.080 2.160 445 890 1010100 A8 1.085 2.170 -440 -880 1010100 A9 1.090 2.180 -435 -870 1010101 A9 1.095 2.190 430 -860 1010101 AA 1.095 2.210 -420 -840 1010101 AB 1.105 2.210 -420 -840 1010110 AC 1.105 2.210 -415 -830 1010110 AE 1.115 2.230 410 -820 1010111 AF 1.120 2.240 -405 -810 1011000 B0 1.125 2.250 -400 -800 10110010 B1 1.130 2.260 -395 -790 10110010 B2 1.135 2.270 -380 -760 1011001	10100100	A4	1.065	2.130	-460	-920
10100111 A7 1.080 2.160 -445 -890 10101000 A8 1.085 2.170 -440 -880 10101001 A9 1.090 2.180 -435 -870 1010101 AA 1.095 2.190 -430 -860 1010101 AA 1.095 2.190 -420 -840 1010110 AC 1.105 2.210 -420 -840 10101101 AD 1.110 2.220 -415 -830 10101101 AE 1.115 2.230 -410 -820 10101111 AF 1.120 2.240 -405 -810 10101011 AF 1.120 2.240 -405 -810 10110000 B0 1.125 2.250 -400 -800 10110001 B1 1.130 2.260 -385 -770 10110010 B4 1.145 2.290 -380 -760 10110101 <td>10100101</td> <td>A5</td> <td>1.070</td> <td>2.140</td> <td>-455</td> <td>-910</td>	10100101	A5	1.070	2.140	-455	-910
10101000 A8 1.085 2.170 -440 -880 10101001 A9 1.090 2.180 -435 -870 10101010 AA 1.095 2.190 -430 -860 1010101 AB 1.100 2.200 -425 -850 1010110 AC 1.105 2.210 -420 -840 10101101 AD 1.110 2.220 -415 -830 10101101 AE 1.115 2.230 -410 -820 10101111 AF 1.120 2.240 -405 -810 1010011 BI 1.130 2.260 -395 -790 1011000 B0 1.125 2.250 -400 -800 1011001 B1 1.130 2.260 -385 -770 1011001 B2 1.135 2.270 -380 -760 1011001 B3 1.140 2.800 -375 -750 10110101	10100110	A6	1.075	2.150	-450	-900
10101001 A9 1.090 2.180 -435 -870 10101010 AA 1.095 2.190 -430 -860 10101011 AB 1.100 2.200 -425 -850 10101100 AC 1.105 2.210 -420 -840 10101101 AD 1.110 2.220 -415 -830 10101101 AE 1.115 2.230 -410 -820 10101111 AF 1.120 2.240 -405 -810 10101000 B0 1.125 2.250 -400 -800 10110001 B1 1.130 2.260 -395 -790 10110001 B2 1.135 2.270 -390 -780 10110010 B2 1.145 2.290 -380 -760 10110101 B5 1.150 2.300 -375 -750 10110101 B6 1.155 2.310 -360 -720 10110101	10100111	Α7	1.080	2.160	-445	-890
10101010 AA 1.095 2.190 -430 -860 10101011 AB 1.100 2.200 -425 -850 10101100 AC 1.105 2.210 -420 -840 10101101 AD 1.110 2.220 -415 -830 10101110 AE 1.115 2.230 -410 -820 10101111 AF 1.120 2.240 -405 -810 10101000 B0 1.125 2.250 -400 -800 10110000 B0 1.125 2.260 -395 -790 10110001 B1 1.130 2.260 -395 -790 10110010 B2 1.135 2.270 -390 -780 10110010 B2 1.145 2.290 -380 -760 10110101 B5 1.150 2.300 -375 -750 10110101 B6 1.155 2.310 -360 -720 10111010	10101000	A8	1.085	2.170	-440	-880
10101011AB1.1002.200-425-85010101100AC1.1052.210-420-84010101101AD1.1102.220-415-83010101111AE1.1152.230-410-82010101111AF1.1202.240-405-8101010000B01.1252.250-400-80010110001B11.1302.260-395-79010110010B21.1352.270-390-78010110010B21.1452.290-385-77010110010B41.1452.290-380-7601011010B41.1552.310-370-7401011011B51.1602.320-365-7301011010B61.1552.310-360-7201011010B41.1752.350-350-7001011101B91.1702.340-355-7101011101BA1.1752.350-340-6801011101BA1.1902.380-335-6701011101BD1.1902.380-335-67010111101BE1.1952.390-330-66010111111BF1.2002.400-325-65011000000C01.2052.410-320-640	10101001	A9	1.090	2.180	-435	-870
10101100AC1.1052.210-420-84010101101AD1.1102.220-415-83010101110AE1.1152.230-410-82010101111AF1.1202.240-405-8101010000B01.1252.250-400-80010110001B11.1302.260-395-79010110010B21.1352.270-390-78010110010B21.1352.270-390-76010110011B31.1402.280-385-7701011010B41.1452.290-380-7601011010B51.1502.300-375-7501011011B51.1602.320-365-7301011010B61.1752.330-360-72010111010B81.1652.330-360-70010111011B91.1702.340-355-71010111010BA1.1752.350-345-6901011101BB1.1802.360-345-6901011101BD1.1902.380-335-67010111101BF1.2002.400-325-650100100000C01.2052.410-320-640	10101010	AA	1.095	2.190	-430	-860
10101101AD1.1102.220-415-83010101110AE1.1152.230-410-82010101111AF1.1202.240-405-8101010000B01.1252.250-400-80010110001B11.1302.260-395-79010110010B21.1352.270-390-78010110010B21.1402.280-385-77010110010B41.1452.290-380-7601011010B41.1552.310-370-7401011010B61.1552.310-370-7401011011B71.1602.320-365-7301011000B81.1752.330-360-7201011100BA1.1752.350-350-7001011101B91.1802.360-345-6901011101BB1.1852.370-340-6801011101BD1.1902.380-335-6701011110BE1.1952.390-330-66010111111BF1.2002.400-325-6501000000C01.2052.410-320-640	10101011	AB	1.100	2.200	-425	-850
10101110AE1.1152.230-410-82010101111AF1.1202.240-405-81010110000B01.1252.250-400-80010110001B11.1302.260-395-79010110010B21.1352.270-390-78010110010B21.1402.280-385-77010110010B41.1452.290-380-7601011010B41.1552.310-375-7501011010B61.1552.310-370-7401011011B71.1602.320-365-73010110111B71.1602.330-360-72010111000B81.1752.350-350-70010111010BA1.1752.350-350-7001011101B81.1852.370-340-6801011101BC1.1852.390-335-67010111101BE1.1902.380-335-6701011111BF1.2002.400-325-65010111111BF1.2002.400-325-6501000000C01.2052.410-320-640	10101100	AC	1.105	2.210	-420	-840
10101111AF1.1202.240-405-81010110000B01.1252.250-400-80010110001B11.1302.260-395-79010110010B21.1352.270-390-78010110011B31.1402.280-385-77010110010B41.1452.290-380-76010110101B51.1502.300-375-75010110101B61.1552.310-370-74010110110B61.1652.330-365-73010110111B71.1602.320-365-71010110101B81.1652.330-360-72010111001B81.1702.340-355-71010111010BA1.1752.350-350-70010111010BA1.1852.370-340-68010111101BD1.1902.380-335-67010111101BD1.1902.380-330-66010111111BF1.2002.400-325-6501000000C01.2052.410-320-640	10101101	AD	1.110	2.220	-415	-830
10110000 B0 1.125 2.250 -400 -800 10110001 B1 1.130 2.260 -395 -790 10110010 B2 1.135 2.270 -390 -780 10110011 B3 1.140 2.280 -385 -770 10110010 B4 1.145 2.290 -380 -760 1011010 B4 1.145 2.290 -380 -760 1011010 B4 1.155 2.310 -370 -740 1011011 B5 1.160 2.320 -365 -730 1011011 B7 1.160 2.320 -365 -730 1011000 B8 1.175 2.330 -360 -720 1011100 B8 1.175 2.350 -350 -700 1011100 BA 1.175 2.350 -340 -680 1011101 BB 1.185 2.370 -340 -680 10111101	10101110	AE	1.115	2.230	-410	-820
10110001B11.1302.26039579010110010B21.1352.270.390.78010110011B31.1402.280.385.7701011000B41.1452.290.380.7601011010B41.1452.290.380.7601011010B51.1502.300.375.7501011011B61.1552.310.370.7401011011B71.1602.320.365.7301011000B81.1652.330.360.7201011100B81.1702.340.355.7101011101B91.1702.360.345.6901011101B81.1852.370.340.68010111101BC1.1902.380.335.6701011111BF1.2002.400.325.6501000000C01.2052.410.320.640	10101111	AF	1.120	2.240	-405	-810
10110010 B2 1.135 2.270 -390 -780 10110011 B3 1.140 2.280 -385 -770 10110100 B4 1.145 2.290 -380 -760 10110101 B5 1.150 2.300 -375 -750 1011010 B6 1.155 2.310 -370 -740 1011011 B7 1.160 2.320 -365 -730 1011011 B7 1.160 2.320 -365 -730 10110101 B8 1.165 2.330 -360 -720 10111000 B8 1.170 2.340 -355 -710 10111001 B9 1.175 2.350 -350 -700 10111010 BA 1.175 2.350 -345 -690 1011101 BB 1.185 2.370 -340 -680 10111101 BC 1.190 2.380 -335 -670 101111101 <td>10110000</td> <td>В0</td> <td>1.125</td> <td>2.250</td> <td>-400</td> <td>-800</td>	10110000	В0	1.125	2.250	-400	-800
10110011 B3 1.140 2.280 -385 -770 10110100 B4 1.145 2.290 -380 -760 10110101 B5 1.150 2.300 -375 -750 10110110 B6 1.155 2.310 -370 -740 10110111 B7 1.160 2.320 -365 -730 10110111 B7 1.160 2.320 -365 -730 1011001 B8 1.165 2.330 -360 -720 1011100 B8 1.170 2.340 -355 -710 10111001 B9 1.170 2.340 -355 -700 1011100 BA 1.175 2.350 -350 -700 1011101 BB 1.180 2.360 -345 -690 10111101 BC 1.185 2.370 -340 -680 10111101 BE 1.190 2.380 -335 -670 101111101 <td>10110001</td> <td>B1</td> <td>1.130</td> <td>2.260</td> <td>-395</td> <td>-790</td>	10110001	B1	1.130	2.260	-395	-790
10110100 B4 1.145 2.290 -380 -760 10110101 B5 1.150 2.300 -375 -750 10110110 B6 1.155 2.310 -370 -740 10110111 B7 1.160 2.320 -365 -730 10110111 B7 1.165 2.330 -360 -720 10111000 B8 1.165 2.330 -360 -720 10111001 B9 1.170 2.340 -355 -710 10111010 BA 1.175 2.350 -350 -700 10111010 BA 1.175 2.350 -345 -690 1011101 BB 1.180 2.360 -345 -690 10111100 BC 1.185 2.370 -340 -680 10111101 BD 1.190 2.380 -335 -670 10111101 BE 1.195 2.390 -330 -660 10111111<	10110010	B2	1.135	2.270	-390	-780
10110101 B5 1.150 2.300 -375 -750 10110110 B6 1.155 2.310 -370 -740 10110111 B7 1.160 2.320 -365 -730 10110011 B7 1.160 2.320 -365 -730 1011000 B8 1.165 2.330 -360 -720 10111001 B9 1.170 2.340 -355 -710 10111010 BA 1.175 2.350 -350 -700 10111010 BA 1.185 2.370 -340 -680 1011101 BB 1.185 2.370 -340 -680 10111100 BC 1.185 2.390 -335 -670 10111101 BD 1.190 2.380 -335 -660 10111110 BF 1.200 2.400 -325 -650 10000000 C0 1.205 2.410 -320 -640	10110011	B3	1.140	2.280	-385	-770
10110110 B6 1.155 2.310 370 740 10110111 B7 1.160 2.320 365 730 1011000 B8 1.165 2.330 360 720 10111001 B9 1.170 2.340 355 710 10111010 BA 1.175 2.350 350 700 10111010 BA 1.175 2.360 345 -690 10111011 BB 1.185 2.370 340 -680 10111101 BC 1.185 2.370 340 -680 10111101 BD 1.190 2.380 335 -670 10111101 BE 1.195 2.390 330 -660 10111111 BF 1.200 2.400 325 -650 110000000 C0 1.205 2.410 320 -640	10110100	B4	1.145	2.290	-380	-760
10110111 B7 1.160 2.320 -365 -730 10111000 B8 1.165 2.330 -360 -720 10111001 B9 1.170 2.340 -355 -710 10111001 B4 1.175 2.350 -350 -700 10111010 BA 1.175 2.360 -345 -690 10111011 BB 1.180 2.360 -345 -690 10111101 BC 1.185 2.370 -340 -680 10111101 BD 1.190 2.380 -335 -670 10111110 BE 1.195 2.390 -330 -660 10111111 BF 1.200 2.400 -325 -650 11000000 C0 1.205 2.410 -320 -640	10110101	B5	1.150	2.300	-375	-750
10111000 B8 1.165 2.330 -360 -720 10111001 B9 1.170 2.340 -355 -710 10111010 BA 1.175 2.350 -350 -700 10111010 BA 1.175 2.360 -345 -690 1011101 BB 1.185 2.370 -340 -680 10111100 BC 1.190 2.380 -335 -670 10111101 BD 1.190 2.390 -330 -660 10111111 BF 1.200 2.400 -325 -650 1000000 C0 1.205 2.410 -320 -640	10110110	B6	1.155	2.310	-370	-740
10111001 B9 1.170 2.340 -355 -710 10111010 BA 1.175 2.350 -350 -700 10111011 BB 1.180 2.360 -345 -690 10111010 BC 1.185 2.370 -340 -680 10111101 BD 1.190 2.380 -335 -670 10111110 BE 1.195 2.390 -330 -660 10111111 BF 1.200 2.400 -325 -650 11000000 C0 1.205 2.410 -320 -640	10110111	B7	1.160	2.320	-365	-730
10111010 BA 1.175 2.350 -350 -700 10111011 BB 1.180 2.360 -345 -690 1011100 BC 1.185 2.370 -340 -680 10111101 BD 1.190 2.380 -335 -670 10111101 BD 1.195 2.390 -330 -660 10111111 BF 1.200 2.400 -325 -650 11000000 C0 1.205 2.410 -320 -640	10111000	B8	1.165	2.330	-360	-720
10111011 BB 1.180 2.360 -345 -690 10111100 BC 1.185 2.370 -340 -680 10111101 BD 1.190 2.380 -335 -670 10111110 BE 1.195 2.390 -330 -660 10111111 BF 1.200 2.400 -325 -650 11000000 C0 1.205 2.410 -320 -640	10111001	B9	1.170	2.340	-355	-710
10111100BC1.1852.370-340-68010111101BD1.1902.380-335-67010111110BE1.1952.390-330-66010111111BF1.2002.400-325-65011000000C01.2052.410-320-640	10111010	BA	1.175	2.350	-350	-700
10111101 BD 1.190 2.380 -335 -670 1011110 BE 1.195 2.390 -330 -660 10111111 BF 1.200 2.400 -325 -650 11000000 C0 1.205 2.410 -320 -640	10111011	BB	1.180	2.360	-345	-690
10111110 BE 1.195 2.390 -330 -660 10111111 BF 1.200 2.400 -325 -650 11000000 C0 1.205 2.410 -320 -640	10111100	BC	1.185	2.370	-340	-680
10111111 BF 1.200 2.400 -325 -650 11000000 C0 1.205 2.410 -320 -640	10111101	BD	1.190	2.380	-335	-670
11000000 C0 1.205 2.410 -320 -640	10111110	BE	1.195	2.390	-330	-660
	10111111	BF	1.200	2.400	-325	-650
11000001 C1 1.210 2.420 -315 -630	11000000	CO	1.205	2.410	-320	-640
	11000001	C1	1.210	2.420	-315	-630

TABLE 4. 5mV OR 10mV VID 8-BIT (Continued)

22

TABLE 4. 5mV OR 10mV VID 8-BIT (Continued)

	HEX	5mV	10mV	5mV	10mV
BINARY CODE	CODE	VID (V)	VID (V)	OFFSET (mV)	OFFSET (mV)
11000010	C2	1.215	2.430	-310	-620
11000011	C3	1.220	2.440	-305	-610
11000100	C4	1.225	2.450	-300	-600
11000101	C5	1.230	2.460	-295	-590
11000110	C6	1.235	2.470	-290	-580
11000111	C7	1.240	2.480	-285	-570
11001000	C8	1.245	2.490	-280	-560
11001001	C9	1.250	2.500	-275	-550
11001010	CA	1.255	2.510	-270	-540
11001011	CB	1.260	2.520	-265	-530
11001100	CC	1.265	2.530	-260	-520
11001101	CD	1.270	2.540	-255	-510
11001110	CE	1.275	2.550	-250	-500
11001111	CF	1.280	2.560	-245	-490
11010000	D0	1.285	2.570	-240	-480
11010001	D1	1.290	2.580	-235	-470
11010010	D2	1.295	2.590	-230	-460
11010011	D3	1.300	2.600	-225	-450
11010100	D4	1.305	2.610	-220	-440
11010101	D5	1.310	2.620	-215	-430
11010110	D6	1.315	2.630	-210	-420
11010111	D7	1.320	2.640	-205	-410
11011000	D8	1.325	2.650	-200	-400
11011001	D9	1.330	2.660	-195	-390
11011010	DA	1.335	2.670	-190	-380
11011011	DB	1.340	2.680	-185	-370
11011100	DC	1.345	2.690	-180	-360
11011101	DD	1.350	2.700	-175	-350
11011110	DE	1.355	2.710	-170	-340
11011111	DF	1.360	2.720	-165	-330
11100000	EO	1.365	2.730	-160	-320
11100001	E1	1.370	2.740	-155	-310
11100010	E2	1.375	2.750	-150	-300
11100010	E3	1.380	2.760	-145	-290
11100100	E4	1.385	2.770	-140	-290
11100100			2.780		
11100101 11100110	E5 E6	1.390 1.395	2.790	-135 -130	-270 -260
11100110	E7	1.395	2.790	-130	-260
11100111	E8	1.400	2.800	-125	-230
11101000	E9	1.410	2.810	-120	-240
11101001	EA	1.415	2.820	-110	-230
11101010	EB	1.420	2.840	-105	-210
11101011	EC	1.425	2.850	-100	-200
11101101	ED	1.430	2.860	-95	-190
11101101		1.400	2.000		100

BINARY CODE	HEX CODE	5mV VID (V)	10mV VID (V)	5mV OFFSET (mV)	10mV OFFSET (mV)
11101110	EE	1.435	2.870	-90	-180
11101111	EF	1.440	2.880	-85	-170
11110000	FO	1.445	2.890	-80	-160
11110001	F1	1.450	2.900	-75	-150
11110010	F2	1.455	2.910	-70	-140
11110011	F3	1.460	2.920	-65	-130
11110100	F4	1.465	2.930	-60	-120
11110101	F5	1.470	2.940	-55	-110
11110110	F6	1.475	2.950	-50	-100
11110111	F7	1.480	2.960	-45	-90
11111000	F8	1.485	2.970	-40	-80
11111001	F9	1.490	2.980	-35	-70
11111010	FA	1.495	2.990	-30	-60
11111011	FB	1.500	3.000	-25	-50
11111100	FC	1.505	3.010	-20	-40
11111101	FD	1.510	3.020	-15	-30
11111110	FE	1.515	3.030	-10	-20
11111111	FF	1.520	3.040	-5	-10

TABLE 4. 5mV OR 10mV VID 8-BIT (Continued)

Load-line Regulation

Some applications require a precisely controlled output resistance. This dependence of output voltage on load current is often termed "droop" or "load-line" regulation. By adding a well controlled output impedance, the output voltage can effectively be level shifted in a direction, which works to achieve the load-line regulation required by these manufacturers.

In other cases, the designer may determine that a more cost-effective solution can be achieved by adding droop. Droop can help to reduce the output-voltage spike that results from fast load-current demand changes.

The magnitude of the spike is dictated by the ESR and ESL of the output capacitors selected. By positioning the no-load voltage level near the upper specification limit, a larger negative spike can be sustained without crossing the lower limit. By adding a well controlled output impedance, the output voltage under load can effectively be level shifted down so that a larger positive spike can be sustained without crossing the upper specification limit.

As shown in Figure 11, a current proportional to the average current of all active channels, I_{AVG} , flows from FB through a load-line regulation resistor R_{FB} , i.e., R_1 . The resulting voltage drop across R_{FB} is proportional to the output current, effectively creating an output voltage droop with a steady-state value defined, as shown in Equation 10:

$$V_{DROOP} = I_{AVG} \cdot R_{FB}$$

(EQ. 10)

The regulated output voltage is reduced by the droop voltage V_{DROOP} . The output voltage as a function of load current is derived by combining Equation 10 with the appropriate sample current expression defined by the current sense method employed, as shown in Equation 11:

$$V_{OUT} = V_{REF} - \left(\frac{I_{LOAD}}{N} \frac{R_X}{R_{ISEN}} R_{FB}\right)$$
(EQ. 11)

where V_{REF} is the reference voltage (DAC), I_{LOAD} is the total output current of the converter, R_{ISEN} is the sense resistor connected to the ISEN+ pin, and R_{FB} is the feedback resistor, N is the active channel number, and R_X is the DCR, or R_{SENSE} depending on the sensing method.

Therefore, the equivalent loadline impedance, i.e. Droop impedance, is equal to Equation 12:

$$R_{LL} = \frac{R_{FB}}{N} \frac{R_X}{R_{ISEN}}$$
(EQ. 12)

The major regulation error comes from the current sensing elements. To improve load-line regulation accuracy, a tight DCR tolerance of inductor or a precision sensing resistor should be considered.

In addition, the overall load-line can be programmed to fit the application needed by the PMBus registers: B0h[7:0] for Load-Line and E4h[9:5] for DC offset. Curve 3 shown in Figure 13, makes a steeper load line than the target to fully utilize the total tolerance band, reduce the output capacitor count and cost.

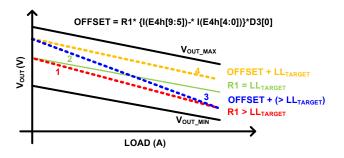


FIGURE 13. PROGRAMMABLE LOAD-LINE REGULATION

Dynamic VID

Some applications need to make changes to their voltage as part of normal operation. They direct the core-voltage regulator to do this by making changes to the VID during regulator operation. The power management solution is required to monitor the DAC and respond to on-the-fly VID changes in a controlled manner. Supervising the safe output voltage transition within the DAC range of the load without discontinuity or disruption is a necessary function of the voltage regulator.

Sixteen different slew rates can be selected for soft-start and during Dynamic VID (DVID) transition for VR.

TABLE 5. SLEW RATE OPTIONS

DVID F6h[4:0]	DVID SLEW RATE (MINIMUM RATE) (mV/µs)	DVID F6h[4:0]	DVID SLEW RATE (MINIMUM RATE) (mV/µs)
Oh	0.315	8h	4.0
1 h	0.625	9h	4.44
2h	1.25	Ah	5.0
3h	2.5	Bh	5.6
4h	2.85	Ch	6.66
5h	3.07	Dh	8.0
6h	3.33	Eh	10
7h	3.63	Fh	13.25

During dynamic VID transition and VID step up, the overcurrent trip point increases by 140% to avoid falsely triggering OCP circuits, while the overvoltage trip point will follow the DAC+OVP level, programmable via PMBus (D8h[2:0]).

Operation Initialization

Prior to converter initialization, proper conditions must exist on the enable inputs and V_{CC} . When the conditions are met, the controller begins soft-start. Once the output voltage is within the proper window of operation, VR_RDY asserts logic high.

Enable and Disable

While in shutdown mode, the PWM outputs are held in a high-impedance state (or pulled to 40% of V_{CC}) to assure the drivers remain off. The following input conditions must be met before the ISL6398 is released from shutdown mode.

- 1. The bias voltage applied at V_{CC} must reach the internal power-on reset (POR) rising threshold. Once this threshold is reached, proper operation of all aspects of the ISL6398 is guaranteed. Hysteresis between the rising and falling thresholds assure that once enabled, ISL6398 will not inadvertently turn off unless the bias voltage drops substantially (see "Electrical Specifications" on page 10).
- 2. The ISL6398 features an enable input (EN_PWR_CFP) for power sequencing between the controller bias voltage and another voltage rail. The enable comparator holds the ISL6398 in shutdown until the voltage at EN_PWR_CFP rises above 0.85V. The enable comparator has about 100mV of hysteresis to prevent bounce. It is important that the drivers reach their POR level before the ISL6398 becomes enabled. The schematic in Figure 14 demonstrates sequencing the ISL6398 with ISL99140 DrMOS and the ISL66xx family of Intersil MOSFET drivers.
- 3. The voltage on TM_EN_OTP must be higher than 1.08V (typically) to enable the controller. This pin is typically connected to the output of VTT VR. However, since the TM_EN_OTP pin is also used for thermal monitoring, it will assert SM_PMALERT# pin low due to thermal alert prior to start-up, therefore, it needs to use CLEAR_FAULT (03h) command to clear the SM_PMALERT# pin and STATUS_BYTE (78h) after power-up. There is no effect on normal operation if SM_PMALERT# and STATUS_BYTE are not used.

t_D

When all conditions previously mentioned are satisfied, the ISL6398 begins the soft-start and ramps the output voltage to the Boot Voltage set by hard-wired "BT" registers. After remaining at the boot voltage for some time, the ISL6398 reads the VID code. If the VID code is valid, ISL6398 will regulate the output to the final VID setting. If the VID code is "OFF" code, ISL6398 will remain shut down.

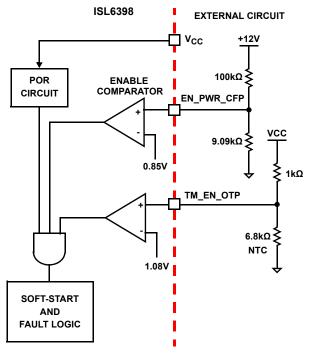


FIGURE 14. POWER SEQUENCING USING THRESHOLD-SENSITIVE ENABLE (EN) FUNCTION

Soft-start

The ISL6398 based VR has 4 periods during soft-start, as shown in Figure 15. After V_{CC}, TM_EN_OTP and EN_PWR_CFP reach their POR/enable thresholds and the NVM_BANK loading time (typically 16ms, and worst case 20ms) expired, the controller will have a fixed delay period t_{D1}. After this delay period, the VR will begin first soft-start ramp until the output voltage reaches the V_{BOOT} voltage at a fixed slew rate, as in Table 5. Then, the controller will regulate the VR voltage at V_{BOOT} for another period t_{D3} until PMBus sends a new VID command. If the VID code is valid, ISL6398 will initiate the second soft-start ramp at a slew rate, set by DVID command in Table 5, until the voltage reaches the new VID voltage. The soft-start time is the sum of the 4 periods, as shown in Equation 13.

$$t_{SS} = t_{D1} + t_{D2} + t_{D3} + t_{D4}$$
 (EQ. 13)

 t_{D1} is a fixed delay with the typical value as $20\mu s.$ t_{D3} is determined by the time to obtain a new valid VID voltage from PMBus. If the VID is valid before the output reaches the boot voltage, the output will turn around to respond to the new VID code.

During t_{D2} and t_{D4} , the ISL6398 digitally controls the DAC voltage change at 5mV per step. The soft-start ramp time t_{D2} and t_{D4} can be calculated based on Equations 14 and 15:

$$t_{D2} = \frac{V_{BOOT}}{DVIDRATE}(\mu s)$$
(EQ. 14)

$$_{4} = \frac{V_{VID} - V_{BOOT}}{DVID RATE}(\mu s)$$

For example, when the V_{BOOT} is set at 1.1V and DVID slew rate is set at 5mV/µs, the first soft-start ramp time t_{D2} will be around 220µs and the second soft-start ramp time t_{D4} will be at maximum of 80µs if an SET_VID command for 1.5V is received after t_{D3} .

(EQ. 15)

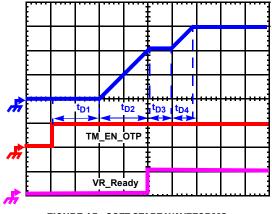


FIGURE 15. SOFT-START WAVEFORMS

Current Sense Output

The current flowing out of the IMON pin is equal to the sensed average current inside the ISL6398. In typical applications, a resistor is placed from the IMON pin to GND to generate a voltage, which is proportional to the load current and the resistor value, as shown in Equation 16:

$$V_{\rm IMON} = \frac{R_{\rm IMON}}{N} \frac{R_{\rm X}}{R_{\rm ISEN}} I_{\rm LOAD}$$
(EQ. 16)

where V_{IMON} is the voltage at the IMON pin, R_{IMON} is the resistor between the IMON pin and GND, I_{LOAD} is the total output current of the converter, R_{ISEN} is the sense resistor connected to the ISEN+ pin, N is the active channel number, and R_X is the DC resistance of the current sense element, either the DCR of the inductor or R_{SENSE} depending on the sensing method.

The resistor from the IMON pin to GND should be chosen to ensure that the voltage at the IMON pin is typically 2.5V at the maximum load current, typically corresponding to the I_{CCMAX} register. The IMON voltage is linearly digitized every 88µs and stored in the READ_IOUT register (8Ch). When the IMON voltage reaches 2.5V or higher, the digitized I_{OUT} will reach the maximum value of ICCMAX and the SM_PMALERT# pin is pulled low.

$$R_{\rm IMON} = \frac{2.5 V R_{\rm ISEN}}{R_{\rm X}} \frac{N}{I_{\rm CC_MAX_21h}}$$
(EQ. 17)

A small capacitor can be placed between the IMON pin and GND to reduce the noise impact and provide averaging. If this pin is not used, tie it to GND.

To deal with layout and design variation of different platforms, the ISL6398 is intentionally trimmed to negative range at no load, thus, an offset can easily be added to calibrate the digitized IMON reading (8Ch in PMBus) whenever needed by PMBus (E4h) or the external pull-up resistor in Figure 16. Hence, the slope on the IMON pin is set by the equivalent impedance of $R_{MON1/}/R_{MON2} = R_{IMON}$. Additional offset can be added by IOUT_CAL_OFFSET (E5h).

 $R_{MON2} = \frac{V_{CC} R_{IMON}}{V_{IMON_OFFSET_DESIRED}}$ $R_{MON1} = \frac{R_{IMON2} R_{IMON}}{R_{IMON2} - R_{IMON}}$ (EQ. 18)

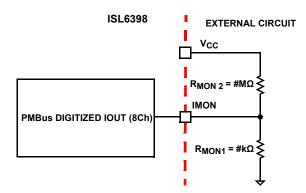


FIGURE 16. IMON NO LOAD OFFSET CALIBRATION

In addition, if the IMON pin voltage is higher than 3.0V, overcurrent shutdown will be triggered, as described in "Overcurrent Protection" on page 27.

Fault Monitoring and Protection

The ISL6398 actively monitors output voltage and current to detect fault conditions. Fault monitors trigger protective measures to prevent damage to a microprocessor load. One common power-good indicator (VR_RDY) is provided for linking to external system monitors. The schematic in Figure 17 outlines the interaction between the fault monitors and the VR_RDY signal.

VR_Ready Signal

The VR_RDY pin is an open-drain logic output which indicates that the soft-start period is complete and the output voltage is within the regulated range. The VR_RDY is pulled low during shutdown and releases high after a successful soft-start. VR_RDY will be pulled low when an fault (OCP, OTP, UVP, or OVP) condition is detected, or the controller is disabled by a reset from EN_PWR_CFP, TM_EN_OTP, POR, or VID OFF-code.

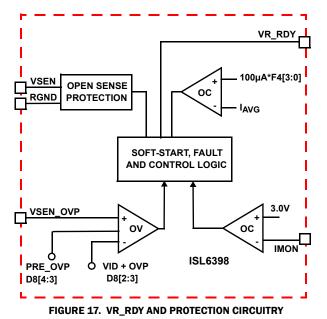
Overvoltage Protection

Regardless of the VR being enabled or not, the ISL6398 overvoltage protection (OVP) circuit will be active after its POR. The OVP thresholds are different under different operation conditions. When VR is not enabled and during the soft-start intervals t_{D1} , the OVP threshold is programmable via PMBus (D8h[4:3]). Once the VR completes the soft-start, the OVP trip point will change to a tracking level of DAC+OVP, programmable via PMBus (D8h[2:0]).

Two actions are taken by ISL6398 to protect the load when an overvoltage condition occurs.

At the inception of an overvoltage event, all PWM outputs are commanded low instantly. This causes the Intersil drivers to turn on the lower MOSFETs and pull the output voltage below a level to avoid damaging the load. When the output voltage falls below the DAC plus 100mV, PWM signals enter a high-impedance state. The Intersil drivers respond to the high-impedance input by turning off both upper and lower MOSFETs. If the overvoltage condition reoccurs, the ISL6398 will again command the lower MOSFETs to turn on. The ISL6398 will continue to protect the load in this fashion as long as the overvoltage condition occurs.

Once an overvoltage condition is detected, the respective VR ceases the normal PWM operation and pulls its VR_Ready low until the ISL6398 is reset. Cycling the voltage V_{CC} below the POR-falling threshold will reset the controller. Cycling EN_PWR_CFP or TM_EN_OTP will NOT reset the controller.



In addition, the ISL6398 features open sensing protection to detect an open of the output voltage sensing as an OVP event, which suspends the controller operation. Without this protection, the VR can regulate up to maximum duty cycle and damage the load and power trains when the output sensing is broken open. Furthermore, since the regulation loop is sensed via the VSEN pin and the OVP is sensed via the VSEN_OVP pin, they are independent paths to keep output within target and below OVP level, respectively. Thus, the ISL6398 protects against a single point of failure.

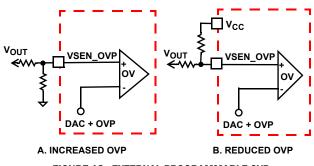


FIGURE 18. EXTERNAL PROGRAMMABLE OVP

Furthermore the regulation loop (VSEN pin) and the OVP sense (VSEN_OVP) are separated paths, the OVP level can be programmed higher or lower than the target, as in Figure 18. The OVP level cannot be scaled too close to DAC to ensure that the OVP is not triggered during transient response and start-up.

In addition, the ISL6398 also provides early OVP warning; when it is triggered, it asserts STATUS_WORD (79h Upper Byte, Bit7) and SM_PMALERT#. It however does not shutdown the system, assert STATUS_BYTE, or pull VR_RDY low. Disregard this if both STATUS_WORD and SM_PMALERT# are not used or disable OVP Warning as needed via DFh.

Undervoltage Protection

When the output voltage drops below a level programmed by PMBus (E1[3:0]), the VR_RDY is pulled low. The controller can respond to UVP with two different options programmed by PMBus (E1[6]): 1) acts as a OCP event, hiccup the output with 9ms duration and pull VR_RDY low; or 2) acts like a PGOOD, pull VR_RDY low, monitor only. To avoid faulty triggering at transient/DVID events, the UVP delay is programmable by E1[5:4]. Furthermore, the UVP delay is programmable by E1[5:4]. Furthermore, the UVP is not enabled during soft-start and also can be disabled by DF[5]. The ISL6398 also provides early UVP warning; when it is triggered, it asserts STATUS_WORD (79h Upper Byte, Bit7) and SM_PMALERT#. It however does not shutdown the system, assert STATUS_BYTE or pull VR_RDY low. Disregard this if both STATUS_WORD and SM_PMALERT# are not used or disable UVP Warning as needed via DFh.

Overcurrent Protection

The ISL6398 has two levels of overcurrent protection. Each phase is protected from a sustained overcurrent condition by limiting its peak current, while the combined phase currents are protected on an instantaneous basis.

For the individual channel overcurrent protection, the ISL6398 continuously compares the sensed peak current (~50ns filter) signal of each channel with the reference current (I_{CL} , typically 125µA, programmable via F4[5:3] and F3[2:0]). If one channel current exceeds the reference current, the ISL6398 will pull PWM signal of this channel to low for the rest of the switching cycle. This PWM signal can be turned on next cycle if the sensed channel current is less than the reference current. The peak current limit of individual channels will only use cycle-by-cycle current limiting and will not trigger the converter to shut down.

In instantaneous protection mode, the ISL6398 utilizes the sensed average current I_{AVG} to detect an overcurrent condition. Refer to "Current Sensing" on page 18 for more details on how

the average current is measured. The average current is continually compared with a reference current (typically 100µA, programmable via F2[2:0]), as shown in Figure 17. Once the average current exceeds the reference current, a comparator triggers the converter to shut down. In addition, the current out of the IMON pin is equal to the sensed average current $I_{\Delta VG}$. With a resistor from IMON to GND, the voltage at IMON will be proportional to the sensed average current and the resistor value. The ISL6398 continuously monitors the voltage at the IMON pin. If the voltage at the IMON pin is higher than 3.0V, a precision comparator triggers the overcurrent shutdown. Since the internal current comparator has wider tolerance than the voltage comparator, the IMON voltage comparator is the preferred one for OCP trip. Therefore, the resistor between IMON and GND can be scaled such that the overcurrent protection threshold is tripping lower than $100\mu A$. For example, the overcurrent threshold for the sensed average current I_{AVG} can be set to 95μ A by using a $31.5k\Omega$ resistor from IMON to GND. Thus, the internal 100µA comparator might only be triggered at its lower corner. However, IMON OCP trip should NOT be too far away from 125µA, which is used for cycle-by-cycle protection and inductor saturation.

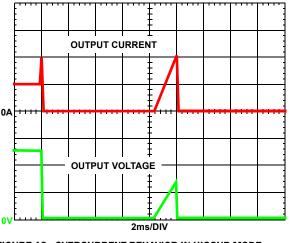


FIGURE 19. OVERCURRENT BEHAVIOR IN HICCUP MODE $F_{SW} = 500 \text{kHz}$

At the beginning of overcurrent shutdown, the controller places all PWM signals in a high-impedance state, commanding the Intersil MOSFET driver ICs to turn off both upper and lower MOSFETs. The system remains in this state a period of 9ms. If the controller is still enabled at the end of this wait period, it will attempt a soft-start. If the fault remains, the trip-retry cycles will continue indefinitely (as shown in Figure 19) until either controller is disabled or the fault is cleared. Note that the energy delivered during trip-retry cycling is much less than during full-load operation, so there is no thermal hazard during this kind of operation.

Thermal Monitoring (VR_HOT#)

VR_HOT# indicates the temperature status of the voltage regulator. VR_HOT# is an open-drain output, and an external pull-up resistor is required. This signal is valid only after the controller is enabled.

The VR_HOT# signal can be used to inform the system that the temperature of the voltage regulator is too high.

The block diagram of thermal monitoring function is shown in Figure 20. One NTC resistor should be placed close to the respective power stage of the voltage regulator VR to sense the operational temperature, and pull-up resistors are needed to form the voltage dividers for the TM pins. As the temperature of the power stage increases, the resistance of the NTC will reduce, resulting in the reduced voltage at the TM pin. Figure 21 shows the TM voltage over the temperature for a typical design with a recommended 6.8kΩ NTC (P/N: NTHS0805N02N6801 from Vishay, b = 3477) and $1k\Omega$ resistor R_{TM}. It is recommended to use those resistors for the accurate temperature compensation since the internal thermal digital code is developed based upon these two components. If a different value is used, the temperature coefficient must be close to 3477 and R_{TM} must be scaled accordingly. For instance, NTC = $10k\Omega$ (b = 3477), then R_{TM} should be $10k\Omega/6.8k\Omega * 1k\Omega = 1.47k\Omega$.

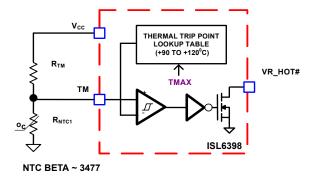


FIGURE 20. BLOCK DIAGRAM OF THERMAL MONITORING FUNCTION

There is a comparator with hysteresis to compare the TM pin voltage to the threshold set by the TMAX register (programmable via PMBus E8[2:0]) for VR_HOT# signal. With TMAX set at $\pm 100^{\circ}$ C, the VR_HOT# signal is pulled to GND when TM voltage is lower than 39.12% of V_{CC} voltage, and is open (pulled high through TM) when TM voltage increases to above 40.98% of V_{CC} voltage. The comparator trip point will be programmable by TMAX values. Figure 21 shows the operation of those signals.

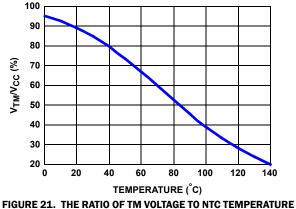


FIGURE 21. THE RATIO OF TM VOLTAGE TO NTC TEMPERATUR WITH RECOMMENDED PARTS

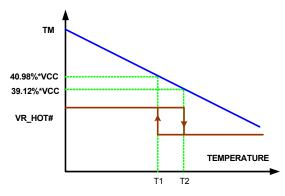


FIGURE 22. VR_HOT# SIGNAL (TMAX = +100°C) vs TM VOLTAGE

Based on the NTC temperature characteristics and the desired threshold of the VR_HOT# signal, the pull-up resistor R_{TM} of TM pin is given by Equation 19:

$$R_{TM} = 1.557 \times R_{NTC(T2)}$$
 (EQ. 19)

R_{NTC(T2)} is the NTC resistance at the VR_HOT# threshold temperature T2. The VR_HOT# is de-asserted at temperature T1, as shown in Table 6. The NTC directly senses the temperature of the PCB and not the exact temperature of the hottest component on the board due to airflow and varied thermal impedance. Therefore, the user should select a lower TMAX number, depending upon the mismatch between NTC and the hottest components, than such component to guarantee a safe operation.

TABLE 6. VR_HOT# 1	IYPICAL TRIP PO	INT AND H	YSTERESIS
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TMAX (°C)	VR_HOT# LOW (° C; T2, %V _{CC})	VR_HOT# OPEN (°C; T1, %V _{CC})	HYSTERESIS (°C)
85	83.1; 48.94%	80.3; 51.04%	2.7
90	88.6; 45.52%	85.9; 47.56%	2.7
95	94.3; 42.26%	91.4; 44.20%	2.9
100	100.0; 39.12%	97.1; 40.98%	2.9
105	106.1; 36.14%	103.0; 37.92%	3.1
110	109.1; 33.32%	106.1; 35.00%	3.0
115	115.5; 30.68%	112.3; 32.24%	3.2
120	118.7; 28.24%	115.5; 29.7%	3.2

In addition, as the temperature increase, the voltage on the TM pin drops. The controller is disabled when the TM pin voltage drops below 0.95 (typically) and becomes active again when it is above 1.05V (typically).

Temperature Compensation

The ISL6398 supports inductor DCR sensing, or resistive sensing techniques. The inductor DCR has a positive temperature coefficient, which is about +0.385%/°C. Since the voltage across the inductor is sensed for the output current information, the sensed current has the same positive temperature coefficient as the inductor DCR. n order to obtain the correct current information, there should be a way to correct the temperature impact on the current sense component.

Integrated Temperature Compensation

The ISL6398 utilizes the voltage at the TM pin and "TCOMP" register to compensate the temperature impact on the sensed current. The block diagram of this function is shown in Figure 23.

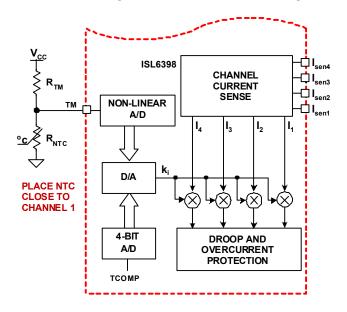


FIGURE 23. BLOCK DIAGRAM OF INTEGRATED TEMPERATURE COMPENSATION

When the NTC is placed close to the current sense component (inductor), the temperature of the NTC will track the temperature of the current sense component. Therefore, the TM voltage can be utilized to obtain the temperature of the current sense component. Since the NTC could pick up noise from phase node, a 0.1μ F ceramic decoupling capacitor is recommended on the TM pin in close proximity to the controller.

Based on the V_{CC} voltage, the ISL6398 converts the TM pin voltage to a 6-bit TM digital signal for temperature compensation. With the non-linear A/D converter of ISL6398, the TM digital signal is linearly proportional to the NTC temperature. For accurate temperature compensation, the ratio of the TM voltage to the NTC temperature of the practical design should be similar to that in Figure 21.

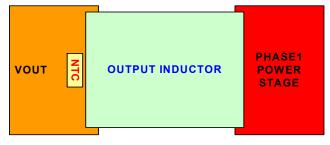


FIGURE 24. RECOMMENDED PLACEMENT OF NTC

Since the NTC attaches to the PCB, but not directly to the current sensing component, it inherits high thermal impedance between the NTC and the current sensing element. The "TCOMP" register values can be utilized to correct the temperature difference between NTC and the current sense component. Figure 24 shows that, the NTC should be placed in proximity to the channel 1 and the output rail; DON'T place it close to the MOSFET side, which generates much more heat.

The ISL6398 multiplexes the "TCOMP" value with the TM digital signal to obtain the adjustment gain to compensate the temperature impact on the sensed channel current. The compensated channel current signal is used for droop and overcurrent protection functions.

E9h	TCOMP (°C)	E9h	TCOMP (°C)
Oh	OFF	8h	16
1h	-2.5	9h	18.9
2h	0	Ah	21.6
3h	2.5	Bh	24.3
4h	5	Ch	27
5h	7	Dh	29.7
6h	10	Eh	32.4
7h	13	Fh	35.1

TABLE 7. "TCOMP" VALUES

When a different NTC type or different voltage divider is used for the TM function, the TCOMP voltage can also be used to compensate for the difference between the recommended TM voltage curve in Figure 21 and that of the actual design. If the same type NTC (β = 3477) but different value is used, the pull-up resistor needs to be scaled, as shown in Equation 20:

$$R_{TM} = \frac{1k\Omega \cdot R_{NTC} NEW}{6.8k\Omega}$$
(EQ. 20)

Design Procedure

- 1. Properly choose the voltage divider for the TM pin to match the TM voltage vs temperature curve with the recommended curve in Figure 21.
- 2. Run the actual board under the full load and the desired cooling condition.
- 3. After the board reaches the thermal steady state, record the temperature (T_{CSC}) of the current sense component (inductor or MOSFET) and the voltage at TM and V_{CC} pins.
- 4. Use Equation 21 to calculate the resistance of the NTC, and find out the corresponding NTC temperature T_{NTC} from the NTC datasheet or using Equation 22, where b is equal to 3477 for recommended NTC.

$$R_{NTC}(T_{NTC}) = \frac{V_{TM} x R_{TM}}{V_{CC} - V_{TM}}$$
(EQ. 21)

$$T_{\rm NTC} = \frac{\beta}{\ln\left(\frac{RTM}{R_{\rm NTC}(T_{\rm NTC})}\right) + \frac{\beta}{298.15}} - 273.15$$
 (EQ. 22)

 In Intersil design worksheet, choose a number close to the result as in Equation 23 in the "TCOMP" cell to calculate the needed resistor network for the register "TCOMP" pin. Note: for worksheet, please contact Intersil Application support at <u>www.intersil.com/design.</u> $T_{COMP} = T_{CSC} - T_{NTC}$

(EQ. 23)

- 6. Run the actual board under full load again with the proper resistors connected to the "TCOMP" pin.
- 7. Record the output voltage as V1 immediately after the output voltage is stable with the full load. Record the output voltage as V2 after the VR reaches the thermal steady state.
- If the output voltage increases over 3mV as the temperature increases, i.e. V2 - V1 > 3mV, reduce "TCOMP" value; if the output voltage decreases over 3mV as the temperature increases, i.e. V1 - V2 > 3mV, increase "TCOMP" values.

Dynamic VID Compensation (DVC)

During DVID transitions, extra current builds up in the output capacitors due to the C*dv/dt. The current is sensed by the controller and fed across the feedback resistor creating extra droop (if enabled) and causing the output voltage not properly tracking the DAC voltage. An independent compensation for DVID up and DVID down are implemented to optimize the DVID transition (Patent Pending), programmable by D7 and D9, respectively.

Programmable Compensation

The ISL6398 controller utilizes Intersil's proprietary Advanced Linear EAPP Digital control scheme that is the best modulation scheme in the industry to achieve linear response for both transient and current balance and can process voltage and current information in real time for fast control and high speed protection and realize digital power management capability and flexibility and. The digital compensation covers a wide range of poles and zeros, as in Figure 25, suitable for computing, networking, ASIC, and many general purpose applications. Refer ISL6398 GUI on Table 16 for more details and advanced features.

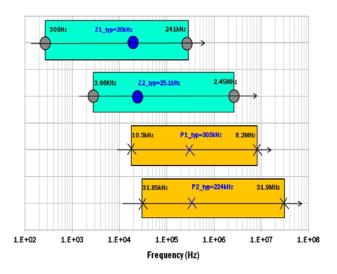


FIGURE 25. TYPE III Compensation Poles and Zero Range

Catastrophic Fault Protection

A catastrophic failure is a failure that will result in an exothermic event if the power source is not removed. A predominate catastrophic failure is a high-side FET shorting, which can cause either output overvoltage or input overcurrent event. When the ISL6398 detects either event, an internal switch is turned on to pull the EN_PWR_CFP pin to V_{CC} , as an indication of a component failure in the regulator's power train. As shown in Figure 26, a CFP fault signal can be generated by using a resistor divider on this pin. To be able to apply the signal to the PS_ON# switch of an ATX power supply or a simply external switch (2N7002), the CFP fault signal should be lower than 0.8V at maximum input voltage, $V_{IN(max)}$ and higher than 3V at lowest normal operational V_{CC} (4.5V) when the input voltage (VIN) is removed. Given such conditions, the equivalent (in parallel) impedance of the upper leg (RUP) and lower leg $(R_{DW} = R_{DW1} + R_{DW1})$ should be higher than $1k\Omega$. For instance, if we select the total lower leg impedance (R_{DW}) as 9.39k Ω , then the R_{IIP} is calculated as in Equation 25, 100k Ω for a maximum POR of 10.72V, The lower leg impedance is then calculated by 2.74k Ω and 6.65kΩ, as in Equations 26 and 27, respectively.

 $R_{DW} = R_{DW1} + R_{DW2}$ (EQ. 24)

$$R_{UP} = \frac{VIN(POR, max) - 0.92V}{0.92V} \cdot R_{DW}$$
(EQ. 25)

$$R_{DW1} = \frac{VIN(max)}{0.8V} \cdot (R_{UP} + R_{DW})$$
(EQ. 26)

$$R_{DW2} = R_{DW} - R_{DW1}$$
(EQ. 27)

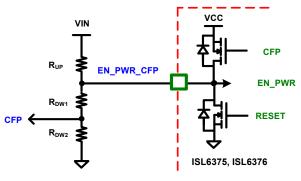


FIGURE 26. BI-DIRECTIONAL EN_PWR_CFP

Prior to an exothermic event, the fault signal (CFP) should be used on the platform to remove the power source either by firing a shunting SCR to blow a fuse or by turning off the AC power supply.

Input Current Sensing

The input current sensing uses Intersil patented technique to overcome the high common-mode input requirement challenge. An R-C network with thermal compensation across the inductor (LIN) extracts the DCR voltage, as shown in Figure 27, while the C might need to be split into 2, one close the LIN and one close to the controller. The input inductor can be used for current sensing and has benefit of isolating noise from the rest of the board. However, when there are insufficient bulk capacitors on the power-stage side, a resonant tank can be formed by input ceramic capacitors and the inductor, yielding oscillation or audio noise during audio frequency range of heavy load transient. In addition, since Z_{NTC} network steals portion of sensed current from R_{IN1} , input current reading will have offset.

In many cases, a narrow input-rail PCB trace (but wide enough to carry DC current) is sufficient to serve as the isolation path. Thus, the input current sensing can simply be realized with a dedicated power resistor, as shown in Figure 28.

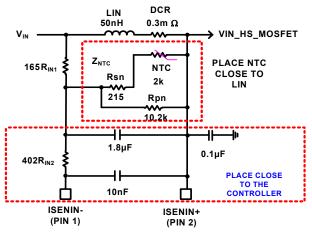
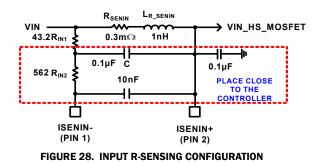


FIGURE 27. INPUT DCR-SENSING CONFIGURATION

The full scale of input current sensing is 10µA, read 1Fh with READ_IIN(89h), via PMBus, while the input over-current trip point is at 15µA (Programmable via F6[6:5]). A greater than 40µs time constant $[C*R_{IN1}*R_{IN2})/(R_{IN1}+R_{IN2})]$ might be needed if the average input current reporting is preferred; and it also reduces chance to trigger CFP during heavy load transient depending upon the input filter. A design worksheet to select these components is available for use. Please contact Intersil Application support at www.intersil.com/design.



When not used, connect ISENIN+ to VIN and a resistor divider with a ratio of 1/3 on ISENIN± pin, say 499k Ohm in between ISENIN± pins and then $1.5M\Omega$ from ISENIN- to ground (see Figure 29).

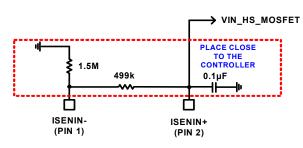


FIGURE 29. DISABLE PIN AND IIN CONFIGURATION

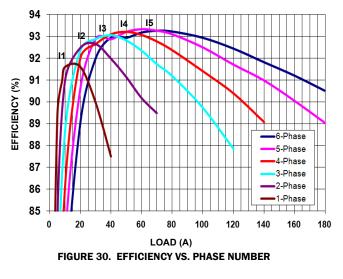
Auto-phase Shedding

The ISL6398 incorporates auto-phase shedding feature to improve light to medium load range. The phase current dropping threshold is programmable with the resistor on auto pin. The efficiency-optimized current trip point (11) from 1-Phase to 2-Phase operation is approximated with Equation 28, which is kx larger than the efficiency-optimized current trip step (dl = I3 - I2) in between from 2-phase to 3-phase (I2) and from 3-phase to 4-phase (I3). The optimized-efficiency current trip point difference between phases remain constant I1/k, as expressed in Equation 29 and Figure 30

$$11 \approx \sqrt{\frac{2 \cdot (P_{QG} + P_{CORE} + P_{COSS})}{ESR_{IN} \cdot D + R_{ON} + L_{DS} \cdot F_{SW}}}$$
(EQ. 28)

$$R_{ON} = D \cdot r_{DS(ON) UP} + (1 - D) \cdot r_{DS(ON) LOW} + DCR$$

where P_{QG} is the per-phase gate charge loss, P_{CORE} is the inductor core loss, P_{QOSS} is the sum of high-side and low-side MOSFETs' output charge loss.



$$I_{\text{IMON}_{\text{OPTIMIZED}_{1}_{\text{PHASE}}} \approx \frac{64 \cdot \text{DCR} \cdot \text{I1}}{N_{\text{MAX}} \cdot R_{\text{SET}}}$$
 (EQ. 29)

$$R_{AUTO} = \frac{1.2V}{I_{IMON_OPTIMIZED_1_PHASE}}$$
 (EQ. 30)

$$R_{AUTO} \approx \frac{1.2V \cdot N_{MAX} \cdot R_{SET}}{64 \cdot DCR \cdot I1}$$
(EQ. 31)

$$I_{(N)} \approx I1 \cdot \left(1 + \frac{1}{K} \cdot (N-1)\right)$$
 (EQ. 32)

Equations 30 and 31 helps approximate the AUTO resistor, while the trip point hysteresis can be programmed via PMBus D1[5:4]. Typically, the higher the inductor ripple current, the higher percentage of hysteresis and k it requires. Following is an easy way to estimate R_{AUTO} value:

- 1. Before AUTO trip point tuning, calibrate IMON current close to zero with PMBus E4[4:0].
- 2. Disable AUTO mode via D4[2] or by tying AUTO pin GND
- 3. Obtain efficiency curve for 1- to 6-phase, programmed via D0,with appropriate load (~25A/Phase. 0.5A step); and APA disabled via D4h as needed.
- 4. Determine I1 from the above test result.
- 5. Short AUTO pin to ground with a current meter to measure the IMON current (I_{IMON OPTIMIZED 1 PHASE}) when VR is at I1 load.
- 6. Calculate RAUTO as in Equation 31.
- 7. Solder down R_{AUTO} and enable AUTO mode.
- 8. Take efficiency curve and compare it with the 1-to 6-Phase Efficiency Curves.
- Tweak R_{AUTO} and D1 (k, l1, Hysteresis) as needed for optimal Efficiency performance at targeted operating input and output voltage as well as airflow.
- 10. Obtain efficiency curve for couple boards and tweak ${\sf R}_{AUTO}$ to re-center overall efficiency of these boards.

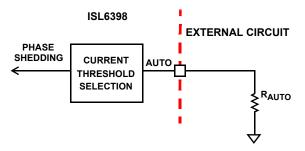


FIGURE 31. SIMPLIFIED AUTO-PHASE SHEDDING CIRCUIT

In addition, the SMBus, PMBus, or I²C gives flexibility to program Auto K-factor (D1[3:2]), hysteresis (D1[5:4]), I1 (D1[7:6]), and number of operating phases after soft-start and when auto mode is disabled by D4[2]. However, all phases will be added back when APA is triggered; and if APA is disabled, all phase are added back only after reset or OCP retry.

The minimum of auto-phase shedding is defaulted by NPSI in PSI1 mode and can also be programmed by the bus command code D1h[1:0], as in Table 14. The phase dropping sequence is summarized in Table 8.

TABLE 8. PHASE DROPPING SEQUENCE

N	PWM# TIED TO V _{CC} (VCORE)	PHASE SEQUENCE
6	NONE	6-3-5-2-4-1
5	PWM6	5-4-2-3-1
4	PWM5	4-2-3-1
3	PWM4	3-2-1
2	PWM3	2-1

To ensure dropped phases have sufficient energy to turn on high-side MOSET and sustain instant load apply after VRO staying in light load condition for a long time (hours to days), a boot-refresh circuit turns on Low-side MOSFET of each dropped phase to refresh the boot capacitor at a rate of slightly above 20kHz. The boot-fresh circuit is automatically turned off to boot efficiency when DAC drops to 0.60V.

Resistor Reader (Patented)

Intersil has developed a high resolution ADC using a patented technique with simple 1%, 100ppm/k or better temperature coefficient resistor divider. The same type of resistors are preferred so that it has similar change over-temperature. In addition, the divider is compared to the internal divider off V_{CC} and GND nodes and therefore must refer to VCC and GND pins, not through any RC decoupling network.

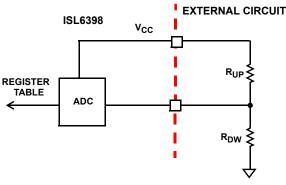


FIGURE 32. SIMPLIFIED RESISTOR DIVIDER ADC

NVM_BANK_BT pin is designed to allow the user to select different NVM Banks (Pre-configured IC) and/or Boot Voltage Level even without PMBus communications; while VRSEL_ADDR is to select different operation mode (5mV or 10mV), indirectly control Boot Voltage Level and DAC resolution, and PMBus Addresses. The programmed values of resistor reader are stored in DC and DD of PMBus.

As an example, Table 9 shows the R_{UP} and R_{DW} values of each pin for a specific system design; DATA for corresponding registers can be read out via PMBus commands (DC and DD). In addition, some tie-high and tie-low options are available for easy programming (save resistor dividers) and can also be used to validate the VR operation during In-Circuit Test (ICT). For instance, when the system boot voltage is required at 0V, the NVM_BANK_BT pin can be set to different voltage level, prior to power-up, to get a known boot voltage to check VR operation with ICT. Resistor reader calculator is available, please contact Intersil Application support at <u>www.intersil.com/design</u>.

TABLE 9. PMBus (DC) RESISTOR READER EXAMPLE

PMBus (DC)	01 01		RECOMMENDED APPLICATIONS	
00h	OPEN	10	80	10mV/Step
01h	49.9	12.4	82	10mV/Step
02h	45.3	12.7	84	10mV/Step
03h	43.2	13.3	86	10mV/Step
08h	29.4	15	CO	10mV/Step
09h	28	15.4	C2	10mV/Step
OCh	24.3	17.4	C8	10mV/Step
0Dh	23.2	17.8	CA	10mV/Step
10h	20	19.6	EO	10mV/Step
11h	19.6	20.5	E2	10mV/Step
14h	17.4	23.2	E8	10mV/Step
15h	16.9	24.3	EA	10mV/Step
80h	OPEN	499	80	5mV/Step
81h	374	93.1	82	5mV/Step
82h	340	95.3	84	5mV/Step
83h	316	100	86	5mV/Step
88h	221	113	CO	5mV/Step
89h	210	115	C2	5mV/Step
8Ch	182	130	C8	5mV/Step
8Dh	174	133	CA	5mV/Step
90h	150	147	EO	5mV/Step
91h	147	154	E2	5mV/Step
94h	130	174	E8	5mV/Step
95h	127	182	EA	5mV/Step

TABLE 10. PMBus (DD) RESISTOR READER EXAMPLE

PMBus (DD)	R _{UP} (kΩ)	R _{DW} (kΩ)	NVM	BT
00h	OPEN	10	NVMO	NVM_BT
20h	118	26.1	NVM1	NVM_BT
40h	196	43.2	NVM2	NVM_BT
60h	294	64.9	NVM3	NVM_BT
80h	422	93.1	NVM4	NVM_BT
A0h	590	130	NVM5	NVM_BT
COh	825	182	NVM6	NVM_BT
EOh	OPEN	499	NVM7	NVM_BT
01h	49.9	12.4	NVMO	0.0V
10h	20	19.6	NVMO	1.7V, 10mV/Step
09h	28	15.4	NVMO	0.6V, 5mV/Step 1.2V, 10mV/Step

TABLE 10. PMBus (DD) RESISTOR READER EXAMPLE (Continued)

PMBus (DD)	R _{UP} (kΩ)	R _{DW} (kΩ)	NVM	BT
32h	40.2	45.3	NVM1	0.9V, 5mV/Step 1.8V, 10mV/Step
55h	59	84.5	NVM2	1.0V, 5mV/Step 2.0V, 10mV/Step
79h	78.7	163	NVM3	1.2V, 5mV/Step 2.4V, 10mV/Step
9Fh	95.3	367	NVM4	1.5V, 5mV/Step 2.0V, 10mV/Step
B2h	196	226	NVM5	1.8V, 10mV/Step
DAh	215	475	NVM6	2.5V, 10mV/Step

NOTE: More options in resistor reader calculator. NVM_BT = Boot Voltage Loaded from the Bank, not fixed by resistor reader.

Memory Banks

The ISL6398 has 8 memory banks to store up

(STORE_USER_ALL, 15h) to 8 different configurations, selectable via PMBus (DEh) or resistor to GND on the NVM_BANK pin, as in Table 11. No decoupling capacitor is allowed on the pin. Prior to the soft-start, the selection of memory bank is stored in the data registers of PMBus (DDh). They are reset by V_{CC} POR. In addition, the selected memory bank can be overridden by PMBus (DEh). Only the selected memory bank's configuration is loaded (RESTORE_USER_ALL,16h) into the operating memory to have control on the VR system prior to issuing soft-start.

TABLE 11. MEMORY BANK (PMBus, DD)

DEh	MEMORY BANK NAME
00h	USER_NVM0
01h	USER_NVM1
02h	USER_NVM2
03h	USER_NVM3
04h	USER_NVM4
05h	USER_NVM5
06h	USER_NVM6
07h	USER_NVM7
	·

Other than device's PMBus Addresses and VR operation mode, all system design parameters are programmed by PMBus, as summarized in Table 12 and detailed in Table 14.

TABLE 12. SYSTEM PARAMETER SUMMARY

CODE	PMBus	DESCRIPTION	RANGE
	REG	DESORIFIION	NANGL
PM_ADDR	N/A	PMBus Address	80-8E, CO-CE, EO-EE, FO-FE
VR_MODE	N/A	By "VRSEL" pin	5mV or 10mVstep
вт	E6	5m Step Boot Voltage	0, 0.25 to 1.52V
5.	20	10mV Step Boot Voltage	0, 0.5, 0.51 to 3.04V
	F6	DVID Slew Rate	0.315 to 13.25mV/ μs
DVID	D7	DVID UP Compensation	Offset, Gain, Slope
	D9	DVID Down Compensation	Offset, Gain, Slope
ТМАХ	E8	Maximum Operating Temperature	+85°C to +120°C (5°C/Step)
ΙΜΑΧ	EA	I _{CCMAX} of Platforms	0-255A, 1A/LSB
NPSI	D2	Minimum Number of Operational Phases in Auto	SI1, SI2, CI1, CI2
	D2	Frequency Limiter	$2F_{SW}$, 1.5 F_{SW} , Infinity
	E1	SET_UV	105mV to 402mV
	D8	SET_OV	136mV to 549mV
	24	Maximum Output Voltage	Up to 3.11V
Protection	DF	PROTECTION_DISABLE	All Faults
	F6	INPUT OCP	100% to 130%
	E9	Thermal APA	75% to 100%
	F4	AVG_OCP CYCLE_LIMITING	1.0 TO 1.6 125% to 70%
	F7-FC	Current Balance	-12% to +9%
DIGITAL	E4	IMON_TRIM	-4µA to +3.75µA
IOUT (8Ch)	E5	IOUT_CAL_OFFSET	-4h to 3h
	D8	UP Ramp Amplitude	0.75, 1.0, 1.2, 1.5V
	DE	NVM_BANK	Up to 8 Banks
	D4	Dither Enable	Enable or Disable
	E9	Mismatching Temperature Compensation between sensing element and NTC	0FF, -2.5°C to +35.1°C
LOOP	E2	PS Mode Transition Compensation	PS Mode Transition
	E2, E3	High Frequency Transient Compensation	E2[4:3]: 20m- 80mV E3: Phase Count Original Speedup
	F5	SET_FREQ	120k TO 2.025MHz
	B0-BF	COMPENSATION	R_1 -R3 and C1-C3
	F3	SP_VdBand_K	Original, 2p-16pF 25mV - 200mV 0 to 0.75, Disable

TABLE 12. SYSTEM PARAMETER SUMMARY (Continued)

TABLE 12. STSTEM PARAMETER SUMMART (CONUMER)						
CODE	PMBus REG	DESCRIPTION	RANGE			
	D6	LOCK_VID_OFFSET	Oh to 3h			
	DA	Set_VID	up to 3.04V			
	DB	Set_OFFSET	up to 1.270V			
Output	D3	Droop Enable	Enable or Disable			
Voltage Regulation	D3	Negative Droop	100% to 5%			
	D3	Positive Droop	0mV, 4mV to 32mV			
	E4	IDROOP_TRIM	-4µA to +3.75µA			
	E4	Output Offset Trim	-4µA to +3.75µA			
	D0	NPHASE	1 TO 6-PHASE			
	D1	AUTO_K	1.0, 1.25, 1.5, 1.7			
	D1	AUTO_HYS	12.5, 16.6, 25, 50%			
	D1	AUTO_I1	80, 90, 100, 110%			
	D1	Minimum Phase	1 TO 4-PHASE			
AUTO	D2	AUTO Blanking	0.6ms to 4.6ms			
	D2	APA Time Constant	tsw/8 to tsw			
	D2	APA_Stackup_Delay	0 to 300ns			
	D4	APA LEVEL	10 to 70mV			
	D4	BOOT REFRESH	Enable or Disable			
	D4	AUTO Enable	Enable or Disable			
	99	MFR_ID	2 BYTES			
	9A	MFR_MODEL	2 BYTES			
USER	9B	MFR_REV	2 BYTES			
	9D	MFR_DATE	3 BYTES			

SMBus, PMBus and I²C Operation

There are 32 PMBus address, which can be programmed by a resistor divider on VRSEL_ADDR pin, as shown in Figure 32 and summarized in Table 13.

The ISL6398 features SMBus, PMBus and I²C with

programmable address via VRSEL_ADDR pin, as in Table 13, while SMBus/PMBus includes an Alert# line and Packet Error Check (PEC) to ensure data properly transmitted. In addition, the output voltage, droop slope, enable, operating phase number, and overvoltage setpoint can be written and read via this bus, as summarized in Table 14. Input, output, fault, and temperature telemetries can be read as summarized in Table 15. For proper operation, users should follow the SMBus, PMBus, and I²C protocol, as shown Figure 36. Note that STOP (P) bit is NOT allowed before the repeated START condition when "reading" contents of register, as shown in Figure 36.

The supported SMBus/PMBus/I²C addresses are in 8-bit format (including write and read bit): 80-8E, EO- EE, CO-CE, FO-FE. The least significant bit of the 8-bit address is for write (0h) and read (1h). For reference purposes, the 7-bit format addresses are also summarized in Table 13. There are a series set of read and write commands as summarized in Tables 14 and 15, respectively. The SMBus/PMBus/I²C allows to program the registers as in Table 12, except for SMBus/PMBus/I²C addresses, 16ms (typically, worst case 20ms) after V_{CC} above POR and prior to Enable pins (EN_PWR_CFP) high. The bus can also program default content during this period. If all Enable pins are high

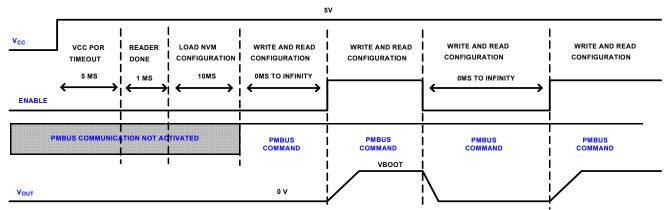
before the NVM configuration is loaded completely, the controller will issue soft-start 16ms (typically, worst case 20ms) after $\rm V_{CC}$ above its POR.

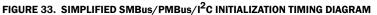
88h-8Eh are two-byte word read with PEC (if applicable), while 78h, F2h, and other write command codes are one-byte word read with PEC (if applicable).

When PMBus is not used, simply leave the respective pull-up on their pins and not connect to the bus..

TABLE 40 OMB	(DAD	
IABLE 13. SMBUS	/PMBus/I ² C 8-BIT AND 7-BIT FORMAT ADDRESS (HE	=X)

8-BIT	7-BIT	8-BIT	7-BIT	8-BIT	7-BIT
80/81	40	C8/C9	64	F0/F1	78
82/83	41	CA/CB	65	F2/F3	79
84/85	42	CC/CD	66	F4/F5	7A
86/87	43	CE/CF	67	F6/F7	7B
88/89	44	E0/E1	70	F8/F9	70
8A/8B	45	E2/E3	71	FA/FB	7D
8C/8D	46	E4/E5	72	FC/FD	7E
8E/8F	47	E6/E7	73	FE/FF	7F
C0/C1	60	E8/E9	74		
C2/C3	61	EA/EB	75		
C4/C6	62	EC/ED	76		
CE/CF	63	EE/EF	77		





5V

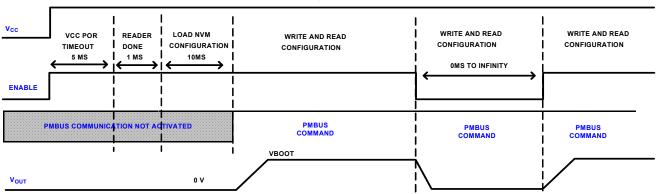
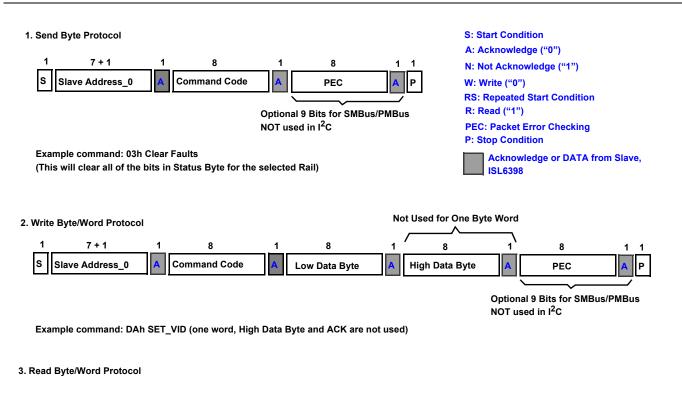
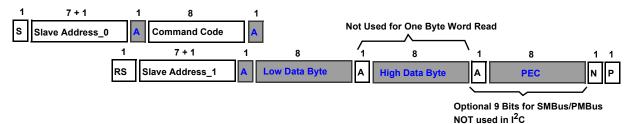


FIGURE 34. SIMPLIFIED SMBus/PMBus/I²C INITIALIZATION TIMING DIAGRAM WITH ENABLE HIGH BEFORE COMPLETING NVM LOADING

ISL6398



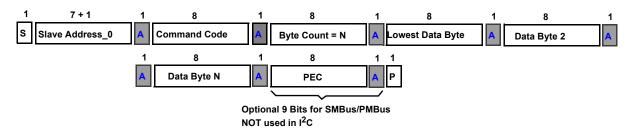


Example command: 8B READ_VOUT (Two words, read voltage of the selected rail).

NOTE: All Writable commands are read with one byte word protocol.

STOP (P) bit is NOT allowed before the repeated START condition when "reading" contents of a register.

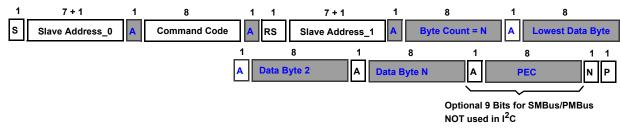
4. Block Write Protocol



Example command: 9Dh MFR_DATA (3 Data Byte)

FIGURE 35. SMBus/PMBus/I²C PROTOCOL

5. Block Read Protocol

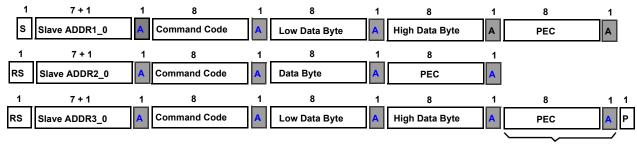


Example command: 8B READ_VOUT (Two words, read voltage of the selected rail).

NOTE: All Writable commands are read with one byte word protocol.

STOP (P) bit is NOT allowed before the repeated START condition when "reading" contents of a register.

6. Group Command Protocol - No more than one command can be sent to the same Address



Optional 9 Bits for SMBus/PMBus

NOT used in I²C

7. Alert Response Address (ARA, 0001_1001, 25h) for SMBus and PMBus, not used for $\rm I^2C$



Optional 9 Bits for SMBus/PMBus NOT used in I²C



COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
01h[2:0]	R/W	40h	EN pin	OPERATION (or ENABLE)	Bit[7]: 0 = OFF (0-F); 1 = ON (80-8Fh) Bit[6:4] = 0; Bit[3:0] = Don't care
10h[7:5]	R/W	NOT	80h	WRITE_PROTECT_ISL	<u>80h</u> = Disable all standard writes (including send bytes) except for WRITE_PROTECT_ISL command. <u>40h</u> = Disable all standard writes (including send bytes), all compensation registers and some Intersil defined commands, BUT not WRITE_PROTECT, OPERATION, CLEAR_FAULT, and some Intersil defined commands. <u>20h</u> = Disable all standard writes, all compensation registers and some Intersil defined commands, BUT NOT WRITE_PROTECT, OPERATION, CLEAR_FAULT and some Intersil defined commands: LOCK_VID_OFFSET, SET_VID, SET_OFFSET. <u>10h</u> = Disable all compensation registers and some Intersil defined commands: LOCK_VID_OFFSET, SET_VID, SET_OFFSET. <u>10h</u> = Disable all compensation registers and some Intersil defined commands, BUT not WRITE_PROTECT, OPERATION, CLEAR_FAULT and some Intersil defined commands (at WRITE PROTECTION LEVEL OF 20h): LOCK_VID_OFFSET, Set_VID, Set_OFFSET, Configurations (UVP, OVP, OCP, CFP, IMAX, TMAX, AUTO, NPHASE, BAL_XX, FREQ, BOOT_VOLTAGE, etc). <u>00h</u> = Enable all write commands. Reject all command code except for 80h, 40h, 20h, 10h, 0h Not support PAGE and ON_OFF_CONFIG; Equivalent VOUT_COMAND is Set_VID, Set_OFFSET, LOCK_VID_OFFSET. "WRITE PROTECT LEVEL" = ANYTHING SPECIFIED IN THIS LEVEL OR BELOW IS ALLOWED TO BE WRITTEN.
15h	SEND	00h	N/A	STORE_USER_ALL	Store user configuration (operating memory) into selected USER_NVM#. The device will declare busy at the assertion of this command, a new command addressed to this device should be sent 300ms afterward.
16h	SEND	00h	N/A	RESTORE_USER_ALL	Restore user configuration (USER_NVM#) into operating memory. The device will declare busy at the assertion of this command, a new command addressed to this device should be sent 6ms afterward.
24h[8:0]	R/W	00h	NVM_BANK	VOUT_MAX	Set maximum output voltage that VR can command (VOUT_MAX = VID+OFFSET > BOOT_Voltage). 5mV Mode: Up to 2.155 (H Byte: 01h; L Byte 7Eh, see Table 18); 10mV Mode: Up to 3.11V (High Byte: 01h; Low Byte 06h).
99[15:0]	BLOCK R/W	00h		MFR_ID	User stores ID.
9A[15:0]	BLOCK R/W	00h		MFR_MODEL	User stores model number.
9B[15:0]	BLOCK R/W	00h		MFR_REVISION	User stores board and/or configuration revision number.
9D[23:0]	BLOCK R/W	00h		MFR_DATE	User stores date.
AD[15:0]	BLOCK R	N/A		IC_DEVICE_ID	Intersil Device ID: product ID (update byte, hardcoded) + ISL configuration revision (lower byte).
AE[15:0]	BLOCK R	N/A		IC_DEVICE_REV	Intersil Device Revision: Silicon revision (upper byte, hardcoded) + ISL configuration revision (lower byte).
D0h[2:0]	R/W	00h	N _{PHASE} By Pin	OPERATE_PHASE_NUMBER	Oh = 7h = N_{MAX} ; 1h=1 Phase;2h = 2 Phases; 3h = 3 Phases; 4h = 4 Phases; 5h = 5 Phases; 6h = 6 Phases. N_{MAX} set by PWMx hard wired; for instance if PWM6 = V_{CC} , N_{MAX} = 5 Phases. DO should NOT be written until 50ms after soft-start and re-written after DVID. When AUTO (R to GND, not shorted to GND) function is enabled, DOh cannot use to program phase number but it reports the operating phase number.

TABLE 14. SMBus, PMBus, AND I²C WRITE AND READ REGISTERS

TABLE 14.	SMBus. PMBus.	AND I ² C WRITE AND	READ REGISTERS

COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
D1h[7:0]	R/W	00h	NVM_BANK	NMIN_AUTOK_HYS_I1	$\begin{array}{l} Bit[1:0] - Minimum Number of Auto Phase Shedding\\ Oh = 1-Phase;1h = 2-Phase; 2h = 3-Phase; 3h = 4-Phase; Default\\ by N_{PSI}\\ Bit[3:2] - AUTO Mode K Factor:\\ Oh = 1.25; 1h = 1.5; 2h = 1.75; 3h = 1.0; Default by AUTO pin\\ Bit[5:4] - AUTO Mode Hysteresis Factor\\ Oh = 50\%; 1h = 25\%; 2h = 16.6\%; 3h = 12.5\%; Default by AUTO pin\\ Bit[7:6] - AUTO Mode I1 Factor:\\ Oh = 100\%; 1h = 80\%; 2h = 90\%; 3h = 110\% of AUTO pin\\ \end{array}$
D2h[9:0]	R/W	00h	NVM_BANK	NPSI_AUTOBLK_FLIMITER_APATC	$\begin{array}{l} \underline{Bit[1:0] - Lower Power Phase Number:} \\ 0h = Sl1, 1-Phase; \\ 1h = Sl2, 2-Phase; \\ 2h = Cl1, 1-Phase; \\ 3h = Cl2, 2-Phase; \\ \underline{Bit[3:2] - Time between subsequent phase drops:} \\ 0h = 4.6ms; 1h = 2.3ms; 2h = 1.2ms; 3h = 0.6ms, Default 0h \\ \underline{Bit[5:4] - Maximum PWM frequency under repetitive Load:} \\ 0h = 2 \ F_{SW}; 1h = 3/2 \ F_{SW}; 2h = 3h = Infinity; Default 0h \\ \underline{Bit[7:6] - APA Time Constant:} \\ 0h = Tsw; 1h = Tsw/2; 2h = Tsw/4; 3h = Tsw/8. Default 3h \\ \underline{Bit[9:8] - APA Stackup Delay:} \\ 0h = 0ns; 1h = 100ns; 2h = 200ns; 3h = 300ns \\ \end{array}$
D3h[6:0]	R/W	10h	NVM_BANK	NEGLL_POSLL	$\begin{array}{l} \underline{Bit[0]} - \underline{Droop\ Enable:}\\ Oh = Disabled,\ 1h = Enabled;\\ \underline{Bit[3:1]\ Droop\ Trim\ (NEGLL)\ of\ Full\ Scale:}\\ Oh = 100\%,\ 1h = 75\%,\ 2h = 5\ 0\%,\ 3h = 25\%,\ 4h = 5\%\\ Adjust\ R_1\ for\ finer\ resolution\\ \underline{Bit[4]:\ Positive\ Load\ Line\ Enabled:}\\ Oh = Disabled;\ 1h = Enabled\\ \underline{Bit[6:5]:\ Positive\ Load\ Line\ Range\ (POSLL):}\\ Oh = 4mV,\ 1h = 8mV;\ 2h = 16mV,\ 3h = 32mV\ at\ IMON\ Full\ Scale \\ \end{array}$
D4h[6:0]	R/W	10h	NVM_BANK	BTR_DE_AUTO_DITHER_APALVL	Bit[0] - Boot-Refresh Enable:Oh = Disabled; 1h = Enabled. Boot refresh circuits is automatically turned off when DAC is lower than 0.605VBit[1] - Diode Emulation EnableOh = Disabled; 1h = EnabledBit[2] - AUTO Enable:Oh = Disabled; 1h = EnabledBit[3] - DITHER Enable:Oh = OFF, 1h = -15kHz, 0, 15kHzBit[6:4] - APA Level:Oh = Disable; 1h = 10mV; 2h = 20mV; 3h = 30mV; 4h = 40mV;5h = 50mV; 6h = 60mV; 7h = 70mV
D5h[1:0]	R/W	00h	NVM_BANK	PWMTRI-LEVEL	$\begin{array}{l} \underline{Bit[0] - PWM \ Support: \ Oh = Compatible \ with \ 3.3V \ PWM \ Tri-State} \\ (Mid) \ Level \ (PWM \ High \ is \ still \ V_{CC}, \ 5V); \ 1h = Compatible \ with \\ 5.0V \ PWM \ Tri-State \ (Mid) \ Level. \ 5.0V \ PWM \ Driver \ is \ also \\ compatible \ with \ "Oh", \ but \ not \ vice \ versa. \end{array}$
D6h[1:0]	R/W	20h	00h	LOCK_VID_OFFSET	Secondary output voltage control protection: Oh= VID and OFFSET NOT CONTROLLABLE 1h = Program Small OFFSET, not VID allowed 2h = Program Large OFFSET, not VID allowed 3h = VID and OFFSET CONTROLLABLE (see Table 16 for details)
D7h[13:0]	BLOCK R/W	10h	NVM_BANK	DVID_UP_OS_GAIN_SLP	BIT[5:0] - DVID_UP_OFFSET 00h = 0mV 01h = 5mV 02h = 10mV

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TABLE 14. SMBus, PMBus, AND I²C WRITE AND READ REGISTERS

COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
D7h[13:0]	BLOCK R/W	10h	NVM_BANK	DVID_UP_OS_GAIN_SLP	$\begin{array}{l} 3Fh = 315mV\\ BIT[8:6] - DVID_UP_GAIN\\ 00 = deltavid*0\\ 01h = deltavid/32\\ 02h = deltavid/16\\\\ 07h = deltavid * 7/32\\ BIT[13:9] - DVID_UP_SLOPE\\ 00h = every 4 clocks(125ns per step - 40mV/\mus)\\ 01h = every 8 clocks(250ns per step - 20mV/\mus)\\\\ 1Fh = every 128 clocks (4\mu s per step - 1.25mV/\mu s) \end{array}$
D8h[6:0]	R/W	10h	NVM_BANK	SET_OV_VRAMP	$\begin{array}{l} \underline{Bit[2:0]} - OVP \ above \ VID \ during \ normal \ operation: \\ Oh = 135mV, \ 1h = 177mV, \ 2h = 218V, \ 3h = 260mV, \ 4h = 342mV, \\ 5h = 425mV, \ 6h = 460mV, \ 7h = 549mV; \ OVP = VID+Bit[2:0] \ with \\ hysteresis \ of \ 83mV. \ OVP_WARNING = VID+Bit[2:0]-80mV \ with \\ hysteresis \ of \ 42mV \ (see \ Electrical \ Specification \ on \ Page \ 10 \ for \\ more \ details). \ OVP \ and \ OVP \ Warning \ can \ be \ disabled \ via \ DFh. \\ \underline{Bit[4:3]. \ soft-start \ OVP \ (with \ 110mV \ Hysteresis): \\ Oh = 1.58V, \ 1h = 1.86V; \ 2h = 2.29V; \ 3h = 3.32V \\ \underline{Bit[6:5]} - VRAMP \\ Oh = 0.75V; \ 1h = 1.0V; \ 2h = 1.2V; \ 3h = 1.5V \end{array}$
D9h[13:0]	BLOCK R/W	10h	NVM_BANK	DVID_DW_OS_GAIN_SLP	$\begin{array}{l} BIT[5:0] - DVID_DW_OFFSET\\ 00h = 0mV\\ 01h = 5mV\\ 02h = 10mV\\ \dots\\ 3Fh = 315mV\\ BIT[8:6] - DVID_DW_GAIN\\ 00 = deltavid*0\\ 01h = deltavid/32\\ 02h = deltavid/16\\ \dots\\ 07h = deltavid + 7/32\\ BIT[13:9] - DVID_DW_SLOPE\\ 00h = every 4 clocks(125ns per step - 40mV/\mus)\\ 01h = every 8 clocks(250ns per step - 20mV/\mus)\\ \dots\\ 1Fh = every 128 clocks(4us per step - 1.25mV/\mus)\\ \end{array}$
DAh[7:0]	R/W	20h	00h	SET_VID	PMBus VID Code (See Table 4)
DBh[7:0]	R/W	20h	NVM_BANK	SET_OFFSET	PMBus OFFSET Code (See Table 4)
DCh[4:0]	R	N/A	PIN	Config Registers	Reference to Resistor Reader. DC
DDh[7:0]	R	N/A	PIN	Config Registers	Reference to Resistor Reader. DD
DEh[2:0]	R/W	20h	PIN	NVM_BANK	Bit[2:0]: Oh = USER_NVM#0 1h = USER_NVM#1 2h = USER_NVM#2 3h = USER_NVM#3 4h = USER_NVM#4 5h = USER_NVM#5 6h = USER_NVM#6 (Copy of NVM#0, otherwise, overwritten) 7h = USER_NVM#7 (Copy of NVM#1, otherwise, overwritten) Select which memory bank to store or load the configurations

COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
DFh[8:0]	R/W	10h	NVM_BANK	PROTECTION_DISABLE	[UV_WARN, OV_WARN,OTP, UVP, IPH_LIMIT, OCP_V, OCP_I, IIN_OCP, OVP]; OCP_V = IMON_3V Trip; OCP_I = 100uA trip; IIN_OCP = input OCP; OVP = Output overvoltage trip; IPH_LIMIT = Phase Current Limiting; UVP = Undervoltage Protection; OTP = TMAX Trip; OV_WARN = Overvoltage Warning; UV_WARN = Undervoltage warning.
E1h[6:0]	R/W	10h	NVM_BANK	SET_UVP_DLY_ACTION	$\begin{array}{l} \underline{Bit[3:0]} - \underline{Output} \ \underline{Under-voltage} \ \underline{Protection} \ \underline{Level:} \\ \hline Oh = 105mV, 1h = 141mV; 2h = 178mV; 3h = 214mV; \\ 4h = 252mV; 5h = 291mV; 6h = 328V; 7h = 402mV; \\ UVP = DAC - UVP \ Level with 19mV \ hysteresis; \\ UVP_WARNING = DAC-UVP+66mV \ (or higher) \ with 17mV \\ Hysteresis \ (see \ Electrical \ Specification \ on \ Page \ 10 \ for \ more \\ details). \ UVP \ and \ UVP \ Warning \ can \ be \ disabled \ via \ DFh. \\ \underline{Bit[5:4]:} \ Output \ Under-voltage \ Protection \ delay: \\ Oh = 10 \mu s, \ 1h = 20 \mu s, \ 2h = 40 \mu s, \ 3h = 120 \mu s \\ \underline{Bit[6] - UVP_\ Actions: \\ Oh = \ Monitor \ Only; \ 1h \ = \ Hiccup \ (same \ as \ OCP \ timing) \end{array}$
E2[11:0]	R/W	10h	NVM_BANK	ADVANCED_PSCOMP_CONFIG	Bit[2:0] PS2 to PS1/0 DCM OFFSET, but make PS0/1 to 2 transition worse, which can help with Bit[8:6]. C2_pop1 momentarily offsets it back up so no dip if C2_pop1 > = bit[2:0] (NOT USED). Oh = 0mV, 1h = 20mV7h = 140mV. Bit[4:3]: High-Frequency Transient VCOMP Bottom Clamp; the lower the better. Oh = 20mV, 1h = 40mV, 2h = 60mV, 3h = 80mV Bit[5] - DECAY_COMP_OFFSET, higher is better (NOT USED)) Oh = 100mV, 1h = 200mV Bit[8:6] - PS0/1 to PS2 Offset (C2_pop1), This likely will take the same value as Bit[2:0] or higher. This improve PS0/1 to PS2 transition, no affect on PS2 to PS1/0. Oh = 0mV, 1h = 20mV7h = 140mV Bit[10:9] PS1 to PS0 Offset (C2_pop2), no affect on other transitions. Oh = 0, 1h = 20mv, 2h = 40mV, 3h = 60mV NOTE: PS2: Diode Emulation (DE) Operation (Not used) PS1: 1-Phase or 2-Phase Operation in Auto Based Upon NPSI PS0: > NSPI Operation Phase

TABLE 14. SMBus, PMBus, AND I²C WRITE AND READ REGISTERS

TABLE 14.	SMBus, PMBus	, AND I ² C WRITE AND	READ REGISTERS
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COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
E3[13:0]	R/W	10h	NVM_BANK	ADVANCED_MOD_CONFIG	Use these registers to Optimize High Frequency Transient Response at Different Phase Count with Original Speed up (F3[2:0] = 0h = Original) Bit[0]: 1 PHASE dBAND: Oh = normal dBand; 1h = reduced dBand (faster); Bit[2:1]: 1 PHASE SPEEDUP Oh = 3h = 1/2 decay; 1h = normal decay; 2h = 1/4 decay (faster); Bit[3]: 2 PHASE dBAND; Oh = normal dBand; 1h = reduced dBand (faster); Bit[5:4]: 2 PHASE SPEEDUP Oh = 3h = 1/2 decay; 1h = normal decay; 2h = 1/4 decay (faster); Bit[6]: 3+ PHASE dBAND; Oh = normal dBand; 1h = reduced dBand (faster); Bit[6]: 3+ PHASE dBAND; Oh = normal dBand; 1h = reduced dBand (faster); Bit[8:7]: 3+ PHASE dBAND; Oh = normal dBand; 1h = reduced dBand (faster); Bit[8:7]: 3+ PHASE SPEEDUP Oh = 3h = 1/2 decay; 1h = normal decay; 2h = 1/4 decay (faster); Bit[10:9]: Peak-Detect CAP Oh = 1pF, 1h = 2pF, 2h = 3pF; 3h = 4pF (smaller cap is less sensitive) Bit[12:11]: High-pass CAP Oh = 1pF, 1h = 2pF, 2h = 3pF; 3h = 4pF (bigger cap, more sensitive) Bit[13]: High-Frequency Balance Gain Oh = 1x; 1h = 2x gain
E4[9:0]	R/W	20h	NVM_BANK	IMON_IDROOP_TRIM	Bit[4:0] - No Load IMON Trim (-4.0 μA to 3.75μA), add current through R ₁ at droop enabled and out of IMON pin together Oh = 0μA10h = -0.25μA
E4[9:0]	R/W	20h	NVM_BANK	IMON_IDROOP_TRIM	1h = $0.25\muA$. 11h = $-0.50\muA$ 2h = $0.50\muA$. 12h = $-0.75\muA$ 3h = $0.75\muA$. 13h = $-1.00\muA$ 4h = $1.00\muA$. 14h = $-1.25\muA$ 5h = $1.25\muA$. 15h = $-1.50\muA$ 6h = $1.50\muA$. 16h = $-1.75\muA$ 7h = $1.75\muA$. 17h = $-2.00\muA$ 8h = $2.00\muA$. 18h = $-2.25\muA$ 9h = $2.25\muA$. 19h = $-2.50\muA$ Ah = $2.50\muA$. 18h = $-3.00\muA$ Ch = $3.00\muA$. 1Ch = $-3.25\muA$ Bh = $2.75\muA$. 1Bh = $-3.00\muA$ Ch = $3.00\muA$. 1Ch = $-3.25\muA$ Dh = $3.25\muA$. 1Dh = $-3.50\muA$ Eh = $3.50\muA$. 1Eh = $-3.75\muA$ Fh = $3.75\muA$. 1Fh = $-4.00\muA$ Bit[9:5] - No Load IDROOP Trim (-4.0 μ Ato $3.75\muA$). add current through R ₁ regardless droop enabled or disabled: use it to fine tune DC offset Oh = $0\muA$. 10h = $-0.25\muA$ 1h = $0.25\muA$. 11h = $-0.50\muA$ 2h = $0.50\muA$. 12h = $-0.75\muA$ 3h = $0.75\muA$. 13h = $1.00\muA$ 4h = $1.00\muA$ 14h = $1.25\muA$ 5h = $1.25\muA$ 15h = $-1.50\muA$ 6h = $1.50\muA$ 16h = $-1.75\muA$ <td< td=""></td<>

TABLE 14. SMBus, PMBus, AND I²C WRITE AND READ REGISTERS

COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
E5[8:0]	R/W	20h	NVM_BANK	IOUT_CAL_OFFSET	OFFSETfor PMBus READ_IOUT (8Ch): Bit[2:0] 1-Phase: $0h = 0h$; $1h = 1h$; $2h = 2h$; $3h = 3h$; $4h = -4h$; $5h = -3h$; $6h = -2h$; $7h = -1h$; Bit[5:3] 2-Phase = 0h = 0h; $1h = 1h$; $2h = 2h$; $3h = 3h$; $4h = -4h$; $5h = -3h$; $6h = -2h$; $7h = -1h$; Bit[8:6] 3-6Phase = 0h = 0h; $1h = 1h$; $2h = 2h$; $3h = 3h$; $4h = -4h$; $5h = -3h$; $6h = -2h$; $7h = -1h$; Bit[8:6] 3-6Phase = 0h = 0h; $1h = 1h$; $2h = 2h$; $3h = 3h$; $4h = -4h$; $5h = -3h$; $6h = -2h$; $7h = -1h$;
E6[7:0]	R/W	10h	NVM_BANK	B00T_Voltage	10mV: 0, 0.5V, 0.51 to 3.04V; 5mV: 0, 0.25, 0.255 To1.52V (see Table 4). The data in this register does not represent the boot voltage programmed by "BT" pin, which can be read via SET_VID.
E7[7:0]	R/W	10h	NVM_BANK		Reserved_RSET
E8[6:0]	R/W	10h	NVM_BANK	TMAX_IINMAX	Bit[2:0] - Tmax: Oh: 100°C 1h: 105°C 2h: 110°C 3h: 115°C 4h: 120°C 5h: 85°C 6h: 90°C 7h: 95°C Bit[5:3] - IINMAX (Scale IIN READ): Oh = 31A; 1h = 15A; 2h = 7A; 3h = 3A; 4h = 1A
E9[5:0]	R/W	10h	NVM_BANK	THERMAL_TCOMP_APA	Bit[3:0] - Thermal Compensation Offset: 0h: OFF 1h: -2.5°C 2h: 0.0°C 3h: 2.5°C 4h: 5.0°C 5h: 7.0°C 6h: 10.0°C 7h: 13.0°C 8h: 16.0°C 9h: 18.9°C Ah: 21.6°C Bh: 24.3°C Ch: 27.0°C Dh: 29.7°C Eh: 32.4°C Fh: 35.1°C Bit[5:4]- Thermal APA: 0h = 75%; 1h = 82%; 2h = 91%;3h = 100% of TMAX
EA[7:0]	R/W	10h	NVM_BANK	IMAX	<u>Scale READ_IOUT (IMON = 2.5V will read IMAX)</u> [0h, 1h:FFh] = [0A, 1A: 255A], 1A/step
F3h[8:0]				SPUP_dBAND_K	For Advanced User ONLY. Speedup (other than Bit[2:0] = Original) will disable frequency limiter so the switching frequency could increase with the load repetitive rate. The higher the capacitance, the faster the speed, which could lead to PSI1/2 to PS0 transition oscillation. Use with caution. Bit[2:0] Speed UP Oh = Original; 1h = 2pF; 2h = 4pF; 3h = 6pF; 4h = 8pF; 5h = 10pF; 6h = 12pF; 7h = 16pF Bit[5:3] VCOMP-dBand Oh = 25mV; 1h = 50mV; 2h = 75mv; 3h = 100mV; 4h = 125mV; 5h = 150mV; 6h = 175mV; 7h = 200mV; Bit[7:6] K-Factor Oh = 0; 1h = 0.25; 2h = 0.5; 3h = 0.75 Bit[8] K-Disabled in DCM Oh = Enable; 1h = Disable

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COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
F4[5:0]	R/W	10h	NVM_BANK	OCP_ICL_TRIM	$\begin{array}{l} \label{eq:bit_states} & \mbox{Bit}[3:0]\mbox{-}\ OCP\ Level\ (lOCP\ AVG\ and\ lCL): \\ Oh = 1.0,\ 1h = 1.1,\ 2h = 1.2;\ 3h = 1.4,\ 4h = 1.5,\ 5h = 1.6\ of\ IMON \\ & \mbox{Bit}[5:4]\mbox{-}\ Output\ Current\ Cycle\ Limiting\ (lCL): \\ Oh = 125\%,\ 01h = 110\%,\ 2h = 100\%;\ 3h = 95\%,\ 4h = 0\%, \\ & \ 5h = 85\%,\ 6h = 80\%,\ 7h = 70\% \end{array}$
F5h[6:0]	R/W	10h	NVM_BANK	SET_FREQ	0h- 7Fh = 120kHz to 2025kHz, 15kHz/Step
F6h[6:0]	R/W	10h	NVM_BANK	DVID_CFP	$\begin{array}{l} Bit[4:0] - Soft-Start and DVID Rate \\ 0h = 0.315mV/\mus; 1h = 0.625mV/\mus; 2h = 1.25mV/\mus; \\ 3h = 2.5mV/\mus; 4h = 2.85mV/\mus; 5h = 3.07mV/\mus; \\ 6h = 3.33mV/\mus; 7h = 3.63mV/\mus, 8h = 4.0mV/\mus, \\ 9h = 4.44 mV/\mus; Ah = 5.0mV/\mus; Bh = 5.6mV/\mus; \\ Ch = 6.66mV/\mus; Dh = 8.0mV/\mus; Eh = 10mV/\mus; \\ Fh = 13.25mV/\mus \\ Bit[6:5] - IN_OCP \\ 0h = 100\%, 1h = 110\%, 2h = 120\%, 3h = 130\% \end{array}$
F7h[2:0] F8h[2:0] F9h[2:0] FAh[2:0] FBh[2:0] FCh[2:0]	R/W	10h	NVM_BANK	F7 = BAL_TRIM_PHASE1 F8 = BAL_TRIM_PHASE2 F9 = BAL_TRIM_PHASE3 FA = BAL_TRIM_PHASE4 FB = BAL_TRIM_PHASE5 FC = BAL_TRIM_PHASE6	$\begin{array}{l} 0h = -12\% \ \text{of full scale} \\ 1h = -9\% \ \text{of full scale} \\ 2h = -6\% \ \text{of full scale} \\ 3h = -3\% \ \text{of full scale} \\ 4h = No \ \text{Offset} \\ 5h = +3\% \ \text{of full scale} \\ 6h = +6\% \ \text{of full scale} \\ 7h = +9\% \ \text{of full scale} \end{array}$
FD[15:0]	R		N/A	CHECK_SUM	Read Calculated CheckSum for individual NVM Bank checksum 10ms after execute EEh(80h) command and 60ms for the total checkSum after execute EEh(40h).
03h	W	40h		CLEAR_FAULTS	Clear "Latched" Fault Registers in 78h For Selected Rail
ARA	R			ALERT_RESPONSE_ADDRESS	8-bit Address: 0001_1001, 19h; 7-bit Address: 0C
COMPENSAT	ION REGIST	ERS			
B0h[7:0]	R/W	00h	NVM_BANK	R ₁	250 Steps: 1.01018x 00h = 599.0 01h = 605.1 F9h = 7471
B1h[4:0]	R/W	00h	NVM_BANK	R2	30 Steps: 1.1x 00h = 2k 01h = 2.2 1Dh = 32K
B2h[4:0]	R/W	00h	NVM_BANK	R3_6PHASE	<u>30 Steps: 1.1x</u>
B3h[4:0]	R/W	00h	NVM_BANK	R3_5PHASE	00h = 50k - 01h= 55
B4h[4:0]	R/W	00h	NVM_BANK	R3_4PHASE	
B5h[4:0]	R/W	00h	NVM_BANK	R3_3PHASE	1Dh =790
B6h[4:0]	R/W	00h	NVM_BANK	R3_2PHASE	B2 = 1Fh, will Remove R3/C3 for all Phase Count. Larger R3 and/or smaller C3 help reduce output noise coupling.
B7h[4:0]	R/W	00h	NVM_BANK	R3_1PHASE	Recommend to keep R3/C3 the same values for highest phase count (Nmax) and Nmax-1 Phase count for smoother transition.
B8h[5:0]	R/W	00h	NVM_BANK	C1	<u>42 Steps: 1.1x</u> 00h = 10pF 01h = 11pF 29h = 500pF

TABLE 14. SMBus, PMBus, AND I²C WRITE AND READ REGISTERS

COMMAND CODE	ACCESS	WRITE PROTECT LEVEL	DEFAULT	COMMAND NAME	DESCRIPTION
B9h[5:0]	R/W	OOh	NVM_BANK	C2	42 Steps: 1.1x 00h = 330pF 01h = 363pF 29h = 16.4nF
BAh[5:0]	R/W	00h	NVM_BANK	C3_6PHASE	42 Steps: 1.1x
BBh[5:0]	R/W	00h	NVM_BANK	C3_5PHASE	00h = 100pF
BCh[5:0]	R/W	00h	NVM_BANK	C3_4PHASE	-01h = 110pF
BDh[5:0]	R/W	00h	NVM_BANK	C3_3PHASE	29h = 5.0nF
BEh[5:0]	R/W	00h	NVM_BANK	C3_2PHASE	
BFh[5:0]	R/W	00h	NVM_BANK	C3_1PHASE	
DIRECT ACC	ESS TO EEPP	ROM (ADVAN	CED USER AN	D TEST MODE ONLY)	
EC[7:0]	R/W	00h	00h	EEP_ADDR_REG	Give user access to EEPROM Address
ED[31:0]	BLOCK R/W	00h	ALL ZEROs	EEP_DATA_REG	User Write 4-bytes (32-bits) of data into called address by EC
EE[7:0]	R/W	00h	0000h	EEP_ACTIVATE	EEPROM Control Register Bit[0] = 1h, Start EEPROM Read Procedure Bit[1] = 1h, Start EEPROM Write Procedure Bit[5:2] - Reserved Bit[6] = 1h, Generate Total Checksum (FD data). Bit[7] = 1h, Generate Individual NVM BANK Checksum (FD data). The device will declare busy at the assertion of this command, a new command addressed to this device should be sent 300ms afterward

When the controller is reset by the Enable pins (TM_EN_OTP or EN_PWR_CFP), not V_{CC}, the programmed registers will be stored in operating memory.

TABLE 15. SMBus, PMBus, AND I²C TELEMETRIES

CODE	WORD LENGTH (BYTE)	COMMAND NAME	DESCRIPTION	TYPICAL RESOLUTION
88h[15:0]	тwo	READ_VIN	Input Voltage (25.5V = FF) Formula: HEX2DEC(Readout)*0.1V	8-BIT, 100mV
89h[15:0]	TWO	READ_IIN	Input Current (1Fh = 10µA)	5-BIT, IIN_FULL/31
8Bh[15:0]	TWO	READ_VOUT	VR Output Voltage (HEX2DEC(Readout)*0.05V)	10-BIT, 5mV
8Ch[15:0]	тwo	READ_IOUT	VR Output Current (2.5V IMON = ICCMAX) HEX2DEC(Readout)*ICCMAX/255	8-BIT,~1A
8Dh[15:0]	TWO	READ_TEMPERATURE_1	TM Temperature (see Table 17) Approximation Formula for Table 19 (T in °C): -0.0000221*T ³ + 0.0094935*T ² - 1.876*T + 213.75	8-BIT, ~1°C*
96h[15:0]	TWO	READ_POUT	Output Power	~ 2W (~1A LSB @ 2V)
97h[15:0]	TWO	READ_PIN	Input Power	~12W (~1A LSB @ 12V)
78h[8:0]	ONE	STATUS_BYTE	Fault Reporting: Bit7 = Busy Bit6 = 0 Bit5 = OverVoltage; Bit4 = OverCurrent, ≥ I _{MAX} ; Bit3 = 0 Bit2 = Over-Temperature, ≥ T _{MAX} ; Bit1 = PMBus Communication Error Bit0 = 0	[BUSY, 0, OV, OC, 0, OT, CML, 0]

TABLE 15. SMBus, PMBus, AND I²C TELEMETRIES

CODE	WORD LENGTH (BYTE)	COMMAND NAME	DESCRIPTION	TYPICAL RESOLUTION
79h[15:0]	TWO	STATUS_WORD	$\label{eq:linear_state} \begin{array}{l} \underline{Lower \ Byte \ Fault \ Reporting \ (= \ 78h)::}}{Bit 7 = Busy} \\ Bit 7 = Busy \\ Bit 6 = 0 \\ Bit 5 = OverVoltage; \\ Bit 4 = OverCurrent, \geq I_{MAX}; \\ Bit 3 = 0 \\ Bit 2 = Over-Temperature, \geq T_{MAX}; \\ Bit 2 = Over-Temperature, \geq T_{MAX}; \\ Bit 1 = PMBus \ Communication \ Error \\ Bit 0 = 0 \\ \hline \\ \underline{Upper \ Byte \ Fault \ Reporting:} \\ Bit 7 = V_{OUT} \ OV, UV, and \ OV/UV \ Warning \\ Bit 6 = I_{OUT} \ OC \\ Bit 5 = INPUT \ OCP >= 1F; \\ Bit [4:0] = 0 \end{array}$	Upper Byte: [V _{OUT} , I _{OUT,} IIN_OCP, 0, 0, 0, 0, 0] Lower Byte: [BUSY, 0, OV, OC, 0, OT, CML, 0]

NOTE: 88h-8Eh are two bytes word, while all others are one byte word.

TABLE 16. LOCK_VID_OFFSET

D6h	SET_VID	SET_OFFSET	FINAL DAC	TARGETED APPLICATIONS
00h	Not	Not	VBOOT	Not output voltage managed needed
01h	Not	Yes	VBOOT+OFFSET	Small offset for compensation
02h	Not	Yes	VBOOT + OFFSET	Large Offset for Voltage Margining
03h	Yes	Yes	VID + OFFSET	Dynamic VID Operation Needed

NOTE: The ISL6398 is designed to provide secondary output voltage control protection. When D6-Oh, it keeps output voltage the same as boot up voltage. When operating in 01h option, SMBus/PMBus/I²C's OFFSET should only adjust slightly higher or lower (say \pm 20mV, but IC does not limit the range) for PCB loss compensation. To program full range of OFFSET, the user should select 02h or 03h options. 03h option gives users full control of the output voltage (VID+OFFSET) via SMBus/PMBus/I²C, commonly used in over-clocking applications. Prior to a successful written PMBus VID or OFFSET, the controller will continue stay at boot up level.

TABLE 17. TYPICAL TEMPERATURE (8Dh and 8Eh)

TABLE 17. TYPICAL TEMPERATURE (8Dh and 8Eh) (Continued)

TABLE 17. TYPICAL TEMPERATURE (8Dh and 8Eh)					
TEMPERATURE (°C)	V _{TM(S)} OF V _{CC} (%)	CODE (HEX)	TEMPERATURE (°C)	V _{TM(S)} OF V _{CC} (%)	CODE (HEX)
0	95.0	F2	71	58.9	96
1	94.8	F1	72	58.2	94
2	94.6	F1	73	57.5	92
3	94.4	FO	74	56.7	90
4	94.1	FO	75	56.0	8E
5	93.9	EF	76	55.3	8D
6	93.6	EE	77	54.6	8B
7	93.4	EE	78	53.9	89
8	93.1	ED	79	53.2	87
9	92.8	EC	80	52.4	85
10	92.6	EC	81	51.7	83
11	92.3	EB	82	51.0	82
12	92.0	EA	83	50.3	80
13	91.6	E9	84	49.6	7E
14	91.3	E8	85	48.9	7C
15	91.0	E7	86	48.2	7B
16	90.7	E7	87	47.6	79
17	90.3	E6	88	46.9	77
18	89.9	E5	89	46.2	75
19	89.6	E4	90	45.5	74
20	89.2	E3	91	44.9	72
21	88.8	E2	92	44.2	70
22	88.4	E1	93	43.5	6F
23	88.0	EO	94	42.9	6D
24	87.6	DF	95	42.3	6B
25	87.2	DE	96	41.6	6A
26	86.7	DD	97	41.0	68
27	86.3	DC	98	40.4	66
28	85.8	DA	99	39.7	65
29	85.4	D9	100	39.1	63
30	84.9	D8	101	38.5	62
31	84.4	D7	102	37.9	60
32	83.9	D6	103	37.3	5F
33	83.4	D4	104	36.7	5D
34	82.9	D3	105	36.1	5C
35	82.4	D2	106	35.5	5A
36	81.9	D0	107	35.0	59
37	81.3	CF	108	34.4	57
38	80.8	CD	109	33.9	56

TEMPERATURE (°C)	V _{TM(S)} OF V _{CC} (%)	CODE (HEX)	TEMPERATURE (°C)	V _{TM(S)} OF V _{CC} (%)	CODE (HEX)
39	80.2	СС	110	33.3	54
40	79.7	СВ	111	32.8	53
41	79.1	C9	112	32.2	52
42	78.5	C8	113	31.7	50
43	77.9	C6	114	31.2	4F
44	77.3	C5	115	30.7	4E
45	76.7	C3	116	30.2	4D
46	76.1	C2	117	29.7	4B
47	75.5	CO	118	29.2	4A
48	74.8	BE	119	28.7	49
49	74.2	BD	120	28.2	48
50	73.5	BB	121	27.8	46
51	72.9	B9	122	27.3	45
52	72.2	B8	123	26.9	44
53	71.6	B6	124	26.4	43
54	70.9	B4	125	26.0	42
55	70.2	B3	126	25.5	41
56	69.5	B1	127	25.1	40
57	68.8	AF	128	24.7	3E
58	68.2	AD	129	24.3	3D
59	67.5	AC	130	23.9	3C
60	66.8	AA	131	23.5	3B
61	66.1	A8	132	23.1	ЗA
62	65.4	A6	133	22.7	39
63	64.6	A4	134	22.3	38
64	63.9	A3	135	21.9	37
65	63.2	A1	136	21.6	36
66	62.5	9F	137	21.2	36
67	61.8	9D	138	20.8	35
68	61.1	9B	139	20.5	34
69	60.3	99	140	20.1	33
70	59.6	98			

TABLE 18. VOUT_MAX (24h) in 5MV/STEP MODE

TABLE 18. VOUT_MAX (24h) in 5MV/STEP MODE (Continued)

TABLE 18. VOUT_MAX (24h) in 5MV/STEP MODE					
VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)
0.000	0	0.885	80	1.525	100
0.250	1	0.890	81	1.530	101
0.255	2	0.895	82	1.535	102
0.260	3	0.900	83	1.540	103
0.265	4	0.905	84	1.545	104
0.270	5	0.910	85	1.550	105
0.275	6	0.915	86	1.555	106
0.280	7	0.920	87	1.560	107
0.285	8	0.925	88	1.565	108
0.290	9	0.930	89	1.570	109
0.295	Α	0.935	8A	1.575	10A
0.300	В	0.940	8B	1.580	10B
0.305	С	0.945	8C	1.585	100
0.310	D	0.950	8D	1.590	10D
0.315	E	0.955	8E	1.595	10E
0.320	F	0.960	8F	1.600	10F
0.325	10	0.965	90	1.605	110
0.330	11	0.970	91	1.610	111
0.335	12	0.975	92	1.615	112
0.340	13	0.980	93	1.620	113
0.345	14	0.985	94	1.625	114
0.350	15	0.990	95	1.630	115
0.355	16	0.995	96	1.635	116
0.360	17	1.000	97	1.640	117
0.365	18	1.005	98	1.645	118
0.370	19	1.010	99	1.650	119
0.375	1A	1.015	9A	1.655	11A
0.380	1B	1.020	9B	1.660	11B
0.385	10	1.025	90	1.665	11C
0.390	1D	1.030	9D	1.670	11D
0.395	1E	1.035	9E	1.675	11E
0.400	1F	1.040	9F	1.680	11F
0.405	20	1.045	A0	1.685	120
0.410	21	1.050	A1	1.690	121
0.415	22	1.055	A2	1.695	122
0.420	23	1.060	A3	1.700	123
0.425	24	1.065	A4	1.705	124
0.430	25	1.070	A5	1.710	125
0.435	26	1.075	A6	1.715	126

VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)
0.440	27	1.080	A7	1.720	127
0.445	28	1.085	A8	1.725	128
0.450	29	1.090	A9	1.730	129
0.455	2A	1.095	AA	1.735	12A
0.460	2B	1.100	AB	1.740	12B
0.465	20	1.105	AC	1.745	12C
0.470	2D	1.110	AD	1.750	12D
0.475	2E	1.115	AE	1.755	12E
0.480	2F	1.120	AF	1.760	12F
0.485	30	1.125	BO	1.765	130
0.490	31	1.130	B1	1.770	131
0.495	32	1.135	B2	1.775	132
0.500	33	1.140	B3	1.780	133
0.505	34	1.145	B4	1.785	134
0.510	35	1.150	B5	1.790	135
0.515	36	1.155	B6	1.795	136
0.520	37	1.160	B7	1.800	137
0.525	38	1.165	B8	1.805	138
0.530	39	1.170	B9	1.810	139
0.535	ЗA	1.175	BA	1.815	13A
0.540	3B	1.180	BB	1.820	13B
0.545	ЗC	1.185	BC	1.825	13C
0.550	3D	1.190	BD	1.830	13D
0.555	ЗE	1.195	BE	1.835	13E
0.560	ЗF	1.200	BF	1.840	13F
0.565	40	1.205	CO	1.845	140
0.570	41	1.210	C1	1.850	141
0.575	42	1.215	C2	1.855	142
0.580	43	1.220	C3	1.860	143
0.585	44	1.225	C4	1.865	144
0.590	45	1.230	C5	1.870	145
0.595	46	1.235	C6	1.875	146
0.600	47	1.240	C7	1.880	147
0.605	48	1.245	C8	1.885	148
0.610	49	1.250	C9	1.890	149
0.615	4A	1.255	CA	1.895	14A
0.620	4B	1.260	СВ	1.900	14B
0.625	4C	1.265	СС	1.905	14C
0.630	4D	1.270	CD	1.910	14D

TABLE 18. VOUT_MAX (24h) in 5MV/STEP MODE (Continued)

TABLE 18. VOUT_MAX (24h) in 5MV/STEP MODE (Continued)					lueu)
VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)
0.635	4E	1.275	CE	1.915	14E
0.640	4F	1.280	CF	1.920	14F
0.645	50	1.285	DO	1.925	150
0.650	51	1.290	D1	1.930	151
0.655	52	1.295	D2	1.935	152
0.660	53	1.300	D3	1.940	153
0.665	54	1.305	D4	1.945	154
0.670	55	1.310	D5	1.950	155
0.675	56	1.315	D6	1.955	156
0.680	57	1.320	D7	1.960	157
0.685	58	1.325	D8	1.965	158
0.690	59	1.330	D9	1.970	159
0.695	5A	1.335	DA	1.975	15A
0.700	5B	1.340	DB	1.980	15B
0.705	5C	1.345	DC	1.985	15C
0.710	5D	1.350	DD	1.990	15D
0.715	5E	1.355	DE	1.995	15E
0.720	5F	1.360	DF	2.000	15F
0.725	60	1.365	EO	2.005	160
0.730	61	1.370	E1	2.010	161
0.735	62	1.375	E2	2.015	162
0.740	63	1.380	E3	2.020	163
0.745	64	1.385	E4	2.025	164
0.750	65	1.390	E5	2.030	165
0.755	66	1.395	E6	2.035	166
0.760	67	1.400	E7	2.040	167
0.765	68	1.405	E8	2.045	168
0.770	69	1.410	E9	2.050	169
0.775	6A	1.415	EA	2.055	16A
0.780	6B	1.420	EB	2.060	16B
0.785	6C	1.425	EC	2.065	16C
0.790	6D	1.430	ED	2.070	16D
0.795	6E	1.435	EE	2.075	16E
0.800	6F	1.440	EF	2.080	16F
0.805	70	1.445	FO	2.085	170
0.810	71	1.450	F1	2.090	171
0.815	72	1.455	F2	2.095	172
0.820	73	1.460	F3	2.100	173
0.825	74	1.465	F4	2.105	174

TABLE 18. VOUT_MAX (24h) in 5MV/STEP MODE (Continued)

	_	. ,	•	•	•
VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)	VOUT (V)	Code (HEX)
0.830	75	1.470	F5	2.110	175
0.835	76	1.475	F6	2.115	176
0.840	77	1.480	F7	2.120	177
0.845	78	1.485	F8	2.125	178
0.850	79	1.490	F9	2.130	179
0.855	7A	1.495	FA	2.135	17A
0.860	7B	1.500	FB	2.140	17B
0.865	7C	1.505	FC	2.145	17C
0.870	7D	1.510	FD	2.150	17D
0.875	7E	1.515	FE	2.155	17E
0.880	7F	1.520	FF		

General Design Guide

This design guide is intended to provide a high-level explanation of the steps necessary to create a multiphase power converter. It is assumed that the reader is familiar with many of the basic skills and 'techniques referenced in the following. In addition to this guide, Intersil provides complete reference designs, which include schematics, bills of materials, and example board layouts for multi-phase VR applications.

Power Stages

The first step in designing a multiphase converter is to determine the number of phases. This determination depends heavily upon the cost analysis, which in turn depends on system constraints that differ from one design to the next. Principally, the designer will be concerned with whether components can be mounted on both sides of the circuit board; whether through-hole components are permitted; and the total board space available for power supply circuitry. Generally speaking, the most economical solutions are those in which each phase handles between 15A and 25A. All surface mount designs will tend toward the lower end of this current range. If through-hole MOSFETs and inductors can be used, higher per-phase currents are possible. In cases where board space is the limiting constraint, current can be pushed as high as 40A per phase, but these designs require heat sinks and forced air to cool the MOSFETs, inductors and heat dissipating surfaces.

MOSFETs

The choice of MOSFETs depends on the current each MOSFET will be required to conduct; the switching frequency; the capability of the MOSFETs to dissipate heat; and the availability and nature of heat sinking and air flow.

LOWER MOSFET POWER CALCULATION

The calculation for heat dissipated in the lower MOSFET is simple, since virtually all of the heat loss in the lower MOSFET is due to current conducted through the channel resistance ($r_{DS(ON)}$). In Equation 33, I_M is the maximum continuous output current; $I_{P.P}$ is the peak-to-peak inductor current (see Equation 1 on page 15); d is the duty cycle (V_{OUT}/V_{IN}); and L is the per-channel inductance.

$$P_{LOW, 1} = r_{DS(ON)} \left[\left(\frac{I_M}{N} \right)^2 + \frac{I_{p-p}}{12} \right] \cdot (1 - d)$$
 (EQ. 33)

An additional term can be added to the lower MOSFET loss equation to account for additional loss accrued during the dead time when inductor current is flowing through the lower MOSFET body diode. This term is dependent on the diode forward voltage at I_M, V_{D(ON)}; the switching frequency, F_{SW}; and the length of dead times, t_{d1} and t_{d2}, at the beginning and the end of the lower MOSFET conduction interval respectively.

$$LOW, 2 = V_{D(ON)}F_{SW}\left[\left(\frac{l_M}{N} + \frac{l_{p-p}}{2}\right)t_{d1} + \left(\frac{l_M}{N} - \frac{l_{p-p}}{2}\right)t_{d2}\right]$$
(EQ. 34)

Finally, the power loss of output capacitance of the lower MOSFET is approximated in Equation 35:

$$\mathsf{P}_{\mathsf{LOW},3} \approx \frac{2}{3} \cdot \mathsf{V}_{\mathsf{IN}}^{1.5} \cdot \mathsf{C}_{\mathsf{OSS}_\mathsf{LOW}} \cdot \sqrt{\mathsf{V}_{\mathsf{DS}_\mathsf{LOW}}} \cdot \mathsf{F}_{\mathsf{SW}} \tag{EQ. 35}$$

where C_{OSS_LOW} is the output capacitance of lower MOSFET at the test voltage of V_{DS_LOW} . Depending on the amount of ringing, the actual power dissipation will be slightly higher than this.

Thus the total maximum power dissipated in each lower MOSFET is approximated by the summation of $P_{LOW,1}$, $P_{LOW,2}$ and $P_{LOW,3}$.

UPPER MOSFET POWER CALCULATION

In addition to $r_{DS(ON)}$ losses, a large portion of the upper MOSFET losses are due to currents conducted across the input voltage (V_{IN}) during switching. Since a substantially higher portion of the upper MOSFET losses are dependent on switching frequency, the power calculation is more complex. Upper MOSFET losses can be divided into separate components involving the upper-MOSFET switching times; the lower MOSFET body-diode reverse-recovery charge, Q_{rrr} ; and the upper MOSFET $r_{DS(ON)}$ conduction loss.

When the upper MOSFET turns off, the lower MOSFET does not conduct any portion of the inductor current until the voltage at the phase node falls below ground. Once the lower MOSFET begins conducting, the current in the upper MOSFET falls to zero as the current in the lower MOSFET ramps up to assume the full inductor current. In Equation 36, the required time for this commutation is t_{1} and the approximated associated power loss is $\mathsf{P}_{UP,1}.$

$$P_{UP,1} \approx V_{IN} \left(\frac{I_M}{N} + \frac{I_{p-p}}{2}\right) \left(\frac{t_1}{2}\right) F_{SW}$$
 (EQ. 36)

At turn on, the upper MOSFET begins to conduct and this transition occurs over a time t_2 . In Equation 37, the approximate power loss is $P_{UP,2}$.

$$P_{UP,2} \approx V_{IN} \left(\frac{I_M}{N} - \frac{I_{p-p}}{2} \right) \left(\frac{t_2}{2} \right) F_{SW}$$
 (EQ. 37)

A third component involves the lower MOSFET's reverse-recovery charge, Q_{rr} . Since the inductor current has fully commutated to the upper MOSFET before the lower MOSFET's body diode can draw all of Q_{rr} , it is conducted through the upper MOSFET across V_{IN} . The power dissipated as a result is $P_{UP,3}$ and is approximated in Equation 38:

$$P_{UP,3} = V_{IN}Q_{rr}F_{SW}$$
(EQ. 38)

The resistive part of the upper MOSFET's is given in Equation 33 as $\mathsf{P}_{UP.4}.$

$$P_{UP,4} \approx r_{DS(ON)} \left[\left(\frac{I_{M}}{N} \right)^{2} + \frac{I_{\underline{p},\underline{p}}}{12} \right] \cdot d$$
 (EQ. 39)

Equation 40 accounts for some power loss due to the drainsource parasitic inductance (L_{DS}, including PCB parasitic inductance) of the upper MOSFETs, although it is not the exact:

$$P_{UP,5} \approx L_{DS} \left(\frac{I_M}{N} + \frac{I_{p-p}}{2} \right)^2$$
 (EQ. 40)

Finally, the power loss of output capacitance of the upper MOSFET is approximated in Equation 41:

$$\mathsf{P}_{\mathsf{UP},6} \approx \frac{2}{3} \cdot \mathsf{V}_{\mathsf{IN}}^{1.5} \cdot \mathsf{C}_{\mathsf{OSS}_\mathsf{UP}} \cdot \sqrt{\mathsf{V}_{\mathsf{DS}_\mathsf{UP}}} \cdot \mathsf{F}_{\mathsf{SW}}$$
(EQ. 41)

where C_{OSS_UP} is the output capacitance of lower MOSFET at test voltage of V_{DS_UP} . Depending on the amount of ringing, the actual power dissipation will be slightly higher than this.

The total power dissipated by the upper MOSFET at full load can now be approximated as the summation of the results from Equations 36 to 41. Since the power equations depend on MOSFET parameters, choosing the correct MOSFETs can be an iterative process involving repetitive solutions to the loss equations for different MOSFETs and different switching frequencies.

Current Sensing Resistor

The resistors connected to the ISEN+ pins determine the gains in the load-line regulation loop and the channel-current balance loop as well as setting the overcurrent trip point. Select values for these resistors by using Equation 42:

$$R_{ISEN} = \frac{R_X}{100 \times 10^{-6}} \frac{I_{OCP}}{N}$$
(EQ. 42)

where R_{ISEN} is the sense resistor connected to the ISEN+ pin, N is the active channel number, $R_{\rm X}$ is the resistance of the current

sense element, either the DCR of the inductor or R_{SENSE} depending on the sensing method, and I_{OCP} is the desired overcurrent trip point. Typically, I_{OCP} can be chosen to be 1.2 times the maximum load current of the specific application.

With integrated temperature compensation, the sensed current signal is independent of the operational temperature of the power stage, i.e. the temperature effect on the current sense element R_X is cancelled by the integrated temperature compensation function. R_X in Equation 42 should be the resistance of the current sense element at the room temperature.

When the integrated temperature compensation function is disabled by selecting "OFF" TCOMP code, the sensed current will be dependent on the operational temperature of the power stage, since the DC resistance of the current sense element may be changed according to the operational temperature. R_X in Equation 42 should be the maximum DC resistance of the current sense element at the all operational temperature.

In certain circumstances, especially for a design with an unsymmetrical layout, it may be necessary to adjust the value of one or more ISEN resistors for VR. When the components of one or more channels are inhibited from effectively dissipating their heat so that the affected channels run cooler than the average, choose new, larger values of R_{ISEN} for the affected phases (see the section entitled "Current Sensing" on page 18). Choose R_{ISEN,2} in proportion to the desired increase in temperature rise in order to cause proportionally more current to flow in the cooler phase, as shown in Equation 43:

$$R_{ISEN,2} = R_{ISEN} \frac{\Delta I_2}{\Delta T_1}$$

$$\Delta R_{ISEN} = R_{ISEN,2} - R_{ISEN}$$
(EQ. 43)

In Equation 43, make sure that ΔT_2 is the desired temperature rise above the ambient temperature, and ΔT_1 is the measured temperature rise above the ambient temperature. Since all channels' R_{ISEN} are integrated and set by one RSET, a resistor (ΔR_{ISEN}) can be in series with the cooler channel's ISEN+ pin to raise this phase current. However, the ISL6398 can adjust the thermal/current balance of the VR via registers F7 to FC.

Load-line Regulation Resistor

The load-line regulation resistor is labelled ${\sf R}_{FB}$ in Figure 11. Its value depends on the desired loadline requirement of the application.

The desired loadline can be calculated using Equation 44:

$$R_{LL} = \frac{V_{DROOP}}{I_{FL}}$$
(EQ. 44)

where ${\rm I}_{FL}$ is the full load current of the specific application, and ${\rm VR}_{\rm DROOP}$ is the desired voltage droop under the full load condition.

Based on the desired loadline ${\sf R}_{LL},$ the loadline regulation resistor can be calculated using Equation 45:

$$R_{FB} = \frac{N \cdot R_{ISEN} \cdot R_{LL}}{R_{X}}$$
(EQ. 45)

where N is the active channel number, R_{ISEN} is the sense resistor connected to the ISEN+ pin, and R_X is the resistance of the current sense element, either the DCR of the inductor or R_{SEN} depending on the sensing method.

If one or more of the current sense resistors are adjusted for thermal balance (as in Equation 43), the load-line regulation resistor should be selected based on the average value of the current sensing resistors, as given in Equation 46:

$$R_{FB} = \frac{R_{LL}}{R_{\chi}} \sum_{n} R_{ISEN(n)}$$
(EQ. 46)

where $\mathsf{R}_{ISEN(n)}$ is the current sensing resistor connected to the n^{th} ISEN+ pin.

Output Filter Design

The output inductors and the output capacitor bank together to form a low-pass filter responsible for smoothing the pulsating voltage at the phase nodes. The output filter also must provide the transient energy until the regulator can respond. Because it has a low bandwidth compared to the switching frequency, the output filter necessarily limits the system transient response. The output capacitor must supply or sink load current while the current in the output inductors increases or decreases to meet the demand.

In high-speed converters, the output capacitor bank is usually the most costly (and often the largest) part of the circuit. Output filter design begins with minimizing the cost of this part of the circuit. The critical load parameters in choosing the output capacitors are the maximum size of the load step, DI; the load-current slew rate, di/dt; and the maximum allowable output-voltage deviation under transient loading, DV_{MAX} . Capacitors are characterized according to their capacitance, ESR, and ESL (equivalent series inductance).

At the beginning of the load transient, the output capacitors supply all of the transient current. The output voltage will initially deviate by an amount approximated by the voltage drop across the ESL. As the load current increases, the voltage drop across the ESR increases linearly until the load current reaches its final value. The capacitors selected must have sufficiently low ESL and ESR so that the total output-voltage deviation is less than the allowable maximum. Neglecting the contribution of inductor current and regulator response, the output voltage initially deviates by an amount, as shown in Equation 47:

$$\Delta V \approx (ESL) \frac{di}{dt} + (ESR) \Delta I$$
 (EQ. 47)

The filter capacitor must have sufficiently low ESL and ESR so that ΔV < $\Delta V_{MAX}.$

Most capacitor solutions rely on a mixture of high-frequency capacitors with relatively low capacitance in combination with bulk capacitors having high capacitance but limited high frequency performance. Minimizing the ESL of the high frequency capacitors allows them to support the output voltage as the current increases. Minimizing the ESR of the bulk capacitors allows them to supply the increased current with less output voltage deviation.

The ESR of the bulk capacitors also creates the majority of the output-voltage ripple. As the bulk capacitors sink and source the

inductor AC ripple current (see "Interleaving" on page 15 and Equation 2), a voltage develops across the bulk-capacitor ESR equal to $I_{c(p-p)}$ (ESR). Thus, once the output capacitors are selected, the maximum allowable ripple voltage, $V_{P-P(MAX)}$, determines the lower limit on the inductance, as shown in Equation 48.

$$L \ge ESR \cdot \frac{V_{OUT} \cdot K_{RCM}}{F_{SW} \cdot V_{IN} \cdot V_{PP(MAX)}}$$
(EQ. 48)

Since the capacitors are supplying a decreasing portion of the load current while the regulator recovers from the transient, the capacitor voltage becomes slightly depleted. The output inductors must be capable of assuming the entire load current before the output voltage decreases more than DV_{MAX}. This places an upper limit on inductance.

Equation 49 gives the upper limit on L for the cases when the trailing edge of the current transient causes a greater output-voltage deviation than the leading edge. Equation 50 addresses the leading edge. Normally, the trailing edge dictates the selection of L because duty cycles are usually less than 50%. Nevertheless, both inequalities should be evaluated, and L should be selected based on the lower of the two results. In each equation, L is the per-channel inductance, C is the total output capacitance, and N is the number of active channels.

$$L \leq \frac{2 \cdot N \cdot C \cdot V_{OUT}}{(\Delta I)^2} \left[\Delta V_{MAX} - \Delta I \cdot ESR \right]$$
(EQ. 49)

$$L \leq \frac{1.25 \cdot N \cdot C}{(\Delta I)^2} \left[\Delta V_{MAX} - \Delta I \cdot ESR \right] \left(V_{IN} - V_{OUT} \right)$$
(EQ. 50)

Switching Frequency Selection

There are a number of variables to consider when choosing the switching frequency, as there are considerable effects on the upper-MOSFET loss calculation. These effects are outlined in "MOSFETs" on page 49, and they establish the upper limit for the switching frequency. The lower limit is established by the requirement for fast transient response and small output-voltage ripple as outlined in "Output Filter Design" on page 51. Choose the lowest switching frequency that allows the regulator to meet the transient-response and output-voltage ripple requirements.

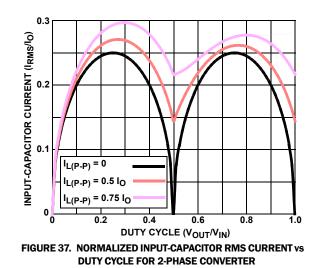
Input Capacitor Selection

The input capacitors are responsible for sourcing the AC component of the input current flowing into the upper MOSFETs. Their RMS current capacity must be sufficient to handle the AC component of the current drawn by the upper MOSFETs which is related to duty cycle and the number of active phases. The input RMS current can be calculated with Equation 51.

$$I_{\text{IN, RMS}} = \sqrt{K_{\text{IN, CM}}^2 \bullet Io^2 + K_{\text{RAMP, CM}}^2 \bullet I_{\text{Lo, p-p}}^2}$$
 (EQ. 51)

$$K_{IN, CM} = \sqrt{\frac{(N \bullet D - m + 1) \bullet (m - N \bullet D)}{N^2}}$$
(EQ. 52)

$$K_{\text{RAMP, CM}} = \sqrt{\frac{m^2 (N \bullet D - m + 1)^3 + (m - 1)^2 (m - N \bullet D)^3}{12N^2 D^2}}$$
 (EQ. 53)



For a 2-phase design, use Figure 37 to determine the input capacitor RMS current requirement given the duty cycle, maximum sustained output current (I₀), and the ratio of the per-phase peak-to-peak inductor current (I_{L(P-)P}) to I₀. Select a bulk capacitor with a ripple current rating which will minimize the total number of input capacitors required to support the RMS current calculated. The voltage rating of the capacitors should also be at least 1.25 times greater than the maximum input voltage.

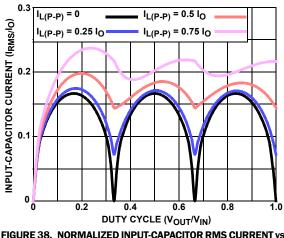
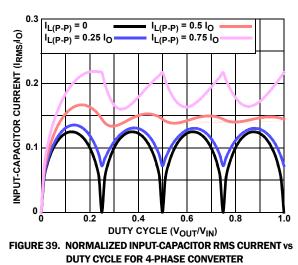
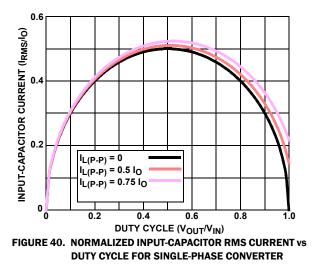


FIGURE 38. NORMALIZED INPUT-CAPACITOR RMS CURRENT vs DUTY CYCLE FOR 3-PHASE CONVERTER



Figures 38 and 39 provide the same input RMS current information for 3 and 4-phase designs respectively. Use the same approach to selecting the bulk capacitor type and number as previously described.

Low capacitance, high-frequency ceramic capacitors are needed in addition to the bulk capacitors to suppress leading and falling edge voltage spikes. The result from the high current slew rates produced by the upper MOSFETs turn on and off. Select low ESL ceramic capacitors and place one as close as possible to each upper MOSFET drain to minimize board parasitic impedances and maximize noise suppression.



MULTIPHASE RMS IMPROVEMENT

Figure 40 is provided as a reference to demonstrate the dramatic reductions in input-capacitor RMS current upon the implementation of the multiphase topology. For example, compare the input RMS current requirements of a 2-phase converter versus that of a single phase. Assume both converters have a duty cycle of 0.25, maximum sustained output current of 40A, and a ratio of $I_{L,PP}$ to I_0 of 0.5. The single phase converter would require 17.3A_{RMS} current capacity while the 2-phase converter would only require 10.9A_{RMS}. The advantages become even more pronounced when output current is increased and additional phases are added to keep the component cost down relative to the single phase approach.

Layout and Design Considerations

The following layout and design strategies are intended to minimize the noise coupling, the impact of board parasitic impedances on converter performance and to optimize the heat-dissipating capabilities of the printed-circuit board. This section highlights some important practices which should be followed during the layout process. A layout check list is available for use.

Pin Noise Sensitivity, Design and Layout Consideration

Table 19 shows the noise sensitivity of each pin and their design and layout consideration. All pins and external components should not be across switching nodes and should be placed in general proximity to the controller.

TABLE 19.	PIN DESIGN	AND/OR LAYOUT	CONSIDERATION

PIN NAME	NOISE SENSITIVE	DESCRIPTION
ISENIN-	Yes	Connect to input supply side of the input inductor or resistor pin with L/DCR or ESL/R matching network in close proximity to the controller. Place NTC in the close proximity to input inductor for thermal compensation. A local 10nF decoupling capacitor between ISENIN+ and ISENIN- is preferred. DCR sensing with thermal compensation will yield no load offset reading. Resistor sensing is preferred for accurate input current reporting. > 40 μ s time constant [C*R _{IN1} *R _{IN2})/(R _{IN1} +R _{IN2})] might be needed if the average input current reporting is preferred; and it also reduces chance to trigger CFP during heavy load transient.
ISENIN+	Yes	Connects to the Drain of High-side MOSFET side of the input inductor or resistor pin. A local 0.1μ F ceramic capacitor is recommended. When not used, connect ISENIN+ to V _{IN} and a resistor divider with a ratio of 1/3 on ISENIN± pin, say 499kΩ in between ISENIN± pins and then 1.5MΩ from ISENIN± to ground (see Figure 29). The voltage of this pin is used feed-forward compensation.
EN_PWR_CFP	Yes	There is an internal μ s filter. Decoupling capacitor is NOT needed, but if needed, use a low time constant one to avoid too large a shut-down delay. It will also be the output of CFP function: 34Ω strong pull-up. 25 mils spacing from other traces.
RGND	Yes	Pair up (within 20 mils) with the positive rail remote sensing line that connected to FB resistor, and routing them to the load sensing points.
VSEN	Yes	Pair up (within 20 mils) with the negative rail of remote sensing line that connected to RGND, and route them to the load sensing points.

TABLE 19. PIN DESIGN AND/OR LAYOUT CONSIDERATION (Continued)

PIN NAME	NOISE SENSITIVE	DESCRIPTION
VSEN_OVP	Yes	Used for Overvoltage protection sensing.
VRSEL_ADDR NVM_BANK_BT	No	Register setting is locked prior to soft- start. Since the external resistor-divider ratio compares with the internal resistor ratio of the V_{CC} , their rail should be exactly tied to the same point as V_{CC} pin, not through an RC filter. DON'T use decoupling capacitors on these pins.
VR_RDY	No	Open drain and high dv/dt pin. Avoid its pull-up higher than V_{CC} . Tie it to ground when not used.
IMON	Yes	Refer to GND, not RGND. Place R and C in general proximity to the controller. The time constant of RC should be sufficient, typically 200μ S, as an averaging function for the digital IOUT.
VR_HOT#	No	Open drain and high dv/dt pin during transitions. Avoid its pull-up rail higher than V_{CC} . 30 mils spacing from other traces.
SM_PM_I2CL SM_PM_I2DA	Yes	50kHz to 1.5MHz signal when the SMBus, PMBus, or I^2C is sending commands, pairing up with PMALERT# and routing carefully back to SMBus, PMBus or I^2C . 20 mils spacing within I2DATA, PMALERT#, and I2CLK; and more than 30 mils to all other signals. Refer to the SMBus, PMBus or I^2C design guidelines and place proper terminated (pull-up) resistance for impedance matching. Ground them when not used.
PMALERT#	No	Open drain and high dv/dt pin during transitions. Route it in the middle of I2DATA and I2LK. Also see above. Leave it open or tie it ground when not used.
BUF_COMP	Yes	Buffer output of internal Comp Signal.
TM_EN_OTP	Yes	Place NTC in close proximity to the output inductor of Channel 1 and to the output rail, not close to MOSFET side (see Figure 24); the return trace should be 25 mils away from other traces. Place 1k Ω pull-up and decoupling capacitor (typically 0.1µF) in close proximity to the controller. The pull-up resistor should be exactly tied to the same point as V _{CC} pin, not through an RC filter. If not used, connect this pin to 1M $\Omega/2M$ Ω resistor divider, or tie to V _{CC} .
AUTO	Yes	Program AUTO phase shedding threshold a resistor from this pin to GND. AUTO phase shedding is disabled when this pin tied to GND.
RSET	Yes	Place the R in close proximity to the controller. DON'T use decoupling capacitor on this pin.

TABLE 19. PIN DESIGN AND/OR LAYOUT CONSIDERATION (Continued)

PIN NAME	NOISE SENSITIVE	DESCRIPTION
v _{cc}	Yes	Place a high quality ceramic capacitor (~ 1µF) in close proximity to the controller.
PWM1-6	NO	Avoid the respective PWM routing across or under other phase's power trains/planes and current sensing network. Don't make them across or under external components of the controller. Keep them at least 20mils away from any other traces.
ISEN[6:1]+	Yes	Connect to the output rail side of the respective channel's output inductor or resistor pin. Decoupling is optional and might be required for long sense traces and a poor layout.
ISEN[6:1]-	Yes	Connect to the phase node side of the respective channel's output inductor or resistor pin with L/DCR or ESL/R _{SEN} matching network in close proximity to the ISEN± pins of VR. Differentially routing back to the controller by paring with respective ISEN+; at least 20 mils spacing between pairs and away from other traces. Each pair should not cross or go under the other channel's switching nodes [PHASE, UGATE, LGATE] and power planes even though they are not in the same layer.
GND	Yes	This EPAD is the return of PWM output drivers and PMBus. Use 4 or more vias to directly connect the EPAD to the power ground plane. Avoid using only single via or 0Ω resistor connection to the power ground plane. Also connect pins 13, 14 and 15 to ground plane.
General Comments		The layer next to the Top or Bottom layer is preferred to be ground players, while the signal layers can be sandwiched in the ground layers if possible.

Component Placement

Within the allotted implementation area, orient the switching components first. The switching components are the most critical because they carry large amounts of energy and tend to generate high levels of noise. Switching component placement should take into account power dissipation. Align the output inductors and MOSFETs such that space between the components is minimized while creating the PHASE plane. Place the Intersil MOSFET driver IC as close as possible to the MOSFETs they control to reduce the parasitic impedances due to trace length between critical driver input and output signals. If possible, duplicate the same placement of these components for each phase.

Next, place the input and output capacitors. Position the high frequency ceramic input capacitors next to each upper MOSFET drain. Place the bulk input capacitors as close to the upper MOSFET drains as dictated by the component size and dimensions. Long distances between input capacitors and MOSFET drains result in too much trace inductance and a reduction in capacitor performance. Locate the output capacitors between the inductors and the load, while keeping ceramic capacitors in close proximity to the microprocessor socket.

To improve the chance of first pass success, it is very important to take time to follow the above outlined design guidelines and Intersil generated layout check list, see more details in "Voltage Regulator (VR) Design Materials" on page 55. Proper planning for the layout is as important as designing the circuits. Running things in a hurry, you could end up spending weeks and months to debug a poorly-designed and improperly laid out board.

Powering Up And Open-Loop Test

The ISL6398 features very easy debugging and powering up. For first-time powering up, an open-loop test can be done by applying sufficient voltage (current limiting to 0.25A) to V_{CC} , signal high to TM_EN_OTP (>1.05V) and EN_PWR_CFP (>0.9V and less than 3.5V) pins with the input voltage (VIN) disconnected.

- 1. Each PWM output should operate at maximum duty cycle and correct switching frequency.
- 2. Read data in DC and DD of PMBus to confirm its proper setting.
- 3. If 5V drivers are used and share the same rail as V_{CC} , the proper switching on UGATEs and LGATEs should be seen.
- 4. If 12V drivers are used and can be disconnected from VIN and sourced by an external 12V supply, the proper switching on UGATEs and LGATEs should be observed.
- 5. If the above is not properly operating, you should check soldering joint, resistor register setting, Power Train connection or damage, i.e, shorted gates, drain and source.

Sometimes the gate might measure short due to residual gate charge. Therefore, a measured short gate with ohmmeter cannot validate if the MOSFET is damaged unless the Drain to Source is also measured short.

- 6. When re-work is needed for the L/DCR matching network, use an ohmmeter across the C to see if the correct R value is measured before powering the VR up; otherwise, the current imbalance due to improper re-work could damage the power trains.
- 7. After everything is checked, apply low input voltage (1-5V) with appropriate current limiting (~0.5A). All phases should be switching evenly when AUTO disabled.
- 8. Remove the pull-up from EN_PWR_CFP pin, using bench power supplies, power-up V_{CC} with current limiting (typically ~ 0.25A if 5V drivers included) and slowly increase Input Voltage with current limiting. For typical application, V_{CC} limited to 0.25A, VIN limited to 0.5A should be safe for powering up with no load. High core-loss inductors likely need to increase the input current limiting. All phases should be switching evenly.

Voltage Regulator (VR) Design Materials

To support VR design and layout, Intersil also developed a set of worksheets and evaluation boards, as listed in Tables 20 and 21, respectively. The tolerance band calculation (TOB) worksheets for VR output regulation and IMON have been developed using the Root Sum Squared (RSS) method with 3 sigma distribution point of the related components and parameters. Note that the "Electrical Specifications" table beginning on page 10 specifies no less than 6 sigma distribution point, not suitable for RSS TOB calculation. Contact Intersil's local office or field support for the latest available information.

ITEM	DESCRIPTION		
0	Design and Validation		
1	Design Worksheet for Compensation and Component Selection		
2	SMBus/PMBus/I ² C Communication Tool with Software		
3	Resistor Register Calculator		
4	Layout Design Guidelines		
5	Evaluation Board Schematics in OrCAD Format and Layout in Allegro Format		

TABLE 20. AVAILABLE DESIGN ASSISTANCE MATERIALS

NOTE: For worksheets, please contact Intersil Application support at www.intersil.com/design/.

EVALUATION BOARDS	PACKAGE	TARGETED APPLICATIONS	SMBus/PMBus/I ² C	PEAK EFFICIENCY	ICCMAX (A)
ISL6398EVAL1Z	5x5 40Ld	3-Phase POL with ISL99140, 6x6 DrMOS Digital Compensation with NVM	Yes	93%, 1.2V@40A	100A
ISL6398EVAL2Z	5x5 40Ld	6-Phase with ISL99140, 6x6 DrMOS Digital Compensation with NVM	Yes	94%, 1.8V@50A	215A

TABLE 21. AVAILABLE EVALUATION BOARDS

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

DATE	REVISION	CHANGE		
August 13, 2015	FN8575.1	Updated "SMBus/PMBus/I ² C" section of Electrical Specification table on page 13. -Added PMBus specs Signal Input Low Voltage, Signal Input High Voltage and Signal Output Low Voltage. -Added min/max Time-out spec -Changed the Time-out typical from "35" to "30". Updated the second sentence under "Soft-start" on page 25. Updated Table 9 on page 33 by splitting PMBus (DC) and PMBus (DD) (now Table 10) into two different tables, also updated R _{DW} value for 80h from "10" to "499". Updated third paragraph under "SMBus, PMBus and I ² C Operation" on page 35. Updated Figure 33 on page 35. Updated Figure 36 on page 37. Updated Figure 36 on page 37. Updated DFh[8:0] description in Table 14 on page 41 and changed bit from "[7:0]" to "[8:0]". Updated POD to current revision. Changes from revision 1 to revision 2 are as follows: Added tolerance ± values.		
April 18, 2014	FN8575.0	Initial Release		

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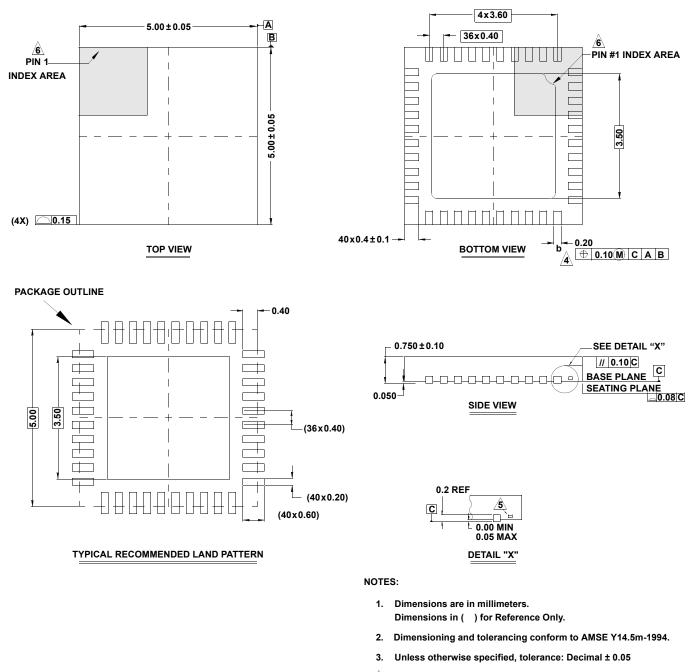
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Package Outline Drawing

L40.5x5

40 LEAD THIN QUAD FLAT NO-LEAD PLASTIC PACKAGE Rev 2, 7/14



- A. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.27mm from the terminal tip.
- **5**. Tiebar shown (if present) is a non-functional feature.
- **C** The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.
- 7. JEDEC reference drawing: MO-220WHHE-1